

# 32-Bit

Microcontroller

# TC1728

32-Bit Single-Chip Microcontroller

Data Sheet

V1.2 2014-06

Microcontrollers

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**Table of Contents**

<b>1</b>	<b>Summary of Features</b> .....	<b>1-1</b>
<b>2</b>	<b>System Overview of the TC1728</b> .....	<b>2-1</b>
2.1	Block Diagrams .....	2-2
<b>3</b>	<b>Pinning</b> .....	<b>3-1</b>
<b>4</b>	<b>Identification Registers</b> .....	<b>4-1</b>
<b>5</b>	<b>Electrical Parameters</b> .....	<b>5-1</b>
5.1	General Parameters .....	5-1
5.1.1	Parameter Interpretation .....	5-1
5.1.2	Pad Driver and Pad Classes Summary .....	5-2
5.1.3	Absolute Maximum Ratings .....	5-3
5.1.4	Pin Reliability in Overload .....	5-5
5.1.5	Operating Conditions .....	5-7
5.2	DC Parameters .....	5-10
5.2.1	Input/Output Pins .....	5-10
5.2.2	Analog to Digital Converters (ADCx) .....	5-23
5.2.3	Fast Analog to Digital Converter (FADC) .....	5-33
5.2.4	Oscillator Pins .....	5-38
5.2.5	Power Supply Current .....	5-39
5.2.5.1	Calculating the 1.3 V Current Consumption .....	5-42
5.3	AC Parameters .....	5-43
5.3.1	Testing Waveforms .....	5-43
5.3.2	Power Sequencing 5V Supply Only .....	5-44
5.3.3	Power Sequencing 3.3V Supply Only .....	5-46
5.3.4	Power Sequencing all Voltages supplied from External .....	5-48
5.3.5	Power, Pad and Reset Timing .....	5-50
5.3.6	EVR Parameter .....	5-53
5.3.7	Phase Locked Loop (PLL) .....	5-55
5.3.8	ERAY Phase Locked Loop (ERAY_PLL) .....	5-57
5.3.9	JTAG Interface Timing .....	5-58
5.3.10	DAP Interface Timing .....	5-60
5.3.11	Peripheral Timings .....	5-62
5.3.11.1	Micro Link Interface (MLI) Timing .....	5-62
5.3.11.2	Micro Second Channel (MSC) Interface Timing .....	5-64
5.3.11.3	SSC Master/Slave Mode Timing .....	5-67
5.3.11.4	ERAY Interface Timing .....	5-70
5.4	Package and Reliability .....	5-71
5.4.1	Package Parameters .....	5-71
5.4.2	Package Outline .....	5-72

---

**Table of Contents**

5.4.3	Flash Memory Parameters .....	5-72
5.4.4	Quality Declarations .....	5-74
<b>6</b>	<b>Revision History .....</b>	<b>6-1</b>

## 1 Summary of Features

The **SAK-TC1728N-192F133HL / SAK-TC1728N-192F133HR** has the following features:

- High-performance 32-bit super-scalar TriCore V1.3.1 CPU with 4-stage pipeline
  - Superior real-time performance
  - Strong bit handling
  - Fully integrated DSP capabilities
  - Single precision Floating Point Unit (FPU)
  - 133 MHz operation at full temperature range
- 32-bit Peripheral Control Processor with single cycle instruction (PCP2)
  - 8 Kbyte Parameter Memory (PRAM)
  - 24 Kbyte Code Memory (CMEM)
  - 133 MHz operation at full temperature range
- Multiple on-chip memories
  - 1.5 Mbyte Program Flash Memory (PFLASH) with ECC
  - 64 Kbyte Data Flash Memory (DFLASH) usable for EEPROM emulation
  - 120 Kbyte Data Memory (LDRAM)
  - Instruction Cache: up to 8Kbyte (ICACHE, configurable)
  - 24 Kbyte Code Scratchpad Memory (SPRAM)
  - Data Cache: up to 4 Kbyte (DCACHE, configurable)
  - 8 Kbyte Overlay Memory (OVRAM)
  - 16 Kbyte BootROM (BROM)
- 16-Channel DMA Controller
- Sophisticated interrupt system with  $2 \times 255$  hardware priority arbitration levels serviced by CPU or PCP2
- High performing on-chip bus structure
  - 64-bit Local Memory Buses between CPU, Flash and Data Memory
  - 32-bit System Peripheral Bus (SPB) for on-chip peripheral and functional units
  - One bus bridge (LFI Bridge)
- Versatile On-chip Peripheral Units
  - Two Asynchronous/Synchronous Serial Channels (ASC) with baud rate generator, parity, framing and overrun error detection
  - Four High-Speed Synchronous Serial Channels (SSC) with programmable data length and shift direction
  - One serial Micro Second Bus interface (MSC) for serial port expansion to external power devices
  - One High-Speed Micro Link interface (MLI) for serial inter-processor communication
  - One MultiCAN Module with 3 CAN nodes and 64 free assignable message objects for high efficiency data handling via FIFO buffering and gateway data transfer

---

**Summary of Features**

- One General Purpose Timer Array Module (GPTA) providing a powerful set of digital signal filtering and timer functionality to realize autonomous and complex Input/Output management
- Two Capture/Compare Unit 6 (CAPCOM6) kernels
- Two General Purpose Timer (GPT12) modules
- 36 analog input lines for ADC
  - 2 independent kernels (ADC0 and ADC1)
  - Analog supply voltage range from 3.3 V to 5 V (single supply)
  - Broken wire detection
- 2 different FADC input channels
  - channels with impedance control and overlaid with ADC1 inputs
  - Extreme fast conversion, 21 cycles of  $f_{FADC}$  clock
  - 10-bit A/D conversion (higher resolution can be achieved by averaging of consecutive conversions in digital data reduction filter)
- 127 digital general purpose I/O lines (GPIO), 3 input lines
- Digital I/O ports with 3.3 V capability
- On-chip debug support for OCDS Level 1 (CPU, PCP, DMA, On Chip Bus)
- Dedicated Emulation Device chip available (TC1728ED)
  - multi-core debugging, real time tracing, and calibration
  - four/five wire JTAG (IEEE 1149.1) or two wire DAP (Device Access Port) interface
- Power Management System
- Clock Generation Unit with PLL

The **SAK-TC1728F-192F133HL / SAK-TC1728F-192F133HR** has the following features:

- High-performance 32-bit super-scalar TriCore V1.3.1 CPU with 4-stage pipeline
  - Superior real-time performance
  - Strong bit handling
  - Fully integrated DSP capabilities
  - Single precision Floating Point Unit (FPU)
  - 133 MHz operation at full temperature range
- 32-bit Peripheral Control Processor with single cycle instruction (PCP2)
  - 8 Kbyte Parameter Memory (PRAM)
  - 24 Kbyte Code Memory (CMEM)
  - 133 MHz operation at full temperature range
- Multiple on-chip memories
  - 1.5 Mbyte Program Flash Memory (PFLASH) with ECC
  - 64 Kbyte Data Flash Memory (DFLASH) usable for EEPROM emulation
  - 120 Kbyte Data Memory (LDRAM)
  - Instruction Cache: up to 8Kbyte (ICACHE, configurable)
  - 24 Kbyte Code Scratchpad Memory (SPRAM)
  - Data Cache: up to 4 Kbyte (DCACHE, configurable)
  - 8 Kbyte Overlay Memory (OVRAM)

---

**Summary of Features**

- 16 Kbyte BootROM (BROM)
- 16-Channel DMA Controller
- Sophisticated interrupt system with  $2 \times 255$  hardware priority arbitration levels serviced by CPU or PCP2
- High performing on-chip bus structure
  - 64-bit Local Memory Buses between CPU, Flash and Data Memory
  - 32-bit System Peripheral Bus (SPB) for on-chip peripheral and functional units
  - One bus bridge (LFI Bridge)
- Versatile On-chip Peripheral Units
  - Two Asynchronous/Synchronous Serial Channels (ASC) with baud rate generator, parity, framing and overrun error detection
  - Four High-Speed Synchronous Serial Channels (SSC) with programmable data length and shift direction
  - One serial Micro Second Bus interface (MSC) for serial port expansion to external power devices
  - One High-Speed Micro Link interface (MLI) for serial inter-processor communication
  - One MultiCAN Module with 3 CAN nodes and 64 free assignable message objects for high efficiency data handling via FIFO buffering and gateway data transfer
  - One FlexRay™ module with 2 channels (E-Ray).
  - One General Purpose Timer Array Module (GPTA) providing a powerful set of digital signal filtering and timer functionality to realize autonomous and complex Input/Output management
  - Two Capture/Compare Unit 6 (CAPCOM6) kernels
  - Two General Purpose Timer (GPT12) modules
- 36 analog input lines for ADC
  - 2 independent kernels (ADC0 and ADC1)
  - Analog supply voltage range from 3.3 V to 5 V (single supply)
  - Broken wire detection
- 2 different FADC input channels
  - channels with impedance control and overlaid with ADC1 inputs
  - Extreme fast conversion, 21 cycles of  $f_{FADC}$  clock
  - 10-bit A/D conversion (higher resolution can be achieved by averaging of consecutive conversions in digital data reduction filter)
- 127 digital general purpose I/O lines (GPIO), 3 input lines
- Digital I/O ports with 3.3 V capability
- On-chip debug support for OCDS Level 1 (CPU, PCP, DMA, On Chip Bus)
- Dedicated Emulation Device chip available (TC1728ED)
  - multi-core debugging, real time tracing, and calibration
  - four/five wire JTAG (IEEE 1149.1) or two wire DAP (Device Access Port) interface
- Power Management System
- Clock Generation Unit with PLL



Summary of Features

**Ordering Information**

The ordering code for Infineon microcontrollers provides an exact reference to the required product. This ordering code identifies:

- The derivative itself, i.e. its function set, the temperature range, and the supply voltage
- The package and the type of delivery.

For the available ordering codes for the TC1728 please refer to the “**Product Catalog Microcontrollers**”, which summarizes all available microcontroller variants.

This document describes the derivatives of the device. The **Table 1** enumerates these derivatives and summarizes the differences.

**Table 1 TC1728 Derivative Synopsis**

Derivative	Ambient Temperature Range	ERAY	Wire Bond Material
SAK-TC1728N-192F133HL	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	No	Gold
SAK-TC1728N-192F133HR <sup>1)</sup>	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	No	Copper
SAK-TC1728F-192F133HR <sup>2)</sup>	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	Yes	Copper
SAK-TC1728F-192F133HL	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	Yes	Gold

1) This derivative has the same features as the SAK-TC1728N-192F133HL, except the wire-bonding material.

2) This derivative has the same features as the SAK-TC1728F-192F133HL, except the wire-bonding material.

## **2 System Overview of the TC1728**

The TC1728 combines three powerful technologies within one silicon die, achieving new levels of power, speed, and economy for embedded applications:

- Reduced Instruction Set Computing (RISC) processor architecture
- Digital Signal Processing (DSP) operations and addressing modes
- On-chip memories and peripherals

DSP operations and addressing modes provide the computational power necessary to efficiently analyze complex real-world signals. The RISC load/store architecture provides high computational bandwidth with low system cost. On-chip memory and peripherals are designed to support even the most demanding high-bandwidth real-time embedded control-systems tasks.

Additional high-level features of the TC1728 include:

- Efficient memory organization: instruction and data scratch memories, caches
- Serial communication interfaces – flexible synchronous and asynchronous modes
- Peripheral Control Processor – standalone data operations and interrupt servicing
- DMA Controller – DMA operations and interrupt servicing
- General-purpose timers
- High-performance on-chip buses
- On-chip debugging and emulation facilities
- Flexible interconnections to external components
- Flexible power-management

The TC1728 is a high-performance microcontroller with TriCore CPU, program and data memories, buses, bus arbitration, an interrupt controller, a peripheral control processor and a DMA controller and several on-chip peripherals. The TC1728 is designed to meet the needs of the most demanding embedded control systems applications where the competing issues of price/performance, real-time responsiveness, computational power, data bandwidth, and power consumption are key design elements.

The TC1728 offers several versatile on-chip peripheral units such as serial controllers, timer units, CAPCOM6 and Analog-to-Digital converters. Within the TC1728, all these peripheral units are connected to the TriCore CPU/system via the Flexible Peripheral Interconnect (FPI) Bus and the Local Memory Bus (LMB). Several I/O lines on the TC1728 ports are reserved for these peripheral units to communicate with the external world.

System Overview of the TC1728

2.1 Block Diagrams

Figure 1 shows the block diagram of the SAK-TC1728N-192F133HL./ SAK-TC1728N-192F133HR.

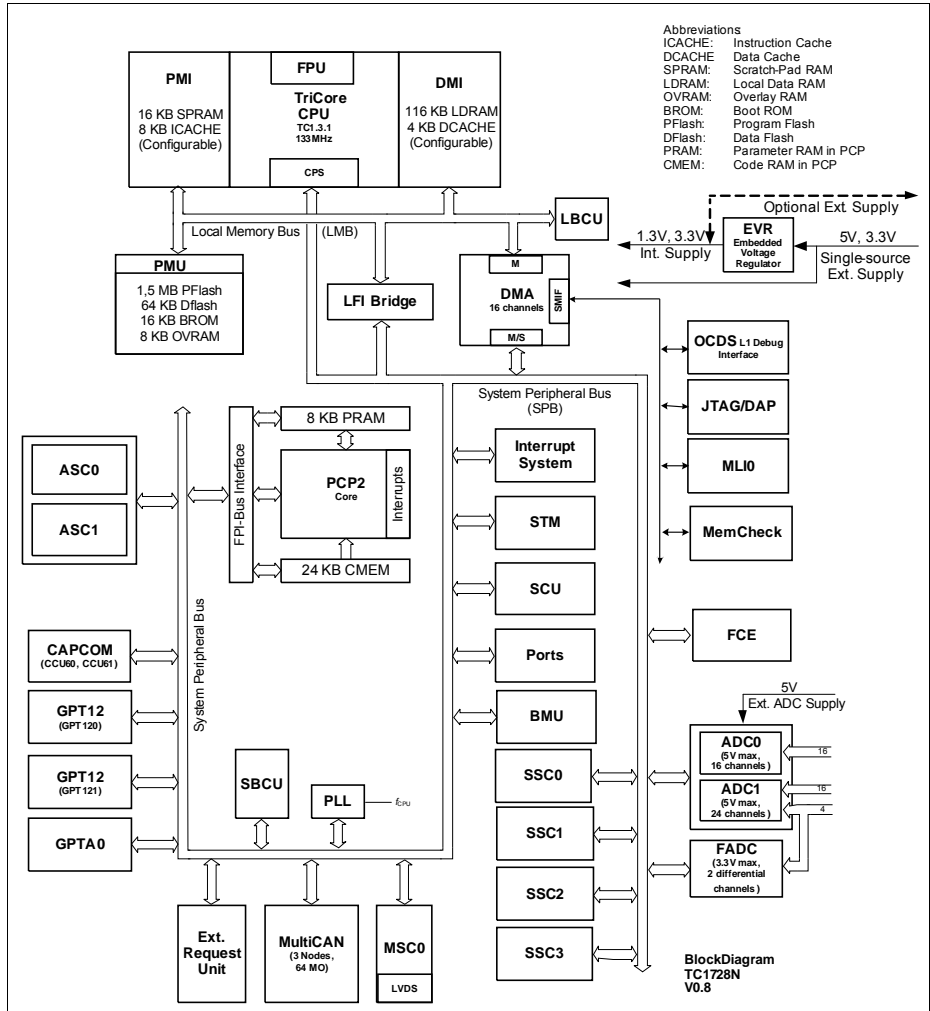


Figure 1 SAK-TC1728N-192F133HL / SAK-TC1728N-192F133HR Block Diagram

System Overview of the TC1728

Figure 2 shows the block diagram of the SAK-TC1728F-192F133HL / SAK-TC1728F-192F133HR.

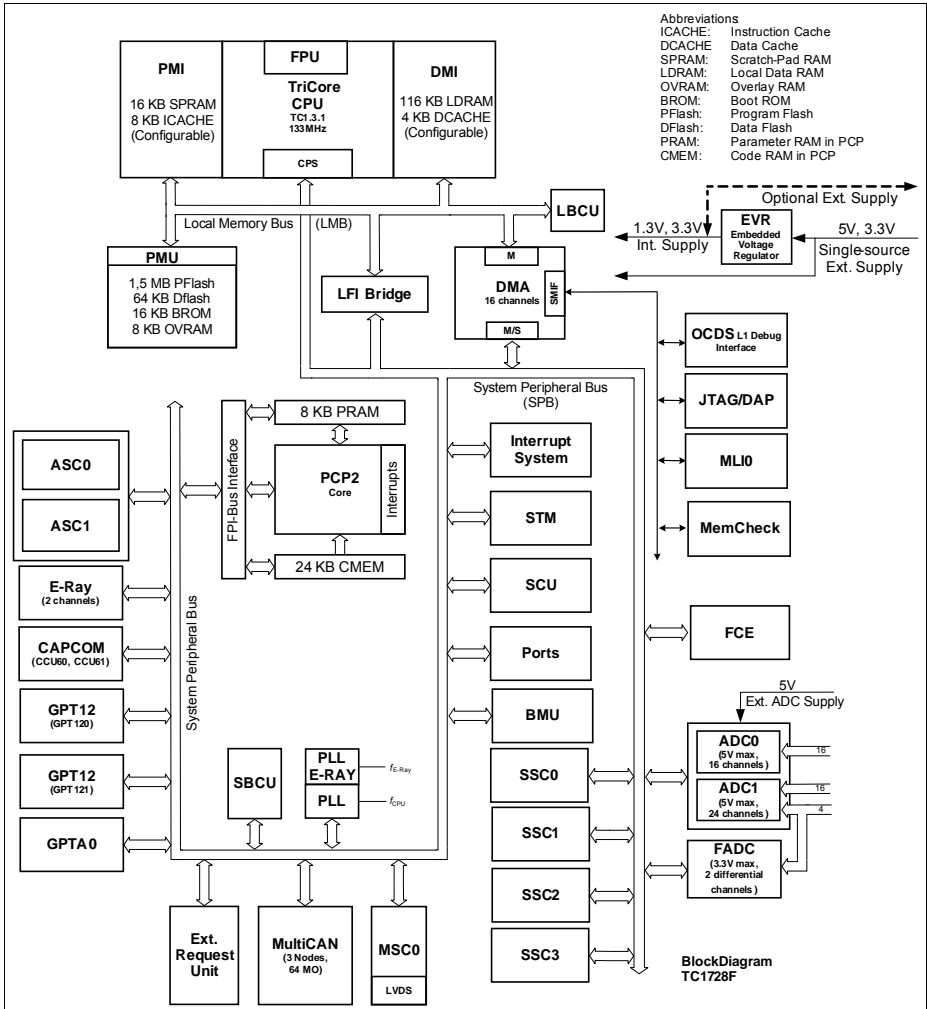


Figure 2 SAK-TC1728F-192F133HR Block Diagram

### 3 Pinning

Figure 3-1 shows the TC1728 Logic Symbol.

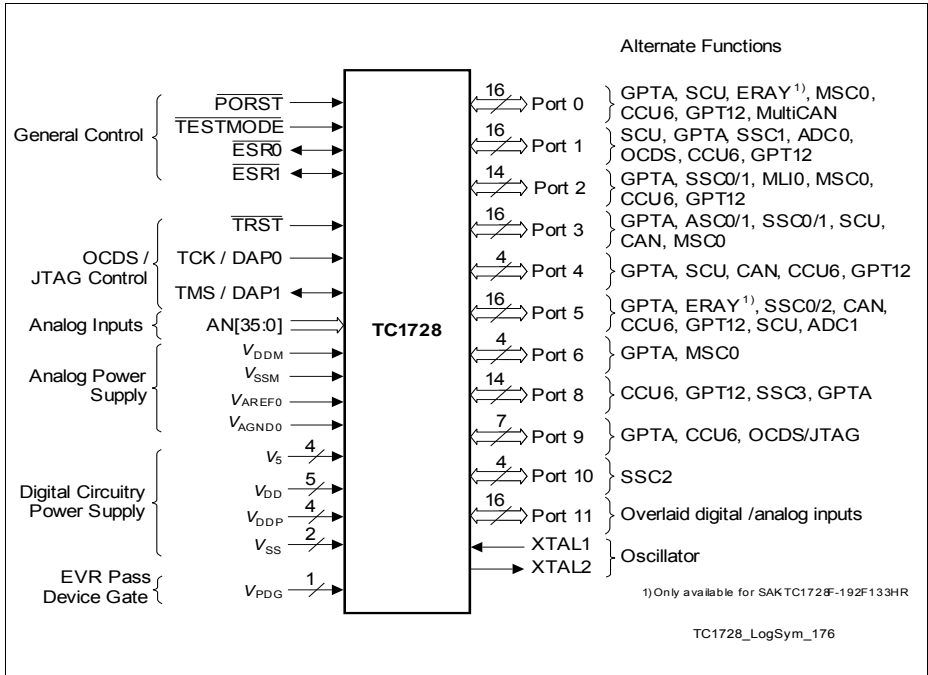


Figure 3-1 TC1728 Logic Symbol

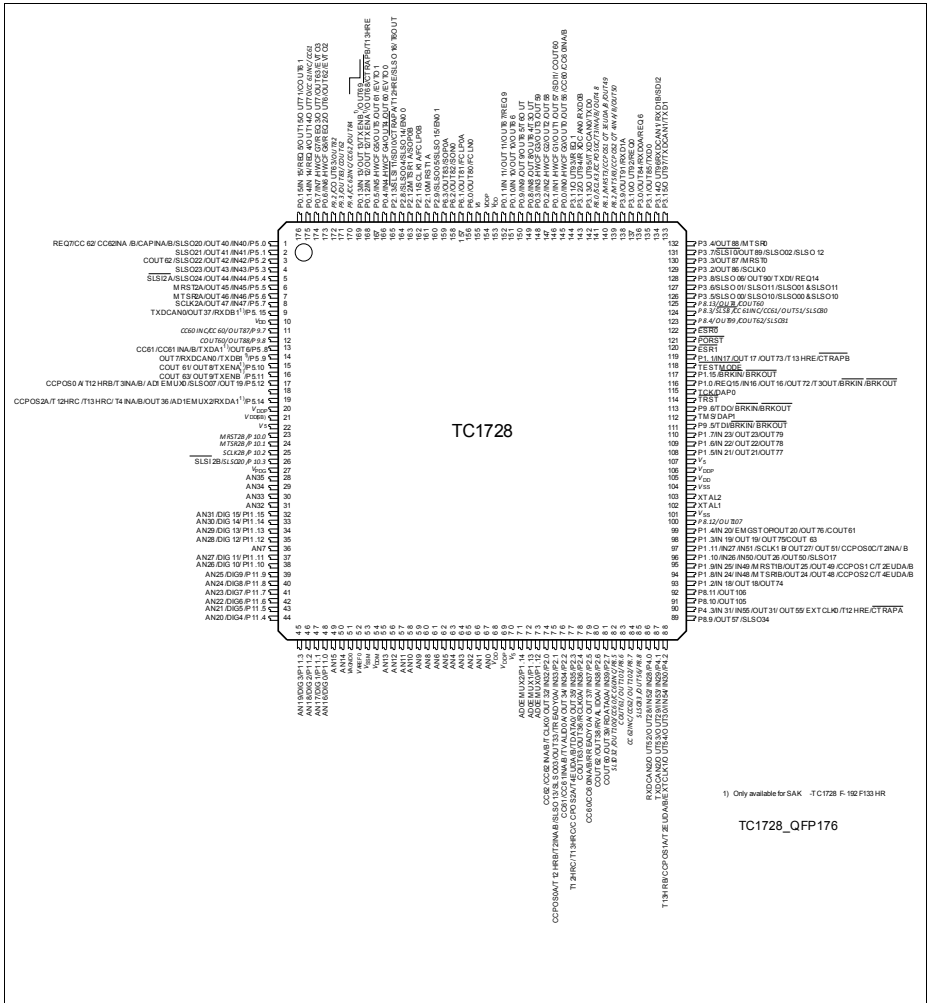


Figure 3-2 SAK-TC1728N-192F133HL / SAK-TC1728N-192F133HR / SAK-TC1728F-192F133HR Pinning

Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package)

Pin	Symbol	Ctrl.	Type	Function
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**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
145	P0.0	I/O0	A1/ PU	<b>Port 0 General Purpose I/O Line 0</b>
	IN0	I		<b>GPTA0 Input 0</b>
	CCU60	I		<b>CC60INA</b>
	CCU61	I		<b>CC60INB</b>
	HWCFG0	I		<b>Hardware Configuration Input 0</b>
	OUT0	O1		<b>GPTA0 Output 0</b>
	OUT56	O2		<b>GPTA0 Output 56</b>
	CCU60	O3		<b>CC60</b>
146	P0.1	I/O0	A1/ PU	<b>Port 0 General Purpose I/O Line 1</b>
	IN1	I		<b>GPTA0 Input 1</b>
	SDI1	I		<b>MSC0 Serial Data Input 1</b>
	HWCFG1	I		<b>Hardware Configuration Input 1</b>
	OUT1	O1		<b>GPTA0 Output 1</b>
	OUT57	O2		<b>GPTA0 Output 57</b>
	CCU60	O3		<b>COOUT60</b>
147	P0.2	I/O0	A1/ PU	<b>Port 0 General Purpose I/O Line 2</b>
	IN2	I		<b>GPTA0 Input 2</b>
	HWCFG2	I		<b>Hardware Configuration Input 2</b>
	OUT2	O1		<b>GPTA0 Output 2</b>
	OUT58	O2		<b>GPTA0 Output 58</b>
	Reserved	O3		-
148	P0.3	I/O0	A1+/ PU	<b>Port 0 General Purpose I/O Line 3</b>
	IN3	I		<b>GPTA0 Input 3</b>
	HWCFG3	I		<b>Hardware Configuration Input 3</b>
	OUT3	O1		<b>GPTA0 Output 3</b>
	OUT59	O2		<b>GPTA0 Output 59</b>
	Reserved	O3		-

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
166	P0.4	I/O0	A1/ PD	<b>Port 0 General Purpose I/O Line 4</b>
	IN4	I		<b>GPTA0 Input 4</b>
	HWCFG4	I		<b>Hardware Configuration Input 4</b>
	OUT4	O1		<b>GPTA0 Output 4</b>
	OUT60	O2		<b>GPTA0 Output 60</b>
	EVT00	O3		<b>MCDS event output 0</b>
167	P0.5	I/O0	A1/ PD	<b>Port 0 General Purpose I/O Line 5</b>
	IN5	I		<b>GPTA0 Input 5</b>
	HWCFG5	I		<b>Hardware Configuration Input 5</b>
	OUT5	O1		<b>GPTA0 Output 5</b>
	OUT61	O2		<b>GPTA0 Output 61</b>
	EVT01	O3		<b>MCDS event output 1</b>
173	P0.6	I/O0	A1/ PU	<b>Port 0 General Purpose I/O Line 6</b>
	IN6	I		<b>GPTA0 Input 6</b>
	HWCFG6	I		<b>Hardware Configuration Input 6</b>
	REQ2	I		<b>External Request Input 2</b>
	OUT6	O1		<b>GPTA0 Output 6</b>
	OUT62	O2		<b>GPTA0 Output 62</b>
	EVT02	O3		<b>MCDS event output 2</b>
174	P0.7	I/O0	A1/ PU	<b>Port 0 General Purpose I/O Line 7</b>
	IN7	I		<b>GPTA0 Input 7</b>
	HWCFG7	I		<b>Hardware Configuration Input 7</b>
	REQ3	I		<b>External Request Input 3</b>
	OUT7	O1		<b>GPTA0 Output 7</b>
	OUT63	O2		<b>GPTA0 Output 63</b>
	EVT03	O3		<b>MCDS event output 3</b>



**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
149	P0.8	I/O0	A1/ PU	<b>Port 0 General Purpose I/O Line 8</b>
	IN8	I		<b>GPTA0 Input 8</b>
	OUT8	O1		<b>GPTA0 Output 8</b>
	OUT64	O2		<b>GPTA0 Output 64</b>
	GPT121	O3		<b>T3OUT</b>
150	P0.9	I/O0	A1/ PU	<b>Port 0 General Purpose I/O Line 9</b>
	IN9	I		<b>GPTA0 Input 9</b>
	OUT9	O1		<b>GPTA0 Output 9</b>
	OUT65	O2		<b>GPTA0 Output 65</b>
	GPT121	O3		<b>T6OUT</b>
151	P0.10	I/O0	A2/ PU	<b>Port 0 General Purpose I/O Line 10</b>
	IN10	I		<b>GPTA0 Input 10</b>
	OUT10	O1		<b>GPTA0 Output 10</b>
	OUT66	O2		<b>GPTA0 Output 66</b>
	Reserved	O3		-
152	P0.11	I/O0	A2/ PU	<b>Port 0 General Purpose I/O Line 11</b>
	IN11	I		<b>GPTA0 Input 11</b>
	REQ9	I		<b>External Request Input 9</b>
	OUT11	O1		<b>GPTA0 Output 11</b>
	OUT67	O2		<b>GPTA0 Output 67</b>
Reserved	O3	-		
168	P0.12	I/O0	A2/ PU	<b>Port 0 General Purpose I/O Line 12</b>
	IN12	I		<b>GPTA0 Input 12</b>
	CCU60	I		<b>CTRAPB</b>
	CCU61	I		<b>T13HRE</b>
	OUT12	O1		<b>GPTA0 Output 12</b>
	OUT68	O2		<b>GPTA0 Output 68</b>
	TXENA	O3		<b>E-Ray Channel A transmit Data Output enable<sup>1)</sup></b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
169	P0.13	I/O0	A2/ PU	Port 0 General Purpose I/O Line 13
	IN13	I		GPTA0 Input 13
	OUT13	O1		GPTA0 Output 13
	OUT69	O2		GPTA0 Output 69
	TXENB	O3		E-Ray Channel B transmit Data Output enable <sup>1)</sup>
175	P0.14	I/O0	A1+/ PU	Port 0 General Purpose I/O Line 14
	IN14	I		GPTA0 Input 14
	REQ4	I		External Request Input 4
	CCU61	I		CC61INC
	OUT14	O1		GPTA0 Output 14
	OUT70	O2		GPTA0 Output 70
	CCU60	O3		CC61
176	P0.15	I/O0	A1+/ PU	Port 0 General Purpose I/O Line 15
	IN15	I		GPTA0 Input 15
	REQ5	I		External Request Input 5
	OUT15	O1		GPTA0 Output 15
	OUT71	O2		GPTA0 Output 71
	CCU60	O3		COUT61
<b>Port 1</b>				
116	P1.0	I/O0	A2/ PU	Port 1 General Purpose I/O Line 0
	REQ15	I		External Request Input 15
	IN16	I		GPTA0 Input 16
	BRKIN	I		Break Input
	OUT16	O1		GPTA0 Output 16
	OUT72	O2		GPTA0 Output 72
	GPT120	O3		T3OUT
	BRKOUT	O		Break Output (controlled by OCDS module)

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
119	P1.1	I/O0	A1/ PU	<b>Port 1 General Purpose I/O Line 1</b>
	IN17	I		<b>GPTA0 Input 17</b>
	CCU60	I		<b>T13HRE</b>
	CCU61	I		<b>CTRAPB</b>
	OUT17	O1		<b>GPTA0 Output 17</b>
	OUT73	O2		<b>GPTA0 Output 73</b>
	Reserved	O3		-
93	P1.2	I/O0	A1/ PU	<b>Port 1 General Purpose I/O Line 2</b>
	IN18	I		<b>GPTA0 Input 18</b>
	OUT18	O1		<b>GPTA0 Output 18</b>
	OUT74	O2		<b>GPTA0 Output 74</b>
	Reserved	O3		-
98	P1.3	I/O0	A1/ PU	<b>Port 1 General Purpose I/O Line 3</b>
	IN19	I		<b>GPTA0 Input 19</b>
	OUT19	O1		<b>GPTA0 Output 19</b>
	OUT75	O2		<b>GPTA0 Output 75</b>
	CCU61	O3		<b>COUT63</b>
99	P1.4	I/O0	A1/ PU	<b>Port 1 General Purpose I/O Line 4</b>
	IN20	I		<b>GPTA0 Input 20</b>
	EMGSTOP	I		<b>Emergency Stop Input</b>
	OUT20	O1		<b>GPTA0 Output 20</b>
	OUT76	O2		<b>GPTA0 Output 76</b>
	CCU61	O3		<b>COUT61</b>
108	P1.5	I/O0	A1/ PU	<b>Port 1 General Purpose I/O Line 35</b>
	IN21	I		<b>GPTA0 Input 21</b>
	OUT21	O1		<b>GPTA0 Output 21</b>
	OUT77	O2		<b>GPTA0 Output 77</b>
	Reserved	O3		-

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
109	P1.6	I/O0	A1/ PU	<b>Port 1 General Purpose I/O Line 6</b>
	IN22	I		<b>GPTA0 Input 22</b>
	OUT22	O1		<b>GPTA0 Output 22</b>
	OUT78	O2		<b>GPTA0 Output 78</b>
	Reserved	O3		-
110	P1.7	I/O0	A1/ PU	<b>Port 1 General Purpose I/O Line 7</b>
	IN23	I		<b>GPTA0 Input 23</b>
	OUT23	O1		<b>GPTA0 Output 23</b>
	OUT79	O2		<b>GPTA0 Output 79</b>
	Reserved	O3		-
94	P1.8	I/O0	A1+/ PU	<b>Port 1 General Purpose I/O Line 8</b>
	IN24	I		<b>GPTA0 Input 24</b>
	IN48	I		<b>GPTA0 Input 48</b>
	MTRS1B	I		<b>SSC1 Slave Receive Input B (Slave Mode)</b>
	CCU61	I		<b>CCPOS2C</b>
	GPT120	I		<b>T4EUDB</b>
	GPT121	I		<b>T4EUDA</b>
	OUT24	O1		<b>GPTA0 Output 24</b>
	OUT48	O2		<b>GPTA0 Output 48</b>
	MTRS1B	O3		<b>SSC1 Master Transmit Output B (Master Mode)</b>
95	P1.9	I/O0	A1+/ PU	<b>Port 1 General Purpose I/O Line 9</b>
	IN25	I		<b>GPTA0 Input 25</b>
	IN49	I		<b>GPTA0 Input 49</b>
	MRST1B	I		<b>SSC1 Master Receive Input B (Master Mode)</b>
	CCU61	I		<b>CCPOS1C</b>
	GPT120	I		<b>T2EUDB</b>
	GPT121	I		<b>T2EUDA</b>
	OUT25	O1		<b>GPTA0 Output 25</b>
	OUT49	O2		<b>GPTA0 Output 49</b>
	MRST1B	O3		<b>SSC1 Slave Transmit Output B (Slave Mode)</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
96	P1.10	I/O0	A1+/ PU	<b>Port 1 General Purpose I/O Line 10</b>
	IN26	I		<b>GPTA0 Input 26</b>
	IN50	I		<b>GPTA0 Input 50</b>
	OUT26	O1		<b>GPTA0 Output 26</b>
	OUT50	O2		<b>GPTA0 Output 50</b>
	SLSO17	O3		<b>SSC1 Slave Select Output 7</b>
97	P1.11	I/O0	A1+/ PU	<b>Port 1 General Purpose I/O Line 11</b>
	IN27	I		<b>GPTA0 Input 27</b>
	IN51	I		<b>GPTA0 Input 51</b>
	SCLK1B	I		<b>SSC1 Clock Input B</b>
	CCU61	I		<b>CCPOS0C</b>
	GPT120	I		<b>T2INB</b>
	GPT121	I		<b>T2INA</b>
	OUT27	O1		<b>GPTA0 Output 27</b>
	OUT51	O2		<b>GPTA0 Output 51</b>
	SCLK1B	O3		<b>SSC1 Clock Output B</b>
	73	P1.12		I/O0
AD0EMUX0		O1	<b>ADC0 External Multiplexer Control Output 0</b>	
Reserved		O2	-	
Reserved		O3	-	
72	P1.13	I/O0	A1/ PU	<b>Port 1 General Purpose I/O Line 13</b>
	AD0EMUX1	O1		<b>ADC0 External Multiplexer Control Output 1</b>
	Reserved	O2		-
	Reserved	O3		-
71	P1.14	I/O0	A1/ PU	<b>Port 1 General Purpose I/O Line 14</b>
	AD0EMUX2	O1		<b>ADC0 External Multiplexer Control Output 2</b>
	Reserved	O2		-
	Reserved	O3		-

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
117	P1.15	I/O0	A2/ PU	<b>Port 1 General Purpose I/O Line 15</b>
	BRKIN	I		<b>Break Input</b>
	Reserved	O1		-
	Reserved	O2		-
	Reserved	O3		-
	BRKOUT	O		<b>Break Output (controlled by OCDS module)</b>
<b>Port 2</b>				
74	P2.0	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 0</b>
	IN32	I		<b>GPTA0 Input 32</b>
	CCU60	I		<b>CC62INB</b>
	CCU61	I		<b>CC62INA</b>
	OUT32	O1		<b>GPTA0 Output 32</b>
	TCLK0	O2		<b>MLI0 Transmitter Clock Output 0</b>
	CCU61	O3		<b>CC62</b>
75	P2.1	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 1</b>
	IN33	I		<b>GPTA0 Input 33</b>
	TREADY0A	I		<b>MLI0 Transmitter Ready Input A</b>
	CCU61	I		<b>CCPOS0A</b>
	CCU60	I		<b>T12HRB</b>
	GPT120	I		<b>T2INA</b>
	GPT121	I		<b>T2INB</b>
	OUT33	O1		<b>GPTA0 Output 33</b>
	SLSO03	O2		<b>SSC0 Slave Select Output Line 3</b>
	SLSO13	O3		<b>SSC1 Slave Select Output Line 3</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

<b>Pin</b>	<b>Symbol</b>	<b>Ctrl.</b>	<b>Type</b>	<b>Function</b>
76	P2.2	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 2</b>
	IN34	I		<b>GPTA0 Input 34</b>
	CCU60	I		<b>CC61INB</b>
	CCU61	I		<b>CC61INA</b>
	OUT34	O1		<b>GPTA0 Output 34</b>
	TVALID0A	O2		<b>MLI0 Transmitter Valid Output</b>
	CCU61	O3		<b>CC61</b>
77	P2.3	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 3</b>
	IN35	I		<b>GPTA0 Input 35</b>
	CCU60	I		<b>T12HRC</b>
	CCU60	I		<b>T13HRC</b>
	CCU61	I		<b>CCPOS2A</b>
	GPT120	I		<b>T4EUDA</b>
	GPT121	I		<b>T4EUDB</b>
	OUT35	O1		<b>GPTA0 Output 35</b>
	TDATA0	O2		<b>MLI0 Transmitter Data Output</b>
	Reserved	O3		-
78	P2.4	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 4</b>
	IN36	I		<b>GPTA0 Input 36</b>
	RCLK0A	I		<b>MLI Receiver Clock Input A</b>
	OUT36	O1		<b>GPTA0 Output 36</b>
	CCU61	O2		<b>COUT63</b>
	Reserved	O3		-
79	P2.5	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 5</b>
	IN37	I		<b>GPTA0 Input 37</b>
	CCU60	I		<b>CC60INB</b>
	CCU61	I		<b>CC60INA</b>
	OUT37	O1		<b>GPTA0 Output 37</b>
	RREADY0A	O2		<b>MLI0 Receiver Ready Output A</b>
	CCU61	O3		<b>CC60</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
80	P2.6	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 6</b>
	IN38	I		<b>GPTA0 Input 38</b>
	RVALID0A	I		<b>MLI Receiver Valid Input A</b>
	OUT38	O1		<b>GPTA0 Output 38</b>
	CCU61	O2		<b>COU62</b>
	Reserved	O3		-
81	P2.7	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 7</b>
	RDATA0A	I		<b>MLI Receiver Data Input A</b>
	IN39	I		<b>GPTA0 Input 39</b>
	OUT39	O1		<b>GPTA0 Output 39</b>
	CCU61	O2		<b>COU60</b>
	Reserved	O3		-
164	P2.8	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 8</b>
	SLSO04	O1		<b>SSC0 Slave Select Output 4</b>
	SLSO14	O2		<b>SSC1 Slave Select Output 4</b>
	EN00	O3		<b>MSC0 Enable Output 0</b>
160	P2.9	I/O0	A2/ PU	<b>Port 2 General Purpose I/O Line 9</b>
	SLSO05	O1		<b>SSC0 Slave Select Output 5</b>
	SLSO15	O2		<b>SSC1 Slave Select Output 5</b>
	EN01	O3		<b>MSC0 Enable Output 1</b>
161	P2.10	I/O0	A1+/ PU	<b>Port 2 General Purpose I/O Line 10</b>
	MRST1A	I		<b>SSC1 Master Receive Input A</b>
	MRST1A	O1		<b>SSC1 Slave Transmit Output</b>
	Reserved	O2		-
	Reserved	O3		-
162	P2.11	I/O0	A1+/ PU	<b>Port 2 General Purpose I/O Line 11</b>
	SCLK1A	I		<b>SSC1 Clock Input A</b>
	SCLK1A	O1		<b>SSC1 Clock Output A</b>
	Reserved	O2		-
	FCLP0B	O3		<b>MSC0 Clock Output Positive B</b>



**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
163	P2.12	I/O0	A1+/ PU	<b>Port 2 General Purpose I/O Line 12</b>
	MTSR1A	I		<b>SSC1 Slave Receive Input A</b>
	MTSR1A	O1		<b>SSC1 Master Transmit Output A</b>
	Reserved	O2		-
	SOP0B	O3		<b>MSC0 Serial Data Output Positive B</b>
165	P2.13	I/O0	A1+/ PU	<b>Port 2 General Purpose I/O Line 13</b>
	SLSI11	I		<b>SSC1 Slave Select Input 1</b>
	SDI0	I		<b>MSC0 Serial Data Input 0</b>
	CCU60	I		<b>CTRAPA</b>
	CCU61	I		<b>T12HRE</b>
	Reserved	O1		-
	SLSO16	O2		<b>SSC1 Slave Select Output 6</b>
	GPT120	O3		<b>T6OUT</b>
<b>Port 3</b>				
136	P3.0	I/O0	A1+/ PU	<b>Port 3 General Purpose I/O Line 0</b>
	RXD0A	I		<b>ASC0 Receiver Input A (Async. &amp; Sync. Mode)</b>
	REQ6	I		<b>External Request Input 6</b>
	RXD0A	O1		<b>ASC0 Output (Sync. Mode)</b>
	Reserved	O2		-
	OUT84	O3		<b>GPTA0 Output 84</b>
135	P3.1	I/O0	A1+/ PU	<b>Port 3 General Purpose I/O Line 1</b>
	TXD0	O1		<b>ASC0 Output</b>
	Reserved	O2		-
	OUT85	O3		<b>GPTA0 Output 85</b>
129	P3.2	I/O0	A1+/ PU	<b>Port 3 General Purpose I/O Line 2</b>
	SCLK0	I		<b>SSC0 Clock Input (Slave Mode)</b>
	SCLK0	O1		<b>SSC0 Clock Output (Master Mode)</b>
	Reserved	O2		-
	OUT86	O3		<b>GPTA0 Output 86</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
130	P3.3	I/O0	A1+/ PU	<b>Port 3 General Purpose I/O Line 3</b>
	MRST0	I		<b>SSC0 Master Receive Input (Master Mode)</b>
	MRST0	O1		<b>SSC0 Slave Transmit Output (Slave Mode)</b>
	Reserved	O2		-
	OUT87	O3		<b>GPTA0 Output 87</b>
132	P3.4	I/O0	A2/ PU	<b>Port 3 General Purpose I/O Line 4</b>
	MTSR0	I		<b>SSC0 Slave Receive Input (Slave Mode)</b>
	MTSR0	O1		<b>SSC0 Master Transmit Output (Master Mode)</b>
	Reserved	O2		-
	OUT88	O3		<b>GPTA0 Output 88</b>
126	P3.5	I/O0	A1+/ PU	<b>Port 3 General Purpose I/O Line 5</b>
	SLSO00	O1		<b>SSC0 Slave Select Output 0</b>
	SLSO10	O2		<b>SSC1 Slave Select Output 0</b>
	SLSOAND00	O3		<b>SSC0 AND SSC1 Slave Select Output 0</b>
127	P3.6	I/O0	A1+/ PU	<b>Port 3 General Purpose I/O Line 6</b>
	SLSO01	O1		<b>SSC0 Slave Select Output 1</b>
	SLSO11	O2		<b>SSC1 Slave Select Output 1</b>
	SLSOAND01	O3		<b>SSC0 AND SSC1 Slave Select Output 1</b>
131	P3.7	I/O0	A2/ PU	<b>Port 3 General Purpose I/O Line 7</b>
	SLSI0	I		<b>SSC0 Slave Select Input 1</b>
	SLSO02	O1		<b>SSC0 Slave Select Output 2</b>
	SLSO12	O2		<b>SSC1 Slave Select Output 2</b>
	OUT89	O3		<b>GPTA0 Output 89</b>
128	P3.8	I/O0	A2/ PU	<b>Port 3 General Purpose I/O Line 8</b>
	REQ14	I		<b>External Request Input 14</b>
	SLSO06	O1		<b>SSC0 Slave Select Output 6</b>
	TXD1	O2		<b>ASC1 Transmit Output</b>
	OUT90	O3		<b>GPTA0 Output 90</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
138	P3.9	I/O0	A1/ PU	<b>Port 3 General Purpose I/O Line 9</b>
	RXD1A	I		<b>ASC1 Receiver Input A</b>
	RXD1A	O1		<b>ASC1 Receiver Output A (Synchronous Mode)</b>
	Reserved	O2		-
	OUT91	O3		<b>GPTA0 Output 91</b>
137	P3.10	I/O0	A1/ PU	<b>Port 3 General Purpose I/O Line 10</b>
	REQ0	I		<b>External Request Input 0</b>
	Reserved	O1		-
	Reserved	O2		-
	OUT92	O3		<b>GPTA0 Output 92</b>
144	P3.11	I/O0	A1/ PU	<b>Port 3 General Purpose I/O Line 11</b>
	REQ1	I		<b>External Request Input 1</b>
	Reserved	O1		-
	Reserved	O2		-
	OUT93	O3		<b>GPTA0 Output 93</b>
143	P3.12	I/O0	A1/ PU	<b>Port 3 General Purpose I/O Line 12</b>
	RXDCAN0	I		<b>CAN Node 0 Receiver Input</b>
	RXD0B	I		<b>ASC0 Receiver Input B</b>
	RXD0B	O1		<b>ASC0 Receiver Output B (Synchronous Mode)</b>
	Reserved	O2		-
	OUT94	O3		<b>GPTA0 Output 94</b>
142	P3.13	I/O0	A2/ PU	<b>Port 3 General Purpose I/O Line 13</b>
	TXDCAN0	O1		<b>CAN Node 0 Transmitter Output</b>
	TXD0	O2		<b>ASC0 Transmit Output</b>
	OUT95	O3		<b>GPTA0 Output 95</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
134	P3.14	I/O0	A1/ PU	<b>Port 3 General Purpose I/O Line 14</b>
	RXDCAN1	I		<b>CAN Node 1 Receiver Input</b>
	RXD1B	I		<b>ASC1 Receiver Input B</b>
	SDI2	I		<b>MSC0 Serial Data Input 2</b>
	RXD1B	O1		<b>ASC1 Receiver Output B (Synchronous Mode)</b>
	Reserved	O2		-
	OUT96	O3		<b>GPTA0 Output 96</b>
133	P3.15	I/O0	A2/ PU	<b>Port 3 General Purpose I/O Line 15</b>
	TXDCAN1	O1		<b>CAN Node 1 Transmitter Output</b>
	TXD1	O2		<b>ASC1 Transmit Output</b>
	OUT97	O3		<b>GPTA0 Output 97</b>
<b>Port 4</b>				
86	P4.0	I/O0	A1+/ PU	<b>Port 4 General Purpose I/O Line 0</b>
	IN28	I		<b>GPTA0 Input 28</b>
	IN52	I		<b>GPTA0 Input 52</b>
	RXDCAN2	I		<b>CAN Node 2 Receiver Input</b>
	OUT28	O1		<b>GPTA0 Output 28</b>
	OUT52	O2		<b>GPTA0 Output 52</b>
	Reserved	O3		-
87	P4.1	I/O0	A1+/ PU	<b>Port 4 General Purpose I/O Line 1</b>
	IN29	I		<b>GPTA0 Input 29</b>
	IN53	I		<b>GPTA0 Input 53</b>
	OUT29	O1		<b>GPTA0 Output 29</b>
	OUT53	O2		<b>GPTA0 Output 53</b>
	TXDCAN2	O3		<b>CAN Node 2 Transmitter Output</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
88	P4.2	I/O0	A2/ PU	<b>Port 4 General Purpose I/O Line 2</b>
	IN30	I		<b>GPTA0 Input 30</b>
	IN54	I		<b>GPTA0 Input 54</b>
	CCU60	I		<b>T13HRB</b>
	CCU61	I		<b>CCPOS1A</b>
	GPT120	I		<b>T2EUDA</b>
	GPT121	I		<b>T2EUDB</b>
	OUT30	O1		<b>GPTA0 Output 30</b>
	OUT54	O2		<b>GPTA0 Output 54</b>
	EXTCLK1	O3		<b>External Clock 1 Output</b>
90	P4.3	I/O0	A2/ PU	<b>Port 4 General Purpose I/O Line 3</b>
	IN31	I		<b>GPTA0 Input 31</b>
	IN55	I		<b>GPTA0 Input 55</b>
	CCU60	I		<b>T12HRE</b>
	CCU61	I		<b>CTRAPA</b>
	OUT31	O1		<b>GPTA0 Output 31</b>
	OUT55	O2		<b>GPTA0 Output 55</b>
	EXTCLK0	O3		<b>External Clock 0 Output</b>
<b>Port 5</b>				
1	P5.0	I/O0	A1+/ PU	<b>Port 5 General Purpose I/O Line 0</b>
	REQ7	I		<b>External Request Input 7</b>
	IN40	I		<b>GPTA0 Input 40</b>
	CCU60	I		<b>CC62INA</b>
	CCU61	I		<b>CC62INB</b>
	GPT120	I		<b>CAPINB</b>
	GPT121	I		<b>CAPINA</b>
	OUT40	O1		<b>GPTA0 Output 40</b>
	CCU60	O2		<b>CC62</b>
	SLSO20	O3		<b>SSC2 Slave Select Output 0</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
2	P5.1	I/O0	A1+/ PU	<b>Port 5 General Purpose I/O Line 1</b>
	IN41	I		<b>GPTA0 Input 41</b>
	OUT41	O1		<b>GPTA0 Output 41</b>
	Reserved	O2		-
	SLSO21	O3		<b>SSC2 Slave Select Output 1</b>
3	P5.2	I/O0	A1+/ PU	<b>Port 5 General Purpose I/O Line 2</b>
	IN42	I		<b>GPTA0 Input 42</b>
	OUT42	O1		<b>GPTA0 Output 42</b>
	CCU60	O2		<b>COU62</b>
	SLSO22	O3		<b>SSC2 Slave Select Output 2</b>
4	P5.3	I/O0	A1+/ PU	<b>Port 5 General Purpose I/O Line 3</b>
	IN43	I		<b>GPTA0 Input 43</b>
	OUT43	O1		<b>GPTA0 Output 43</b>
	Reserved	O2		-
	SLSO23	O3		<b>SSC2 Slave Select Output 3</b>
5	P5.4	I/O0	A1+/ PU	<b>Port 5 General Purpose I/O Line 4</b>
	IN44	I		<b>GPTA0 Input 44</b>
	SLSI2A	I		<b>SSC2 Slave Select Input A</b>
	OUT44	O1		<b>GPTA0 Output 44</b>
	Reserved	O2		-
	SLSO24	O3		<b>SSC2 Slave Select Output 4</b>
6	P5.5	I/O0	A1+/ PU	<b>Port 5 General Purpose I/O Line 5</b>
	IN45	I		<b>GPTA0 Input 45</b>
	MRST2A	I		<b>SSC2 Master Receive Input A (Master Mode)</b>
	OUT45	O1		<b>GPTA0 Output 45</b>
	Reserved	O2		-
	MRST2	O3		<b>SSC2 Slave Transmit Output (Slave Mode)</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
7	P5.6	I/O0	A1+/PU	<b>Port 5 General Purpose I/O Line 6</b>
	IN46	I		<b>GPTA0 Input 46</b>
	MTSR2A	I		<b>SSC2 Slave Receive Input (Slave Mode)</b>
	OUT46	O1		<b>GPTA0 Output 46</b>
	Reserved	O2		-
	MTSR2	O3		<b>SSC2 Master Transmit Output (Master Mode)</b>
8	P5.7	I/O0	A1+/PU	<b>Port 5 General Purpose I/O Line 7</b>
	IN47	I		<b>GPTA0 Input 47</b>
	SCLK2A	I		<b>SSC2 Clock Input A (Slave Mode)</b>
	OUT47	O1		<b>GPTA0 Output 47</b>
	Reserved	O2		-
	SCLK2	O3		<b>SSC2 Clock Output (Master Mode)</b>
13	P5.8	I/O0	A2/PU	<b>Port 5 General Purpose I/O Line 8</b>
	CCU60	I		<b>CC61INA</b>
	CCU61	I		<b>CC61INB</b>
	OUT6	O1		<b>GPTA0 Output 6</b>
	TXDA1	O2		<b>E-Ray Channel A transmit Data Output<sup>1)</sup></b>
	CCU60	O3		<b>CC61</b>
14	P5.9	I/O0	A2/PU	<b>Port 5 General Purpose I/O Line 9</b>
	RXDCAN0	I		<b>CAN Node 0 Receiver Input</b>
	OUT7	O1		<b>GPTA0 Output 7</b>
	TXDB1	O2		<b>E-Ray Channel B transmit Data Output<sup>1)</sup></b>
	Reserved	O3		-
15	P5.10	I/O0	A2/PU	<b>Port 5 General Purpose I/O Line 10</b>
	OUT8	O1		<b>GPTA0 Output 8</b>
	TXENA	O2		<b>E-Ray Channel A transmit Data Output enable<sup>1)</sup></b>
	CCU60	O3		<b>COUT61</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
16	P5.11	I/O0	A2/ PU	Port 5 General Purpose I/O Line 11
	OUT9	O1		GPTA0 Output 9
	TXENB	O2		E-Ray Channel B transmit Data Output enable <sup>1)</sup>
	CCU60	O3		COU63
17	P5.12	I/O0	A1+/ PU	Port 5 General Purpose I/O Line 12
	CCU60	I		CCPOS0A
	CCU61	I		T12HRB
	GPT120	I		T3INA
	GPT121	I		T3INB
	OUT19	O1		GPTA0 Output 19
	SLSO07	O2		SSC0 Slave Select Output 7
	AD1EMUX0	O3		ADC1 External Multiplexer Control Output 0
18	P5.13	I/O0	A1+/ PU	Port 5 General Purpose I/O Line 13
	CCU60	I		CCPOS1A
	CCU61	I		T13HRB
	GPT120	I		T3EUDA
	GPT121	I		T3EADB
	OUT20	O1		GPTA0 Output 20
	Reserved	O2		-
	AD1EMUX1	O3		ADC1 External Multiplexer Control Output 1
19	P5.14	I/O0	A1+/ PU	Port 5 General Purpose I/O Line 14
	RXDA1	I		E-Ray Channel A Receive Data Input 1 <sup>1)</sup>
	CCU60	I		CCPOS2A
	CCU61	I		T12HRC
	CCU61	I		T13HRC
	GPT120	I		T4INA
	GPT121	I		T4INB
	OUT36	O1		GPTA0 Output 36
	Reserved	O2		-
	AD1EMUX2	O3		ADC1 External Multiplexer Control Output 2



**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
9	P5.15	I/O0	A1+/ PU	<b>Port 5 General Purpose I/O Line 15</b>
	RXDB1	I		<b>E-Ray Channel B Receive Data Input 1<sup>1)</sup></b>
	OUT37	O1		<b>GPTA0 Output 37</b>
	Reserved	O2		-
	TXDCAN0	O3		<b>CAN Node 0 Transmitter Output</b>
<b>Port 6</b>				
156	P6.0	I/O0	F/ PU	<b>Port 6 General Purpose I/O Line 0</b>
	FCLN0	O1		<b>MSC0 Clock Output Negative</b>
	OUT80	O2		<b>GPTA0 Output 80</b>
	Reserved	O3		-
157	P6.1	I/O0	F/ PU	<b>Port 6 General Purpose I/O Line 1</b>
	FCLP0A	O1		<b>MSC0 Clock Output Positive A</b>
	OUT81	O2		<b>GPTA0 Output 81</b>
	Reserved	O3		-
158	P6.2	I/O0	F/ PU	<b>Port 6 General Purpose I/O Line 2</b>
	SON0	O1		<b>MSC0 Serial Data Output Negative</b>
	OUT82	O2		<b>GPTA0 Output 82</b>
	Reserved	O3		-
159	P6.3	I/O0	F/ PU	<b>Port 6 General Purpose I/O Line 3</b>
	SOP0A	O1		<b>MSC0 Serial Data Output Positive A</b>
	OUT83	O2		<b>GPTA0 Output 83</b>
	Reserved	O3		-
<b>Port 8</b>				

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
141	P8.0	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 0</b>
	SCLK3	I		<b>SSC3 Clock Input (Slave Mode)</b>
	CCU60	I		<b>CCPOS0C</b>
	GPT120	I		<b>T3INB</b>
	GPT121	I		<b>T3INA</b>
	Reserved	O1		-
	OUT48	O2		<b>GPTA0 Output 48</b>
	SCLK3	O3		<b>SSC3 Clock Output (Master Mode)</b>
140	P8.1	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 1</b>
	MRST3	I		<b>SSC3 Master Receive Input (Master Mode)</b>
	CCU60	I		<b>CCPOS1C</b>
	GPT120	I		<b>T3EADB</b>
	GPT121	I		<b>T3EUDA</b>
	Reserved	O1		-
	OUT49	O2		<b>GPTA0 Output 49</b>
	MRST3	O3		<b>SSC3 Slave Transmit Output (Slave Mode)</b>
139	P8.2	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 2</b>
	MTRS3	I		<b>SSC3 Slave Receive Input (Slave Mode)</b>
	CCU60	I		<b>CCPOS2C</b>
	GPT120	I		<b>T4INB</b>
	GPT121	I		<b>T4INA</b>
	Reserved	O1		-
	OUT50	O2		<b>GPTA0 Output 50</b>
	MTRS3	O3		<b>SSC3 Master Transmit Output (Master Mode)</b>
124	P8.3	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 3</b>
	SLSI3	I		<b>SSC3 Slave Select Input B</b>
	CCU60	I		<b>CC61INC</b>
	CCU61	O1		<b>CC61</b>
	OUT51	O2		<b>GPTA0 Output 51</b>
	SLSO30	O3		<b>SSC3 Slave Select Output 0</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
123	P8.4	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 4</b>
	OUT99	O1		<b>GPTA0 Output 99</b>
	CCU61	O2		<b>COUT62</b>
	SLSO31	O3		<b>SSC3 Slave Select Output 1</b>
82	P8.5	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 5</b>
	CCU60	I		<b>CC60INC</b>
	OUT100	O1		<b>GPTA0 Output 100</b>
	CCU61	O2		<b>CC60</b>
	SLSO32	O3		<b>SSC3 Slave Select Output 2</b>
83	P8.6	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 6</b>
	OUT101	O1		<b>GPTA0 Output 101</b>
	Reserved	O2		-
	CCU61	O3		<b>COUT61</b>
84	P8.7	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 7</b>
	CCU60	I		<b>CC62INC</b>
	OUT102	O1		<b>GPTA0 Output 102</b>
	Reserved	O2		-
	CCU61	O3		<b>CC62</b>
85	P8.8	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 8</b>
	Reserved	O1		-
	OUT56	O2		<b>GPTA0 Output 56</b>
	SLSO33	O3		<b>SSC3 Slave Select Output 3</b>
89	P8.9	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 9</b>
	Reserved	O1		-
	OUT57	O2		<b>GPTA0 Output 57</b>
	SLSO34	O3		<b>SSC3 Slave Select Output 4</b>
91	P8.10	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 10</b>
	OUT105	O1		<b>GPTA0 Output 105</b>
	Reserved	O2		-
	Reserved	O3		-

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
92	P8.11	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 11</b>
	OUT106	O1		<b>GPTA0 Output 106</b>
	Reserved	O2		-
	Reserved	O3		-
100	P8.12	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 12</b>
	OUT107	O1		<b>GPTA0 Output 107</b>
	Reserved	O2		-
	Reserved	O3		-
125	P8.13	I/O0	A2/ PU	<b>Port 8 General Purpose I/O Line 13</b>
	OUT4	O1		<b>GPTA0 Output 4</b>
	Reserved	O2		-
	CCU61	O3		<b>COUT60</b>
<b>Port 9</b>				
172	P9.2	I/O0	A1/ PU	<b>Port 9 General Purpose I/O Line 2</b>
	Reserved	O1		-
	OUT82	O2		<b>GPTA0 Output 82</b>
	CCU60	O3		<b>COUT63</b>
171	P9.3	I/O0	A1/ PU	<b>Port 9 General Purpose I/O Line 3</b>
	Reserved	O1		-
	OUT83	O2		<b>GPTA0 Output 83</b>
	CCU60	O3		<b>COUT62</b>
170	P9.4	I/O0	A1/ PU	<b>Port 9 General Purpose I/O Line 4</b>
	CCU61	I		<b>CC62INC</b>
	Reserved	O1		-
	OUT84	O2		<b>GPTA0 Output 84</b>
	CCU60	O3		<b>CC62</b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
111	P9.5	I/O0	A2/ PU	<b>Port 9 General Purpose I/O Line 5</b>
	TDI	I		<b>JTAG Serial Data Input</b>
	$\overline{\text{BRKIN}}$	I		<b>OCDS Break Input</b>
	Reserved	O1		-
	Reserved	O2		-
	Reserved	O3		-
	$\overline{\text{BRKOUT}}$	O		<b>OCDS Break Output (controlled by OCDS module)</b>
113	P9.6	I/O0	A2/ PU	<b>Port 9 General Purpose I/O Line 6</b>
	TDO	I		<b>JTAG Serial Data Output</b>
	$\overline{\text{BRKIN}}$	I		<b>OCDS Break Input</b>
	Reserved	O1		-
	Reserved	O2		-
	Reserved	O3		-
	$\overline{\text{BRKOUT}}$	O		<b>OCDS Break Output (controlled by OCDS module)</b>
	TDO	O		<b>JTAG Serial Data Output (controlled by OCDS module)</b>
11	P9.7	I/O0	A1/ PU	<b>Port 9 General Purpose I/O Line 7</b>
	CCU61	I		<b>CC60INC</b>
	Reserved	O1		-
	OUT87	O2		<b>GPTA0 Output 87</b>
	CCU60	O3		<b>CC60</b>
12	P9.8	I/O0	A1/ PU	<b>Port 9 General Purpose I/O Line 7</b>
	Reserved	O1		-
	OUT88	O2		<b>GPTA0 Output 88</b>
	CCU60	O3		<b>COUT60</b>

**Port 10**

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
23	P10.0	I/O0	A2/ PU	<b>Port 10 General Purpose I/O Line 0</b>
	MRST2B	I		<b>SSC2 Master Receive Input B (Master Mode)</b>
	MRST2	O1		<b>SSC2 Slave Transmit Output (Slave Mode)</b>
	Reserved	O2		-
	Reserved	O3		-
24	P10.1	I/O0	A2/ PU	<b>Port 10 General Purpose I/O Line 1</b>
	MTR2B	I		<b>SSC2 Slave Receive Input B (Slave Mode)</b>
	MTR2	O1		<b>SSC2 Master Transmit Output (Master Mode)</b>
	Reserved	O2		-
	Reserved	O3		-
25	P10.2	I/O0	A2/ PU	<b>Port 10 General Purpose I/O Line 2</b>
	SCLK2B	I		<b>SSC2 Clock Input B (Slave Mode)</b>
	SCLK2	O1		<b>SSC2 Clock Output (Master Mode)</b>
	Reserved	O2		-
	Reserved	O3		-
26	P10.3	I/O0	A2/ PU	<b>Port 10 General Purpose I/O Line 3</b>
	SLSI2B	I		<b>SSC2 Slave Select Input B</b>
	SLSO20	O1		<b>SSC2 Slave Select Output 0</b>
	Reserved	O2		-
	Reserved	O3		-

**Port 11**

48	P11.0	I	D / S	<b>Port 11 General Purpose I/O Line 0<sup>2)</sup></b>
	Dig0	I		<b>Digital Input 0</b>
	AN16	I		<b>Analog Input : ADC1.CH0<sup>3)</sup></b>
47	P11.1	I	D / S	<b>Port 11 General Purpose I/O Line 1<sup>2)</sup></b>
	Dig1	I		<b>Digital Input 1</b>
	AN17	I		<b>Analog Input : ADC1.CH1<sup>3)</sup></b>
46	P11.2	I	D / S	<b>Port 11 General Purpose I/O Line 2<sup>2)</sup></b>
	Dig2	I		<b>Digital Input 2</b>
	AN18	I		<b>Analog Input : ADC1.CH2<sup>3)</sup></b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

<b>Pin</b>	<b>Symbol</b>	<b>Ctrl.</b>	<b>Type</b>	<b>Function</b>
45	P11.3	I	D / S	<b>Port 11 General Purpose I/O Line 3<sup>2)</sup></b>
	Dig3	I		<b>Digital Input 3</b>
	AN19	I		<b>Analog Input : ADC1.CH3<sup>3)</sup></b>
44	P11.4	I	D / S	<b>Port 11 General Purpose I/O Line 4<sup>2)</sup></b>
	Dig4	I		<b>Digital Input 4</b>
	AN20	I		<b>Analog Input : ADC1.CH4<sup>3)</sup></b>
43	P11.5	I	D / S	<b>Port 11 General Purpose I/O Line 5<sup>2)</sup></b>
	Dig5	I		<b>Digital Input 5</b>
	AN21	I		<b>Analog Input : ADC1.CH5<sup>3)</sup></b>
42	P11.6	I	D / S	<b>Port 11 General Purpose I/O Line 6<sup>2)</sup></b>
	Dig6	I		<b>Digital Input 6</b>
	AN22	I		<b>Analog Input : ADC1.CH6<sup>3)</sup></b>
41	P11.7	I	D / S	<b>Port 11 General Purpose I/O Line 7<sup>2)</sup></b>
	Dig7	I		<b>Digital Input 7</b>
	AN23	I		<b>Analog Input : ADC1.CH7<sup>3)</sup></b>
40	P11.8	I	D / S	<b>Port 11 General Purpose I/O Line 8<sup>2)</sup></b>
	Dig8	I		<b>Digital Input 8</b>
	AN24	I		<b>Analog Input : ADC1.CH8<sup>3)</sup></b>
39	P11.9	I	D / S	<b>Port 11 General Purpose I/O Line 9<sup>2)</sup></b>
	Dig9	I		<b>Digital Input 9</b>
	AN25	I		<b>Analog Input : ADC1.CH9<sup>3)</sup></b>
38	P11.10	I	D / S	<b>Port 11 General Purpose I/O Line 10<sup>2)</sup></b>
	Dig10	I		<b>Digital Input 10</b>
	AN26	I		<b>Analog Input : ADC1.CH10<sup>3)</sup></b>
37	P11.11	I	D / S	<b>Port 11 General Purpose I/O Line 11<sup>2)</sup></b>
	Dig11	I		<b>Digital Input 11</b>
	AN27	I		<b>Analog Input : ADC1.CH11<sup>3)</sup></b>
35	P11.12	I	D / S	<b>Port 11 General Purpose I/O Line 12<sup>2)</sup></b>
	Dig12	I		<b>Digital Input 12</b>
	AN28	I		<b>Analog Input : ADC1.CH12<sup>3)</sup></b>

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
34	P11.13	I	D / S	<b>Port 11 General Purpose I/O Line 13<sup>2)</sup></b>
	Dig13	I		<b>Digital Input 13</b>
	AN29	I		<b>Analog Input : ADC1.CH13 <sup>3)</sup></b>
33	P11.14	I	D / S	<b>Port 11 General Purpose I/O Line 14<sup>2)</sup></b>
	Dig14	I		<b>Digital Input 14</b>
	AN30	I		<b>Analog Input : ADC1.CH14 <sup>3)</sup></b>
32	P11.15	I	D / S	<b>Port 11 General Purpose I/O Line 15<sup>2)</sup></b>
	Dig15	I		<b>Digital Input 15</b>
	AN31	I		<b>Analog Input : ADC1.CH15 <sup>3)</sup></b>

**Analog Input Port**

67	AN0	I	D	<b>Analog Input 0: ADC0.CH0 <sup>3)</sup></b>
66	AN1	I	D	<b>Analog Input 1: ADC0.CH1 <sup>3)</sup></b>
65	AN2	I	D	<b>Analog Input 2: ADC0.CH2 <sup>3)</sup></b>
64	AN3	I	D	<b>Analog Input 3: ADC0.CH3 <sup>3)</sup></b>
63	AN4	I	D	<b>Analog Input 4: ADC0.CH4 <sup>3)</sup></b>
62	AN5	I	D	<b>Analog Input 5: ADC0.CH5 <sup>3)</sup></b>
61	AN6	I	D	<b>Analog Input 6: ADC0.CH6 <sup>3)</sup></b>
36	AN7	I	D	<b>Analog Input 7: ADC0.CH7 <sup>3)</sup></b>
60	AN8	I	D	<b>Analog Input 8: ADC0.CH8 <sup>3)</sup></b>
59	AN9	I	D	<b>Analog Input 9: ADC0.CH9 <sup>3)</sup></b>
58	AN10	I	D	<b>Analog Input 10: ADC0.CH10 <sup>3)</sup></b>
57	AN11	I	D	<b>Analog Input 11: ADC0.CH11 <sup>3)</sup></b>
56	AN12	I	D	<b>Analog Input 12: ADC0.CH12 <sup>3)</sup></b>
55	AN13	I	D	<b>Analog Input 13: ADC0.CH13 <sup>3)</sup></b>
50	AN14	I	D	<b>Analog Input 14: ADC0.CH14 <sup>3)</sup></b>
49	AN15	I	D	<b>Analog Input 15: ADC0.CH15 <sup>3)</sup></b>
48	AN16	I	D / S	<b>Analog Input 16: ADC1.CH0, Dig0 <sup>3)</sup></b>
47	AN17	I	D / S	<b>Analog Input 17: ADC1.CH1, Dig1 <sup>3)</sup></b>
46	AN18	I	D / S	<b>Analog Input 18: ADC1.CH2, Dig2 <sup>3)</sup></b>
45	AN19	I	D / S	<b>Analog Input 19: ADC1.CH3, Dig3 <sup>3)</sup></b>



**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
44	AN20	I	D / S	Analog Input 20: ADC1.CH4, Dig4 <sup>3)</sup>
43	AN21	I	D / S	Analog Input 21: ADC1.CH5, Dig5 <sup>3)</sup>
42	AN22	I	D / S	Analog Input 22: ADC1.CH6, Dig6 <sup>3)</sup>
41	AN23	I	D / S	Analog Input 23: ADC1.CH7, Dig7 <sup>3)</sup>
40	AN24	I	D / S	Analog Input 24: ADC1.CH8, Dig8 <sup>3)</sup>
39	AN25	I	D / S	Analog Input 25: ADC1.CH9, Dig9 <sup>3)</sup>
38	AN26	I	D / S	Analog Input 26: ADC1.CH10, Dig10 <sup>3)</sup>
37	AN27	I	D / S	Analog Input 27: ADC1.CH11, Dig11 <sup>3)</sup>
35	AN28	I	D / S	Analog Input 28: ADC1.CH12, Dig12 <sup>3)</sup>
34	AN29	I	D / S	Analog Input 29: ADC1.CH13, Dig13 <sup>3)</sup>
33	AN30	I	D / S	Analog Input 30: ADC1.CH14, Dig14 <sup>3)</sup>
32	AN31	I	D / S	Analog Input 31: ADC1.CH15, Dig15 <sup>3)</sup>
31	AN32	I	D	Analog Input 32: FADC_FADIN0P <sup>4)</sup>
30	AN33	I	D	Analog Input 33: FADC_FADIN0N <sup>4)</sup>
29	AN34	I	D	Analog Input 34: FADC_FADIN1P <sup>4)</sup>
28	AN35	I	D	Analog Input 35: FADC_FADIN1N <sup>4)</sup>
54	V <sub>DDM</sub>	-	-	ADC Analog Part Power Supply (3.3V - 5V)
53	V <sub>SSM</sub>	-	-	ADC Analog Part Ground
52	V <sub>AREF0</sub>	-	-	ADC0 and ADC1 Reference Voltage
51	V <sub>AGND0</sub>	-	-	ADC Reference Ground
10, 21 <sup>5)</sup> , 68, 105, 153	V <sub>DD</sub>	-	-	Digital Core Power Supply (1.3V)
20, 69, 106, 154	V <sub>DDP</sub>	-	-	Port Power Supply (3.3V)

**Table 3-1 Pin Definitions and Functions (PG-LQFP-176-6 Package) (cont'd)**

Pin	Symbol	Ctrl.	Type	Function
22, 70, 107, 155	$V_5$	-	-	<b>EVR Power Supply (5V)</b>
27	$V_{PDG}$	-	-	<b>EVR Pass Device Gate</b> If this pin is connected to ground, the internal pass devices are used and the external pass device bypassed.
101, 104	$V_{SS}$	-	-	<b>Digital Ground</b>
102	XTAL1	I		<b>Main Oscillator Input</b>
103	XTAL2	O		<b>Main Oscillator Output</b>
112	TMS	I	A2/ PD	<b>JTAG State Machine Control Input</b>
	DAP1	I/O		<b>Device Access Port Line 1</b>
114	TRST	I	A1/ PD	<b>JTAG Reset Input</b>
115	TCK	I	A1/ PD	<b>JTAG Clock Input</b>
	DAP0	I		<b>Device Access Port Line 0</b>
118	TESTMODE	I	I/PU	<b>Test Mode Select Input</b>
120	ESR1	I/O	A2/ PD	<b>External System Request Reset Input 1</b>
121	PORST	I	I/PU	<b>Power On Reset</b>
122	ESR0	I/O	A2	<b>External System Request Reset Input 0</b> Default configuration during and after reset is open-drain driver. The driver drives low during power-on reset.

- 1) Only applicable for SAK-TC1728F-192F133HR.
- 2) Analog input overlaid with digital input functionality. The related port logic is used to configure the input as either analog input (default after reset) or digital input. The related port logic supports only the port input features as the connected pads are input only pads.
- 3) IOZ1 valid for this pin is the parameter with overlaid = No in the ADC parameter table.
- 4) IOZ1 valid for this pin is the parameter with overlaid = Yes in the ADC parameter table.
- 5) For the emulation device (ED), this pin is bonded to  $VDD_{SB}$  (ED Stand By RAM supply). In the production devide device, this pin is bonded to a VDD pad.

**Legend for Table 3-1**

Column "Ctrl.":

I = Input (for GPIO port lines with IOCR bit field selection  $PCx = 0XXX_B$ )

O = Output

O0 = Output with IOCR bit field selection  $PCx = 1X00_B$ O1 = Output with IOCR bit field selection  $PCx = 1X01_B$  (ALT1)O2 = Output with IOCR bit field selection  $PCx = 1X10_B$  (ALT2)O3 = Output with IOCR bit field selection  $PCx = 1X11_B$  (ALT3)

Column "Type":

A1 = Pad class A1 (LVTTTL)

A1+ = Pad class A1+ (LVTTTL)

A2 = Pad class A2 (LVTTTL)

F = Pad class F (LVDS/CMOS)

D = Pad class D (ADC)

I = Pad class I (LVTTTL)

S = Pad class S (CMOS)

PU = with pull-up device connected during reset ( $\overline{PORST} = 0$ )PD = with pull-down device connected during reset ( $\overline{PORST} = 0$ )TR = tri-state during reset ( $\overline{PORST} = 0$ )



## 4 Identification Registers

The Identification Registers uniquely identify the device.

**Table 2 SAK-TC1728N-192F133HL Identification Registers**

Short Name	Value	Address	Stepping
CBS_JDPID	0000 6350 <sub>H</sub>	F000 0408 <sub>H</sub>	AB
CBS_JTAGID	101D 0083 <sub>H</sub>	F000 0464 <sub>H</sub>	AB
SCU_CHIPID	0300 9C01 <sub>H</sub>	F000 0640 <sub>H</sub>	AB
SCU_MANID	0000 1820 <sub>H</sub>	F000 0644 <sub>H</sub>	AB
SCU_RTID	0000 0001 <sub>H</sub>	F000 0648 <sub>H</sub>	AB

**Table 3 SAK-TC1728N-192F133HR Identification Registers**

Short Name	Value	Address	Stepping
CBS_JDPID	0000 6350 <sub>H</sub>	F000 0408 <sub>H</sub>	AC
CBS_JTAGID	101D 0083 <sub>H</sub>	F000 0464 <sub>H</sub>	AC
SCU_CHIPID	8300 9C01 <sub>H</sub>	F000 0640 <sub>H</sub>	AC
SCU_MANID	0000 1820 <sub>H</sub>	F000 0644 <sub>H</sub>	AC
SCU_RTID	0000 0002 <sub>H</sub>	F000 0648 <sub>H</sub>	AC

**Table 4 SAK-TC1728F-192F133HR Identification Registers**

Short Name	Value	Address	Stepping
CBS_JDPID	0000 6350 <sub>H</sub>	F000 0408 <sub>H</sub>	AC
CBS_JTAGID	101D 0083 <sub>H</sub>	F000 0464 <sub>H</sub>	AC
SCU_CHIPID	8300 AD01 <sub>H</sub>	F000 0640 <sub>H</sub>	AC
SCU_MANID	0000 1820 <sub>H</sub>	F000 0644 <sub>H</sub>	AC
SCU_RTID	0000 0002 <sub>H</sub>	F000 0648 <sub>H</sub>	AC

**Table 5 SAK-TC1728F-192F133HL Identification Registers**

Short Name	Value	Address	Stepping
CBS_JDPID	0000 6350 <sub>H</sub>	F000 0408 <sub>H</sub>	AB
CBS_JTAGID	101D 0083 <sub>H</sub>	F000 0464 <sub>H</sub>	AB
SCU_CHIPID	0300 AD01 <sub>H</sub>	F000 0640 <sub>H</sub>	AB

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**Identification Registers****Table 5      SAK-TC1728F-192F133HL Identification Registers (cont'd)**

<b>Short Name</b>	<b>Value</b>	<b>Address</b>	<b>Stepping</b>
SCU_MANID	0000 1820 <sub>H</sub>	F000 0644 <sub>H</sub>	AB
SCU_RTID	0000 0001 <sub>H</sub>	F000 0648 <sub>H</sub>	AB

## 5 Electrical Parameters

This specification provides all electrical parameters of the TC1728.

### 5.1 General Parameters

#### 5.1.1 Parameter Interpretation

The parameters listed in this section partly represent the characteristics of the TC1728 and partly its requirements on the system. To aid interpreting the parameters easily when evaluating them for a design, they are marked with an two-letter abbreviation in column "Symbol":

- **CC**  
Such parameters indicate **C**ontroller **C**haracteristics which are a distinctive feature of the TC1728 and must be regarded for a system design.
- **SR**  
Such parameters indicate **S**ystem **R**equirements which must provided by the microcontroller system in which the TC1728 designed in.

### 5.1.2 Pad Driver and Pad Classes Summary

This section gives an overview on the different pad driver classes and its basic characteristics. More details (mainly DC parameters) are defined in the [Section 5.2.1](#).

**Table 6 Pad Driver and Pad Classes Overview**

Class	Power Supply	Type	Sub Class	Speed Grade	Load	Leakage <sup>1)</sup> 150°C	Termination
A	3.3 V	LVTTTL I/O, LVTTTL outputs	A1 (e.g. GPIO)	6 MHz	100 pF	500 nA	No
			A1+ (e.g. serial I/Os)	25 MHz	50 pF	1 $\mu$ A	Series termination recommended
			A2 (e.g. serial I/Os)	40 MHz	50 pF	3 $\mu$ A	Series termination recommended
F	3.3 V	LVDS	–	50 MHz	–	–	<sup>2)</sup>
		CMOS	–	50 MHz	–	–	Parallel termination, 100 $\Omega \pm 10\%$
DE	5 V	ADC	–	–	–	–	
I	3.3 V	LVTTTL (input only)	–	–	–	–	

1) Two values are given: for  $T_j = 150\text{ }^\circ\text{C}$  and a 50% higher value for  $T_j = 160\text{ }^\circ\text{C}$ .

2) In applications where the LVDS pins are not used (disabled), these pins must be either left unconnected, or properly terminated with the differential parallel termination of 100  $\Omega \pm 10\%$ .



### 5.1.3 Absolute Maximum Ratings

Stresses above the values listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

**Table 7 Absolute Maximum Rating Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Storage temperature	$T_{ST}$ SR	-65	–	160	°C	–
Voltage at 1.3 V power supply pins with respect to $V_{SS}$	$V_{DD}$ SR	–	–	2.0	V	–
Voltage at 3.3 V power supply pins with respect to $V_{SS}$	$V_{DDP}$ SR	–	–	4.33	V	–
Voltage at 5 V power supply pins with respect to $V_{SS}$	$V_{DDM}$ SR	–	–	7.0	V	–
Voltage on any Class A input pin and dedicated input pins with respect to $V_{SS}$	$V_{IN}$ SR	-0.6	–	$V_{DDP} + 0.5$ or max. 4.33	V	Whatever is lower
Voltage on any Class D analog input pin with respect to $V_{AGND}$	$V_{AIN}$ $V_{AREF_x}$ SR	-0.6	–	7.0	V	–
Voltage on any shared Class D analog input pin with respect to $V_{SSAF}$ , if the FADC is switched through to the pin.	$V_{AINF}$  SR	-0.6	–	7.0	V	–
Input current on any pin during overload condition	$I_{IN}$	-10	–	+10	mA	
Absolute maximum sum of all input circuit currents for one port group during overload condition <sup>1)</sup>	$I_{IN}$	-75	–	+75	mA	
Absolute maximum sum of all input circuit currents during overload condition	$\Sigma I_{IN}$	–	–	[200]	mA	

- 1) The port groups are defined in [Table 12](#).

### 5.1.4 Pin Reliability in Overload

When receiving signals from higher voltage devices, low-voltage devices experience overload currents and voltages that go beyond their own IO power supplies specification.

**Table 8** defines overload conditions that will not cause any negative reliability impact if all the following conditions are met:

- full operation life-time (24000 h) is not exceeded
- **Operating Conditions** are met for
  - pad supply levels ( $V_{DDP}$  or  $V_{DDM}$ )
  - temperature

If a pin current is out of the **Operating Conditions** but within the overload parameters, then the parameters functionality of this pin as stated in the Operating Conditions can no longer be guaranteed. Operation is still possible in most cases but with relaxed parameters.

*Note: An overload condition on one or more pins does not require a reset.*

**Table 8 Overload Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input current on any digital pin during overload condition except LVDS pins	$I_{IN}$	-5	–	+5	mA	
Input current on LVDS pins	$I_{INLVDS}$	-3	–	+3	mA	
Absolute sum of all input circuit currents for one port group during overload condition <sup>1)</sup>	$I_{ING}$	-70	–	+70	mA	
Input current on analog pins	$I_{INANA}$	-3	–	+3	mA	
Absolute sum of all analog input currents for analog inputs of a single ADC during overload condition	$I_{INSAS}$	-15	–	+15	mA	
Absolute sum of all input circuit currents during overload condition	$\Sigma I_{INS}$	-100	–	100	mA	

1) The port groups are defined in **Table 12**.

*Note: FADC input pins count as analog pin as they are overlaid with an ADC pins.*

**Table 9 PN-Junction Characteristics for positive Overload**

Pad Type	$I_{IN} = 3 \text{ mA}$	$I_{IN} = 5 \text{ mA}$
A1 / A1+ / F	$U_{IN} = V_{DDP} + 0.6 \text{ V}$	$U_{IN} = V_{DDP} + 0.7 \text{ V}$
A2	$U_{IN} = V_{DDP} + 0.5 \text{ V}$	$U_{IN} = V_{DDP} + 0.6 \text{ V}$
LVDS	$U_{IN} = V_{DDP} + 0.7 \text{ V}$	-
D / S	$U_{IN} = V_{DDM} + 0.6 \text{ V}$	-

**Table 10 PN-Junction Characteristics for negative Overload**

Pad Type	$I_{IN} = -3 \text{ mA}$	$I_{IN} = -5 \text{ mA}$
A1 / A1+ / F	$U_{IN} = V_{SS} - 0.6 \text{ V}$	$U_{IN} = V_{SS} - 0.7 \text{ V}$
A2	$U_{IN} = V_{SS} - 0.5 \text{ V}$	$U_{IN} = V_{SS} - 0.6 \text{ V}$
LVDS	$U_{IN} = V_{SS} - 0.7 \text{ V}$	-
D / S	$U_{IN} = V_{SSM} - 0.6 \text{ V}$	-

*Note: A series resistor at the pin to limit the current to the maximum permitted overload current is sufficient to handle failure situations like short to battery without having any negative reliability impact on the operational life-time.*

### 5.1.5 Operating Conditions

The following operating conditions must not be exceeded in order to ensure correct operation and reliability of the TC1728. All parameters specified in the following tables refer to these operating conditions, unless otherwise noticed.

Digital supply voltages applied to the TC1728 from external must be static regulated voltages which allow a typical voltage swing of  $\pm 5\%$ .

All parameters specified in the following tables refer to these operating conditions (**Table 11**), unless otherwise noticed in the Note / Test Condition column.

**Table 11 Operating Conditions Parameters**

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ	Max.		
Overload coupling factor for analog inputs, negative	$K_{OVAN}$	CC	–	–	0.0001		$I_{OV} \geq -2$ mA; $I_{OV} \leq 0$ mA; analog pad= 5.0 V
Overload coupling factor for analog inputs, positive	$K_{OVAP}$	CC	–	–	0.00001		$I_{OV} \geq 0$ mA; $I_{OV} \leq 3$ mA; analog pad= 5.0 V
CPU Frequency	$f_{CPU}$	SR	–	–	133	MHz	
FPI Frequency	$f_{FPI}$	SR	–	–	110	MHz	
LMB Frequency	$f_{LMB}$	SR	–	–	133	MHz	
PCP Frequency	$f_{PCP}$	SR	–	–	133	MHz	
Inactive device pin current	$I_{ID}$	SR	-1	–	1	mA	All power supply voltages $V_{DDx} = 0$
Short circuit current of digital outputs <sup>1)</sup>	$I_{SC}$	SR	-5	–	5	mA	
Absolute sum of short circuit currents of the device	$\Sigma I_{SC\_D}$	CC	–	–	100	mA	
Absolute sum of short circuit currents per pin group	$\Sigma I_{SC\_PG}$	CC	–	–	70	mA	
Ambient Temperature	$T_A$	SR	-40	–	125	°C	

## Electrical Parameters

**Table 11 Operating Conditions Parameters**

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ	Max.		
Junction temperature	$T_J$	SR	-40	–	160	°C	
Core Supply Voltage	$V_{DD}$	SR	1.17	1.3	1.43 <sup>2)</sup>	V	Only required if externally supplied <sup>5)</sup>
ADC analog supply voltage	$V_{DDM}$	SR	2.97	5.0	5.5 <sup>3)</sup>	V	
EVR supply voltage	$V_5$	SR	4.00	5.0	5.5	V	5.0V single supply
			2.97	3.3	3.63	V	3.3V single supply
Digital supply voltage for IO pads	$V_{DDP}$	SR	2.97	3.3	3.63 <sup>4)</sup>	V	Only required if externally supplied <sup>5)</sup>
VDDP voltage to ensure defined pad states <sup>6)</sup>	$V_{DDPPA}$	CC	0.65	–	–	V	
Digital ground voltage	$V_{SS}$	SR	0	–	–	V	
Analog ground voltage for $V_{DDM}$	$V_{SSM}$	SR	-0.1	0	0.1	V	

1) Applicable for digital outputs.

2) Voltage overshoot to 1.7V is permissible at Power-Up and  $\overline{PORST}$  low, provided the pulse duration is less than 100  $\mu$ s and the cumulated sum of the pulses does not exceed 1 h.

3) Voltage overshoot to 6.5V is permissible at Power-Up and  $\overline{PORST}$  low, provided the pulse duration is less than 100  $\mu$ s and the cumulated sum of the pulses does not exceed 1 h.

4) Voltage overshoot to 4.0V is permissible at Power-Up and  $\overline{PORST}$  low, provided the pulse duration is less than 100  $\mu$ s and the cumulated sum of the pulses does not exceed 1 h.

5) No external inductive load permissible if EVR is used.

6) This parameter is valid under the assumption the  $\overline{PORST}$  signal is constantly at low level during the power-up/power-down of  $V_{DDP}$ .

**Table 12 Pin Groups for Overload / Short-Circuit Current Sum Parameter**

Group	Pins
1	P0.[15], P5.[7:0], P5.[15:8], P9.[8:7], P10.[3:0]
2	P0.[14:0], P2.[13:8], P3.[1:0], P3.[4:3], P3.7, P3.[15:9], P6.[3:0], P8.[2:0], P9.[4:2]

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**Electrical Parameters****Table 12 Pin Groups for Overload / Short-Circuit Current Sum Parameter**  
(cont'd)

<b>Group</b>	<b>Pins</b>
3	P1.[1:0], P1.[7:5], P1.15, P3.2, P3.[6:5], P3.8, P8.[4:3], P8.13, P9.[6:5]
4	P1.[4:2], P1.[14:8], P2.[7:0], P4.[3:0], P8.[12:5]

## 5.2 DC Parameters

### 5.2.1 Input/Output Pins

**Table 13 Standard\_Pads Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Pin capacitance (digital inputs/outputs)	$C_{IO}$ CC	–	–	10	pF	$T_A = 25\text{ °C}$ ; $f = 1\text{ MHz}$
Pull-down current	$ I_{PDL} $ CC	–	–	150	$\mu\text{A}$	$V_i \geq 0.6 \times V_{DDP}$ V
		10	–	–	$\mu\text{A}$	$V_i \geq 0.36 \times V_{DDP}$ V
Pull-Up current	$ I_{PUH} $ CC	10	–	–	$\mu\text{A}$	$V_i \leq 0.6 \times V_{DDP}$ V
		–	–	100	$\mu\text{A}$	$V_i \leq 0.36 \times V_{DDP}$ V
Spike filter always blocked pulse duration	$t_{SF1}$ CC	–	–	10	ns	only PORST pin
Spike filter pass-through pulse duration	$t_{SF2}$ CC	120	–	–	ns	only PORST pin

**Table 14 Standard\_Pads Class\_A1**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input Hysteresis for pads of all A classes <sup>1)</sup>	$HYS_A$ CC	$0.1 \times V_{DDP}$	–	–	V	
Input Leakage Current Class A1	$I_{OZA1}$ CC	-500	–	500	nA	$V_i \leq V_{DDP}$ V; $V_i \geq 0$ V; $-40\text{ °C} \leq T_j \leq 150\text{ °C}$
		-750	–	750	nA	$V_i \leq V_{DDP}$ V; $V_i \geq 0$ V; $150\text{ °C} < T_j \leq 160\text{ °C}$
Ratio $V_{iL}/V_{iH}$ , A1 pads	$V_{ILA1} / V_{IHA1}$ CC	0.6	–	–		



## Electrical Parameters

Table 14 Standard\_Pads Class\_A1

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
On-Resistance of the class A1 pad, weak driver	$R_{DSONW}$ CC	–	450	600	Ohm	$I_{OH} > -0.5$ mA; P_MOS
		–	210	340	Ohm	$I_{OL} < 0.5$ mA; N_MOS
On-Resistance of the class A1 pad, medium driver	$R_{DSONM}$ CC	–	–	155	Ohm	$I_{OH} > -2$ mA; P_MOS
		–	–	110	Ohm	$I_{OL} < 2$ mA; N_MOS
Fall time, pad type A1	$t_{FA1}$ CC	–	–	150	ns	$C_L = 20$ pF; pin out driver= weak
		–	–	50	ns	$C_L = 50$ pF; pin out driver= medium
		–	–	140	ns	$C_L = 150$ pF; pin out driver= medium
		–	–	550	ns	$C_L = 150$ pF; pin out driver= weak
		–	–	18000	ns	$C_L = 20000$ pF; pin out driver= medium
		–	–	65000	ns	$C_L = 20000$ pF; pin out driver= weak
Rise time, pad type A1	$t_{RA1}$ CC	–	–	150	ns	$C_L = 20$ pF; pin out driver= weak
		–	–	50	ns	$C_L = 50$ pF; pin out driver= medium
		–	–	140	ns	$C_L = 150$ pF; pin out driver= medium
		–	–	550	ns	$C_L = 150$ pF; pin out driver= weak
		–	–	18000	ns	$C_L = 20000$ pF; pin out driver= medium
		–	–	65000	ns	$C_L = 20000$ pF; pin out driver= weak

## Electrical Parameters

Table 14 Standard\_Pads Class\_A1

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input high voltage, class A1 pads	$V_{IHA1}$ SR	$0.6 \times V_{DDP}$	–	$\min(V_D, V_{DDP} + 0.3, 3.6)$	V	
Input low voltage, class A1 pads	$V_{ILA1}$ SR	-0.3	–	$0.36 \times V_{DDP}$	V	
Output voltage high, class A1 pads	$V_{OHA1}$ CC	$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq -1.4$ mA; pin out driver= medium
		2.4	–	–	V	$I_{OH} \geq -2$ mA; pin out driver= medium
		$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq -400$ $\mu$ A; pin out driver= weak
		2.4	–	–	V	$I_{OH} \geq -500$ $\mu$ A; pin out driver= weak
Output voltage low, class A1 pads	$V_{OLA1}$ CC	–	–	0.4	V	$I_{OL} \leq 2$ mA; pin out driver= medium
		–	–	0.4	V	$I_{OL} \leq 500$ $\mu$ A; pin out driver= weak

1) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can't be guaranteed that it suppresses switching due to external system noise.

Table 15 Standard\_Pads Class\_A1+

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input Hysteresis for A1+ pads <sup>1)</sup>	$HYS_{A1+}$ CC	$0.1 \times V_{DDP}$	–	–	V	
Input Leakage Current Class A1+	$I_{OZA1+}$ CC	-1000	–	1000	nA	

## Electrical Parameters

Table 15 Standard\_Pads Class\_A1+

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ	Max.		
On-Resistance of the class A1+ pad, weak driver	$R_{DSONW}$ CC	–	450	600	Ohm	$I_{OH} > -0.5$ mA; P_MOS
		–	210	340	Ohm	$I_{OL} < 0.5$ mA; N_MOS
On-Resistance of the class A1+ pad, medium driver	$R_{DSONM}$ CC	–	–	155	Ohm	$I_{OH} > -2$ mA; P_MOS
		–	–	110	Ohm	$I_{OL} < 2$ mA; N_MOS
On-Resistance of the class A1+ pad, strong driver	$R_{DSON1+}$ CC	–	–	110	Ohm	$I_{OH} > -2$ mA; P_MOS
		–	–	80	Ohm	$I_{OL} < 2$ mA; N_MOS
Fall time, pad type A1+	$t_{FA1+}$ C	–	–	150	ns	$C_L = 20$ pF; pin out driver= weak
		–	–	28	ns	$C_L = 50$ pF; edge= slow; pin out driver= strong
		–	–	16	ns	$C_L = 50$ pF; edge= soft ; pin out driver= strong
		–	–	50	ns	$C_L = 50$ pF; pin out driver= medium
		–	–	140	ns	$C_L = 150$ pF; pin out driver= medium
		–	–	550	ns	$C_L = 150$ pF; pin out driver= weak
		–	–	18000	ns	$C_L = 20000$ pF; pin out driver= medium
		–	–	65000	ns	$C_L = 20000$ pF; pin out driver= weak

## Electrical Parameters

Table 15 Standard\_Pads Class\_A1+

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ	Max.		
Rise time, pad type A1+	$t_{RA1+}$ C	–	–	150	ns	$C_L = 20$ pF; pin out driver= weak
	C	–	–	28	ns	$C_L = 50$ pF; edge= slow ; pin out driver= strong
		–	–	16	ns	$C_L = 50$ pF; edge= soft ; pin out driver= strong
		–	–	50	ns	$C_L = 50$ pF; pin out driver= medium
		–	–	140	ns	$C_L = 150$ pF; pin out driver= medium
		–	–	550	ns	$C_L = 150$ pF; pin out driver= weak
		–	–	18000	ns	$C_L = 20000$ pF; pin out driver= medium
		–	–	65000	ns	$C_L = 20000$ pF; pin out driver= weak
Input high voltage, Class A1+ pads	$V_{IHA1+}$ SR	$0.6 \times V_{DDP}$	–	$\min(V_{D_{DP}} + 0.3, 3.6)$	V	
Input low voltage, Class A1+ pads	$V_{ILA1+}$ SR	-0.3	–	$0.36 \times V_{DDP}$	V	
Ratio $V_{il}/V_{ih}$ , A1+ pads	$V_{ILA1+} / V_{IHA1+}$ CC	0.6	–	–		

## Electrical Parameters

Table 15 Standard\_Pads Class\_A1+

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Output voltage high, class A1+ pads	$V_{OHA1+CC}$	$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq -1.4$ mA; pin out driver= medium
		$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq -1.4$ mA; pin out driver= strong
		2.4	–	–	V	$I_{OH} \geq -2$ mA; pin out driver= medium
		2.4	–	–	V	$I_{OH} \geq -2$ mA; pin out driver= strong
		$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq -400$ $\mu$ A; pin out driver= weak
		2.4	–	–	V	$I_{OH} \geq -500$ $\mu$ A; pin out driver= weak
Output voltage low, class A1+ pads	$V_{OLA1+CC}$	–	–	0.4	V	$I_{OL} \leq 2$ mA; pin out driver= medium
		–	–	0.4	V	$I_{OL} \leq 2$ mA; pin out driver= strong
		–	–	0.4	V	$I_{OL} \leq 500$ $\mu$ A; pin out driver= weak

1) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can't be guaranteed that it suppresses switching due to external system noise.

Table 16 Standard\_Pads Class\_A2

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input Hysteresis for A2 pads <sup>1)</sup>	$HYS_{A2CC}$	$0.1 \times V_{DDP}$	–	–	V	

## Electrical Parameters

Table 16 Standard\_Pads Class\_A2

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input Leakage current Class A2	$I_{OZA2}$ CC	-6000	–	6000	nA	$V_i < V_{DDP} / 2 - 1 \text{ V};$ $V_i > V_{DDP} / 2 + 1 \text{ V};$ $V_i \geq 0 \text{ V};$ $V_i \leq V_{DDP} \text{ V}$
		-3000	–	3000	nA	$V_i > V_{DDP} / 2 - 1 \text{ V};$ $V_i < V_{DDP} / 2 + 1 \text{ V}$
Ratio $V_{iL}/V_{iH}$ , A2 pads	$V_{iLA2} / V_{iHA2}$ CC	0.6	–	–		
On-Resistance of the class A2 pad, weak driver	$R_{DSONW}$ CC	–	450	600	Ohm	$I_{OH} > -0.5 \text{ mA};$ P_MOS
		–	210	340	Ohm	$I_{OL} < 0.5 \text{ mA};$ N_MOS
On-Resistance of the class A2 pad, medium driver	$R_{DSONM}$ CC	–	–	155	Ohm	$I_{OH} > -2 \text{ mA};$ P_MOS
		–	–	110	Ohm	$I_{OL} < 2 \text{ mA};$ N_MOS
On-Resistance of the class A2 pad, strong driver	$R_{DSON2}$ CC	–	–	42	Ohm	$I_{OH} > -2 \text{ mA};$ P_MOS
		–	–	22	Ohm	$I_{OL} < 2 \text{ mA};$ N_MOS

## Electrical Parameters

Table 16 Standard\_Pads Class\_A2

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Fall time, pad type A2	$t_{FA2\ CC}$	–	–	150	ns	$C_L = 20\ \text{pF}$ ; pin out driver= weak
		–	–	7	ns	$C_L = 50\ \text{pF}$ ; edge= medium ; pin out driver= strong
		–	–	10	ns	$C_L = 50\ \text{pF}$ ; edge= medium- minus ; pin out driver= strong
		–	–	3.7	ns	$C_L = 50\ \text{pF}$ ; edge= sharp ; pin out driver= strong
		–	–	5	ns	$C_L = 50\ \text{pF}$ ; edge= sharp- minus ; pin out driver= strong
		–	–	16	ns	$C_L = 50\ \text{pF}$ ; edge= soft ; pin out driver= strong
		–	–	50	ns	$C_L = 50\ \text{pF}$ ; pin out driver= medium
		–	–	7.5	ns	$C_L = 100\ \text{pF}$ ; edge= sharp ; pin out driver= strong
		–	–	140	ns	$C_L = 150\ \text{pF}$ ; pin out driver= medium

## Electrical Parameters

Table 16 Standard\_Pads Class\_A2

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Rise time, pad type A2	$t_{RA2\ CC}$	–	–	550	ns	$C_L = 150\text{ pF}$ ; pin out driver= weak
		–	–	18000	ns	$C_L = 20000\text{ pF}$ ; pin out driver= medium
		–	–	65000	ns	$C_L = 20000\text{ pF}$ ; pin out driver= weak
		–	–	150	ns	$C_L = 20\text{ pF}$ ; pin out driver= weak
		–	–	7.0	ns	$C_L = 50\text{ pF}$ ; edge= medium ; pin out driver= strong
		–	–	10	ns	$C_L = 50\text{ pF}$ ; edge= medium-minus ; pin out driver= strong
		–	–	3.7	ns	$C_L = 50\text{ pF}$ ; edge= sharp ; pin out driver= strong
		–	–	5	ns	$C_L = 50\text{ pF}$ ; edge= sharp-minus ; pin out driver= strong
		–	–	16	ns	$C_L = 50\text{ pF}$ ; edge= soft ; pin out driver= strong
–	–	50	ns	$C_L = 50\text{ pF}$ ; pin out driver= medium		
–	–	7.5	ns	$C_L = 100\text{ pF}$ ; edge= sharp ; pin out driver= strong		
–	–	140	ns	$C_L = 150\text{ pF}$ ; pin out driver= medium		



## Electrical Parameters

Table 16 Standard\_Pads Class\_A2

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
		–	–	550	ns	$C_L = 150$ pF; pin out driver= weak
		–	–	18000	ns	$C_L = 20000$ pF; pin out driver= medium
		–	–	65000	ns	$C_L = 20000$ pF; pin out driver= weak
Input high voltage, class A2 pads	$V_{IHA2}$ SR	$0.6 \times V_{DDP}$	–	$\min(V_{DDP} + 0.3, 3.6)$	V	
Input low voltage, Class A2 pads	$V_{ILA2}$ SR	-0.3	–	$0.36 \times V_{DDP}$	V	
Output voltage high, class A2 pads	$V_{OHA2}$ CC	$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq -1.4$ mA; pin out driver= medium
		$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq -1.4$ mA; pin out driver= strong
		2.4	–	–	V	$I_{OH} \geq -2$ mA; pin out driver= medium
		2.4	–	–	V	$I_{OH} \geq -2$ mA; pin out driver= strong
		$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq -400$ $\mu$ A; pin out driver= weak
		2.4	–	–	V	$I_{OH} \geq -500$ $\mu$ A; pin out driver= weak
Output voltage low, class A2 pads	$V_{OLA2}$ CC	–	–	0.4	V	$I_{OL} \leq 2$ mA; pin out driver= medium
		–	–	0.4	V	$I_{OL} \leq 2$ mA; pin out driver= strong
		–	–	0.4	V	$I_{OL} \leq 500$ $\mu$ A; pin out driver= weak

1) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can't be guaranteed that it suppresses switching due to external system noise.

Table 17 Standard\_Pads Class\_F

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input Hysteresis F <sup>1)</sup>	$HYSF_{CC}$	$0.05 \times V_{DDP}$	–	–	V	
Input Leakage Current Class F	$I_{OZF_{CC}}$	-6000	–	6000	nA	$V_i \leq V_{DDP} V$ ; $V_i \geq 0 V$ ; $V_i < V_{DDP} / 2 - 1 V$ ; $V_i > V_{DDP} / 2 + 1 V$
		-3000	–	3000	nA	$V_i < V_{DDP} / 2 + 1 V$ ; $V_i > V_{DDP} / 2 - 1 V$
Ratio $V_{iL} / V_{iH}$ , F pads	$V_{iLF} / V_{iHF_{CC}}$	0.6	–	–		
On-Resistance of the class F pad, medium driver	$R_{DSONM_{CC}}$	–	–	175	Ohm	$I_{OH} > -2 \text{ mA}$ ; P_MOS
		–	–	160	Ohm	$I_{OL} < 2 \text{ mA}$ ; N_MOS
Fall time, pad type F, CMOS mode	$t_{FF_{CC}}$	–	–	60	ns	$C_L = 50 \text{ pF}$
Rise time, pad type F, CMOS mode	$t_{RF_{CC}}$	–	–	60	ns	$C_L = 50 \text{ pF}$
Input high voltage, pad class F, CMOS mode	$V_{iHF_{SR}}$	$0.6 \times V_{DDP}$	–	$\min(V_{DDP} + 0.3, 3.6)$	V	
Input low voltage, Class F pads, CMOS mode	$V_{iLF_{SR}}$	-0.3	–	$0.36 \times V_{DDP}$	V	
Output high voltage, class F pads, CMOS mode	$V_{oHF_{CC}}$	$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq -1.4 \text{ mA}$
		2.4	–	–	V	$I_{OH} \geq -2 \text{ mA}$
Output low voltage, class F pads, CMOS mode	$V_{oLF_{CC}}$	–	–	0.4	V	$I_{OL} \leq 2 \text{ mA}$

1) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can't be guaranteed that it suppresses switching due to external system noise.

**Table 18 Standard\_Pads Class\_I**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input Hysteresis Class I <sup>1)</sup>	$HYSI$ CC	$0.1 \times V_{DDP}$	–	–	V	
Input Leakage Current	$I_{OZI}$ CC	-1000	–	1000	nA	$-40^{\circ}\text{C} \leq T_J \leq 150^{\circ}\text{C}$
		-1500	–	1500	nA	$150^{\circ}\text{C} < T_J \leq 160^{\circ}\text{C}$
Ratio between low and high input threshold	$V_{ILI} / V_{IHI}$ CC	0.6	–	–		
Input high voltage, class I pins	$V_{IHI}$ SR	$0.6 \times V_{DDP}$	–	$\min(V_D, V_{DP} + 0.3, 3.6)$	V	
Input low voltage, Class I pads	$V_{ILI}$ SR	-0.3	–	$0.36 \times V_{DDP}$	V	

1) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can't be guaranteed that it suppresses switching due to external system noise.

LVDS parameter are valid for  $V_{DD} = 1.235 \text{ V to } 1.365 \text{ V}$ ;  $V_{DDP} = 3.135 \text{ V to } 3.465 \text{ V}$ .

**Table 19 LVDS\_Pads Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Output impedance, pad class F, LVDS mode	$R_O$ CC	40	–	140	Ohm	
Fall time, pad type LVDS	$t_{FL}$ CC	–	–	2	ns	termination $100 \Omega \pm 1 \%$ ;
Rise time, pad type LVDS	$t_{RL}$ CC	–	–	2	ns	termination $100 \Omega \pm 1 \%$ ;
Pad set-up time	$t_{SET\_LVDS}$ CC	–	–	13	$\mu\text{s}$	termination $100 \Omega \pm 1 \%$
Output Differential Voltage	$V_{OD}$ CC	150	–	400	mV	termination $100 \Omega \pm 1 \%$

## Electrical Parameters

**Table 19 LVDS\_Pads Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Output voltage high, pad class F, LVDS mode	$V_{OH}$ CC	–	–	1525	mV	termination 100 $\Omega$ $\pm$ 1 %
Output voltage low, pad class F, LVDS mode	$V_{OL}$ CC	875	–	–	mV	termination 100 $\Omega$ $\pm$ 1 %
Output Offset Voltage	$V_{OS}$ CC	1075	–	1325	mV	termination 100 $\Omega$ $\pm$ 1 %

Class S pad parameters are only valid for  $V_{DDM} = 4.75$  V to 5.25 V.

**Table 20 Standard\_Pads Class\_S**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input Hysteresis for class S pads <sup>1)</sup>	$HYSS$ CC	0.3	–	–	V	
Input leakage current	$I_{OZS}$ CC	–300	–	300	nA	
Input voltage high	$V_{IHS}$ CC	–	–	3.6	V	
Input voltage low	$V_{ILS}$ CC	1.9	–	–	V	
$V_{ILS}$ Delta <sup>2)</sup>	$V_{ILSD}$ CC	-50	–	50	mV	Maximum input low state threshold variation over 1ms ( $V_{DDP} = \text{constant}$ )

1) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can't be guaranteed that it suppresses switching due to external system noise.

2)  $V_{ILSD}$  is implemented to ensure J2716 specification. It can't be guaranteed that it suppresses switching due to external noise.

### 5.2.2 Analog to Digital Converters (ADCx)

ADC parameter in **Table 21** are valid for  $V_{DD} = 1.235\text{ V}$  to  $1.365\text{ V}$ ;  $V_{DDM} = 4.75\text{ V}$  to  $5.25\text{ V}$ ;  $T_J = 150^\circ\text{C}$ .

**Table 21 5V ADC Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Switched capacitance at the analog voltage inputs <sup>1)</sup>	$C_{AINSW\ CC}$	–	9	20	pF	
Total capacitance of an analog input	$C_{AINTOT\ CC}$	–	20	30	pF	
Switched capacitance at the positive reference voltage input <sup>2)(3)</sup>	$C_{AREFSW\ CC}$	–	15	30	pF	
Total capacitance of the voltage reference inputs <sup>2)</sup>	$C_{AREFTOT\ CC}$	–	20	40	pF	
Differential Non-Linearity Error <sup>4)(5)(6)(7)</sup>	$EA_{DNL\ CC}$	-3	–	3	LSB	ADC resolution= 12-bit <sup>8) 9)</sup>
Gain Error <sup>4)(5)(6)(7)</sup>	$EA_{GAIN\ CC}$	-3.5	–	3.5	LSB	ADC resolution= 12-bit <sup>8) 9)</sup>
Integral Non-Linearity <sup>4)(5)(6)(7)</sup>	$EA_{INL\ CC}$	-3	–	3	LSB	ADC resolution= 12-bit <sup>8) 9)</sup>
Offset Error <sup>4)(5)(6)(7)</sup>	$EA_{OFF\ CC}$	-4	–	4	LSB	ADC resolution= 12-bit <sup>8) 9)</sup>
Converter clock	$f_{ADC\ SR}$	4	–	110	MHz	$f_{ADC} = f_{FPI}$
Internal ADC clock	$f_{ADCI\ CC}$	1	–	20	MHz	<sup>10)</sup>
Charge consumption per conversion	$Q_{CONV\ CC}$	70	85 <sup>11)</sup>	100	pC	charge needs to be provided via $V_{AREF0}$

## Electrical Parameters

Table 21 5V ADC Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input leakage at analog inputs <sup>12)</sup>	$I_{OZ1}$ CC	-100	–	500	nA	$V_i \geq 0.97 \times V_{DDM} V$ ; $V_i \leq V_{DDM} V$ ; overlayed= No
		-100	–	600	nA	$V_i \geq 0.97 \times V_{DDM} V$ ; $V_i \leq V_{DDM} V$ ; overlayed= Yes
		-500	–	100	nA	$V_i \geq 0 V$ ; $V_i \leq 0.03 \times V_{DDM} V$ ; overlayed= No
		-600	–	100	nA	$V_i \leq 0.03 \times V_{DDM} V$ ; $V_i \geq 0 V$ ; overlayed= Yes
		-100	–	200	nA	$V_i > 0.03 \times V_{DDM} V$ ; $V_i < 0.97 \times V_{DDM} V$ ; overlayed= No
		-100	–	300	nA	$V_i > 0.03 \times V_{DDM} V$ ; $V_i < 0.97 \times V_{DDM} V$ ; overlayed= Yes
		Input leakage current at VAREF0	$I_{OZ2}$ CC	-2	–	2
Input leakage current at VAGND0	$I_{OZ3}$ CC	-2	–	2	$\mu A$	$V_{AGND0} \geq 0V$ ; $V_{AGND0} \leq V_{DDM} V$
ON resistance of the transmission gates in the analog voltage path	$R_{AIN}$ CC	–	900	1500	Ohm	

## Electrical Parameters

Table 21 5V ADC Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
ON resistance for the ADC test (pull down for AIN7)	$R_{AIN7T}$ CC	180	550	900	Ohm	Test feature available only for odd AINx pins
Resistance of the reference voltage input path	$R_{AREF}$ CC	–	500	1000	Ohm	500 Ohm increased if AIN[1:0] used as reference input
Broken wire detection delay against VAGND	$t_{BWG}$ CC	–	–	50	<sup>13)</sup>	
Broken wire detection delay against VAREF	$t_{BWR}$ CC	–	–	50	<sup>14)</sup>	
Sample time	$t_S$ CC	2	–	257	$T_{ADCI}$	
Calibration time after bit ADC_GLOB_CFG.SUCAL is set	$t_{CAL}$ CC	–	–	4352	cycles	
Total Unadjusted Error <sup>5)6)15)</sup>	$TUE$ CC	-4	–	4 <sup>16)</sup>	LSB	ADC resolution= 12-bit
Wakeup time from analog powerdown, fast mode	$t_{AWAF}$ CC	–	–	5	μs	
Wakeup time from analog powerdown, slow mode	$t_{AWAS}$ CC	–	–	10	μs	
Analog reference ground <sup>2)</sup>	$V_{AGND0}$ SR	$V_{SSM} - 0.05$	–	$V_{AREF0} - V_{DDM}/2$	V	
Analog input voltage	$V_{AIN}$ SR	$V_{AGND0}$	–	$V_{AREF0}$	V	
Analog reference voltage <sup>2)</sup>	$V_{AREF0}$ SR	$V_{AGND0} + V_{DDM}/2$	–	$V_{DDM} + 0.05$ <sup>17)</sup> <sup>18)</sup>	V	
Analog reference voltage range <sup>5)6)2)</sup>	$V_{AREF0} - V_{AGND0}$ SR	$V_{DDM}/2$	–	$V_{DDM} + 0.05$	V	

**Electrical Parameters**

- 1) The sampling capacity of the conversion C-network is pre-charged to  $V_{AREF}/2$  before the sampling moment. Because of the parasitic elements the voltage measured at AINx can deviate from  $V_{AREF}/2$ .
- 2) Applies to AINx, when used as auxiliary reference input.
- 3) This represents an equivalent switched capacitance. This capacitance is not switched to the reference voltage at once. Instead smaller capacitances are successively switched to the reference voltage.
- 4) The sum of DNL/INL/GAIN/OFF errors does not exceed the related TUE total unadjusted error.
- 5) If the analog reference voltage range is below  $V_{DDM}$  but still in the defined range of  $V_{DDM}/2$  and  $V_{DDM}$  is used, then the ADC converter errors increase. If the reference voltage is reduced by the factor k ( $k < 1$ ), TUE, DNL, INL, Gain, and Offset errors increase also by the factor  $1/k$ .
- 6) If a reduced analog reference voltage between 1V and  $V_{DDM}/2$  is used, then there are additional decrease in the ADC speed and accuracy.
- 7) If the analog reference voltage is  $> V_{DDM}$ , then the ADC converter errors increase.
- 8) For 10-bit conversions the error value must be multiplied with a factor 0.25.
- 9) For 8-bit conversions the error value must be multiplied with a factor 0.0625.
- 10) If the alternate reference is used or  $f_{ADCi}$  is more than 16 MHz, the accuracy of the ADC may decrease.
- 11) For a conversion time of  $1 \mu s$  a rms value of  $85 \mu A$  result for  $I_{AREF0}$ .
- 12) The leakage current definition is a continuous function, as shown in figure ADCx Analogue Input Leakage. The numerical values defined determine the characteristic points of the given continuous linear approximation - they do not define step function.
- 13) The broken wire detection delay against  $V_{AGND}$  is measured in numbers of consecutive precharge cycles at a conversion rate of not more than  $250 \mu s$ . Results below 10% ( $199_H$ ).
- 14) The broken wire detection delay against  $V_{AREF}$  is measured in numbers of consecutive precharge cycles at a conversion rate of not more than  $10 \mu s$ . This function is influenced by leakage current, in particular at high temperature. Results above 60% ( $999_H$ ).
- 15) Measured without noise.
- 16) For 10-bit conversion the TUE is  $\pm 2LSB$ ; for 8-bit conversion the TUE is  $\pm 1LSB$
- 17) A running conversion may become inexact in case of violating the normal conditions (voltage overshoot).
- 18) If the reference voltage  $V_{AREF}$  increase or the  $V_{DDM}$  decrease, so that  $V_{AREF} = (V_{DDM} + 0.05V \text{ to } V_{DDM} + 0.07V)$ , then the accuracy of the ADC decrease by  $4LSB_{12}$ .

ADC parameter in **Table 22** are valid for  $V_{DD} = 1.235 \text{ V to } 1.365 \text{ V}$ ;  $V_{DDM} = 3.135 \text{ V to } 3.465 \text{ V}$ ;  $T_J = 150^\circ\text{C}$ .

**Table 22 3.3V ADC Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Switched capacitance at the analog voltage inputs <sup>1)</sup>	$C_{AINSW}$ CC	–	9	20	pF	
Total capacitance of an analog input	$C_{AINTOT}$ CC	–	20	30	pF	



## Electrical Parameters

Table 22 3.3V ADC Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Switched capacitance at the positive reference voltage input <sup>2)3)</sup>	$C_{AREFS\_W\_CC}$	–	15	30	pF	
Total capacitance of the voltage reference inputs <sup>2)</sup>	$C_{AREFTO\_T\_CC}$	–	20	40	pF	
Differential Non-Linearity Error <sup>4)5)6)7)</sup>	$EA_{DNL\_CC}$	-4	–	4	LSB	ADC resolution= 12-bit <sup>8) 9)</sup>
Gain Error <sup>4)5)6)7)</sup>	$EA_{GAIN\_CC}$	-3.5	–	3.5	LSB	ADC resolution= 12-bit <sup>8) 9)</sup>
Integral Non-Linearity <sup>4)5)6)7)</sup>	$EA_{INL\_CC}$	-4	–	4	LSB	ADC resolution= 12-bit <sup>8) 9)</sup>
Offset Error <sup>4)5)6)7)</sup>	$EA_{OFF\_CC}$	-4	–	4	LSB	ADC resolution= 12-bit <sup>8) 9)</sup>
Converter clock	$f_{ADC\_SR}$	4	–	110	MHz	$f_{ADC} = f_{FPI}$
Internal ADC clock	$f_{ADCI\_CC}$	1	–	20	MHz	<sup>10)</sup>
Charge consumption per conversion <sup>11)</sup>	$Q_{CONV\_CC}$	–	–	70	pC	charge needs to be provided via $V_{AREFO}$

## Electrical Parameters

Table 22 3.3V ADC Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input leakage at analog inputs <sup>12)</sup>	$I_{OZ1}$ C C	-100	–	500	nA	$V_i \geq 0.97 \times V_{DDM}$ V; $V_i \leq V_{DDM}$ V; overlaid= No
		-100	–	600	nA	$V_i \geq 0.97 \times V_{DDM}$ V; $V_i \leq V_{DDM}$ V; overlaid= Yes
		-500	–	100	nA	$V_i \geq 0$ V; $V_i \leq 0.03 \times V_{DDM}$ V; overlaid= No
		-600	–	100	nA	$V_i \leq 0.03 \times V_{DDM}$ V; $V_i \geq 0$ V; overlaid= Yes
		-100	–	200	nA	$V_i > 0.03 \times V_{DDM}$ V; $V_i < 0.97 \times V_{DDM}$ V; overlaid= No
		-100	–	300	nA	$V_i > 0.03 \times V_{DDM}$ V; $V_i < 0.97 \times V_{DDM}$ V; overlaid= Yes
Input leakage current at V <sub>aref</sub>	$I_{OZ2}$ CC	-2	–	2	μA	$V_{AREF0} \leq V_{DDM}$ V
Input leakage current at V <sub>agnd</sub>	$I_{OZ3}$ CC	-2	–	2	μA	$V_{AGND0} \leq V_{DDM}$ V
ON resistance of the transmission gates in the analog voltage path	$R_{AIN}$ C C	–	3500	9000	Ohm	
ON resistance for the ADC test (pull down for AIN7)	$R_{AIN7T}$ CC	180	800	1800	Ohm	Test feature available only for odd AINx pins

## Electrical Parameters

Table 22 3.3V ADC Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Resistance of the reference voltage input path	$R_{AREF}$ CC	–	1700	3000	Ohm	500 Ohm increased if AIN[1:0] used as reference input
Broken wire detection delay against VAGND	$t_{BWD}$ CC	–	–	50	<sup>13)</sup>	
Broken wire detection delay against VAREF	$t_{BWR}$ CC	–	–	50	<sup>14)</sup>	
Sample time	$t_S$ CC	2	–	257	$T_{ADCI}$	
Calibration time after bit ADC_GLOBCFG.SUCAL is set	$t_{CAL}$ CC	–	–	4352	cycles	
Total Unadjusted Error <sup>5)6)15)</sup>	$TUE$ CC	-4.5	–	4.5 <sup>16)</sup>	LSB	ADC resolution= 12-bit
Analog reference ground <sup>2)</sup>	$V_{AGND0}$ SR	$V_{SSM} - 0.05$	–	$V_{AREF0} - V_{DDM}/2$	V	
Analog input voltage	$V_{AIN}$ SR	$V_{AGND0}$	–	$V_{AREF0}$	V	
Analog reference voltage <sup>2)</sup>	$V_{AREF0}$ SR	$V_{AGND0} + V_{DDM}/2$	–	$V_{DDM} + 0.05$ <sup>17)18)</sup>	V	
Analog reference voltage range <sup>5)6)2)</sup>	$V_{AREF0} - V_{AGND0}$ SR	$V_{DDM}/2$	–	$V_{DDM} + 0.05$	V	

- 1) The sampling capacity of the conversion C-network is pre-charged to  $V_{AREF}/2$  before the sampling moment. Because of the parasitic elements the voltage measured at AINx can deviate from  $V_{AREF}/2$ .
- 2) Applies to AINx, when used as auxiliary reference input.
- 3) This represents an equivalent switched capacitance. This capacitance is not switched to the reference voltage at once. Instead smaller capacitances are successively switched to the reference voltage.
- 4) The sum of DNL/INL/GAIN/OFF errors does not exceed the related TUE total unadjusted error.
- 5) If the analog reference voltage range is below  $V_{DDM}$  but still in the defined range of  $V_{DDM}/2$  and  $V_{DDM}$  is used, then the ADC converter errors increase. If the reference voltage is reduced by the factor k ( $k < 1$ ), TUE, DNL, INL, Gain, and Offset errors increase also by the factor  $1/k$ .

**Electrical Parameters**

- 6) If a reduced analog reference voltage between 1V and  $V_{DDM} / 2$  is used, then there are additional decrease in the ADC speed and accuracy.
- 7) If the analog reference voltage is  $> V_{DDM}$ , then the ADC converter errors increase.
- 8) For 10-bit conversions the error value must be multiplied with a factor 0.25.
- 9) For 8-bit conversions the error value must be multiplied with a factor 0.0625.
- 10) If the alternate reference is used, or  $f_{ADCI}$  is more than 16 MHz, or STC is lower than 8, the accuracy of the ADC may decrease.
- 11)  $Q_{CONV}$  is calculated as  $Q_{CONV} = C_{AREF} * V_{AREF}$ .
- 12) The leakage current definition is a continuous function, as shown in figure ADCx Analogue Input Leakage. The numerical values defined determine the characteristic points of the given continuous linear approximation - they do not define step function.
- 13) The broken wire detection delay against  $V_{AGND}$  is measured in numbers of consecutive precharge cycles at a conversion rate of not more than 250 $\mu$ s. Results below 10% (199<sub>H</sub>).
- 14) The broken wire detection delay against  $V_{AREF}$  is measured in numbers of consecutive precharge cycles at a conversion rate of not more than 10 $\mu$ s. This function is influenced by leakage current, in particular at high temperature. Results above 60% (999<sub>H</sub>).
- 15) Measured without noise.
- 16) For 10-bit conversion the TUE is  $\pm 2$ LSB; for 8-bit conversion the TUE is  $\pm 1$ LSB
- 17) A running conversion may become inexact in case of violating the normal conditions (voltage overshoot).
- 18) If the reference voltage  $V_{AREF}$  increase or the  $V_{DDM}$  decrease, so that  $V_{AREF} = (V_{DDM} + 0.05V \text{ to } V_{DDM} + 0.07V)$ , then the accuracy of the ADC decrease by 4LSB12.

**Table 23 Conversion Time (Operating Conditions apply)**

Parameter	Symbol	Values	Unit	Note
Conversion time with post-calibration	$t_C$ CC	$2 \times T_{ADC} + (4 + STC + n) \times T_{ADCI}$	$\mu$ s	n = 8, 10, 12 for n - bit conversion $T_{ADC} = 1 / f_{FPI}$ $T_{ADCI} = 1 / f_{ADCI}$
Conversion time without post-calibration		$2 \times T_{ADC} + (2 + STC + n) \times T_{ADCI}$		

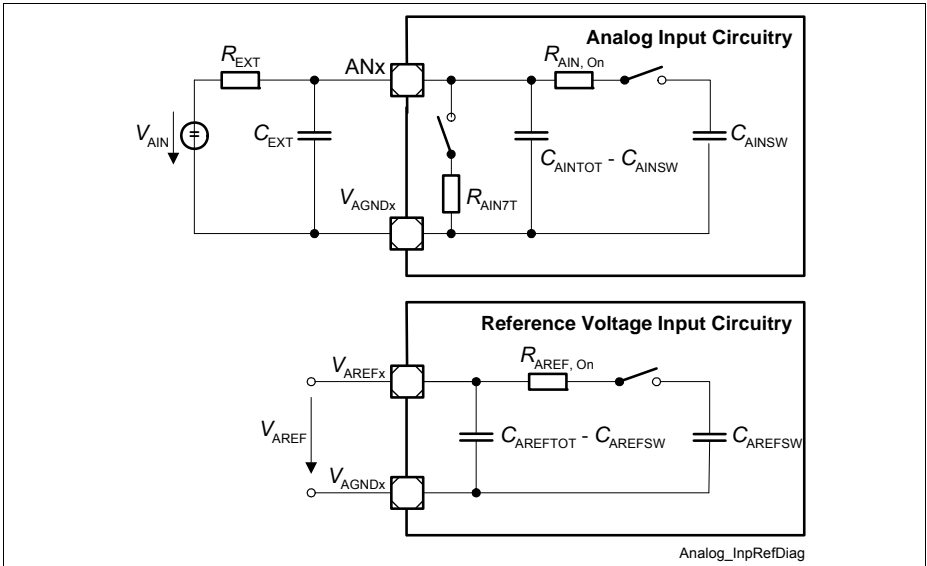


Figure 3 ADCx Input Circuits

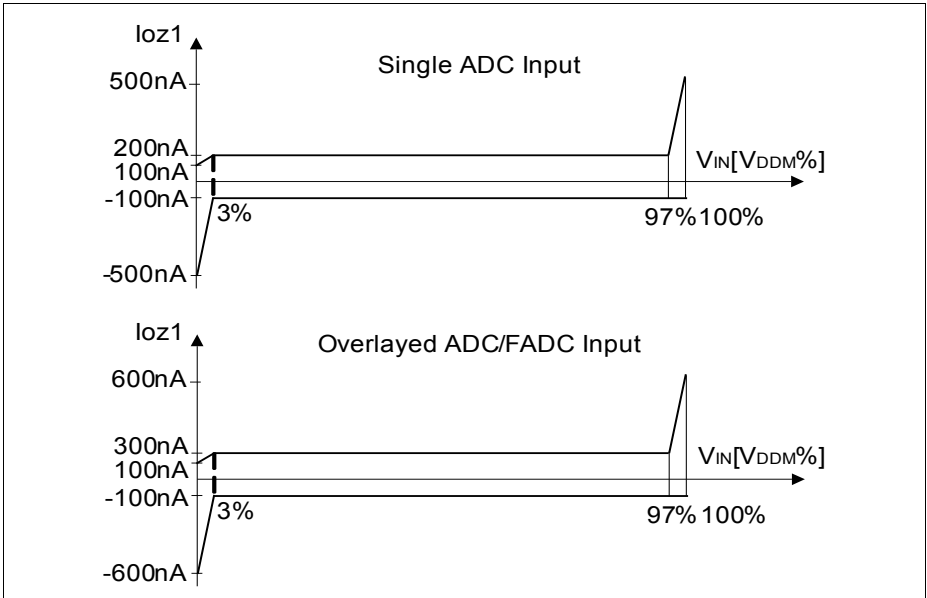


Figure 4 ADCx Analog Inputs Leakage

## Electrical Parameters

## 5.2.3 Fast Analog to Digital Converter (FADC)

FADC parameter are valid for  $V_{DDM} = 4.75\text{ V to }5.25\text{ V}; T_J = 150^\circ\text{C}$ .

**Table 24 FADC Parameters with  $V_{DDM} = 5\text{V}$** 

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
DNL error	$EF_{DNL\ CC}$	-1	–	1	LSB	$V_{IN}$ mode= differential Gain = 1, 2
		-1	–	1	LSB	$V_{IN}$ mode= single ended Gain = 1, 2
		-2	–	2	LSB	$V_{IN}$ mode= differential Gain = 4, 8 $T_J = 150^\circ\text{C}$ <sup>1)</sup>
		-2.5	–	2.5	LSB	$V_{IN}$ mode= differential Gain = 4, 8 $T_J = 160^\circ\text{C}$ <sup>1)</sup>
		-2	–	2	LSB	$V_{IN}$ mode= single ended Gain = 4, 8 $T_J = 150^\circ\text{C}$ <sup>1)</sup>
		-2.5	–	2.5	LSB	$V_{IN}$ mode= single ended Gain = 4, 8 $T_J = 160^\circ\text{C}$ <sup>1)</sup>

## Electrical Parameters

 Table 24 FADC Parameters with  $V_{DDM} = 5V$ 

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
GRADient error	$EF_{GRAD}$ CC	-5	–	5	%	$V_{IN}$ mode= differential ; Gain < 4
		-5	–	5	%	$V_{IN}$ mode= single ended ; Gain < 4
		-5.5	–	5	%	$V_{IN}$ mode= differential ; Gain = 4
		-5.5	–	5	%	$V_{IN}$ mode= single ended ; Gain = 4
		-6	–	6	%	$V_{IN}$ mode= differential ; Gain = 8
		-6	–	6	%	$V_{IN}$ mode= single ended ; Gain = 8
INL error	$EF_{INL}$ CC	-4	–	4	LSB	$V_{IN}$ mode= differential
		-4	–	4	LSB	$V_{IN}$ mode= single ended



## Electrical Parameters

 Table 24 FADC Parameters with  $V_{DDM} = 5V$ 

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Offset error	$EF_{OFF\ CC}$	-90	–	90	mV	$V_{IN}$ mode= differential ; Calibration= No
		-90	–	90	mV	$V_{IN}$ mode= single ended ; Calibration= No
		-20	–	20	mV	$V_{IN}$ mode= differential ; Calibration= Yes <sup>2)3)</sup>
		-20	–	20	mV	$V_{IN}$ mode= single ended ; Calibration= Yes <sup>2)3)</sup>
Error of common mode voltage $V_{FAREFI}/2$	$EF_{REFI\ CC}$	-80	–	80	mV	
Channel amplifier cutoff frequency	$f_{COFF\ CC}$	2	–	–	MHz	
Converter clock	$f_{FADC\ SR}$	4	–	110	MHz	$f_{FADC} = f_{FPI}$
Conversion time	$t_C\ CC$	–	–	21	1 / $f_{FADC}$	For 10-bit conversion
Input resistance of the analog voltage path ( $R_n$ , $R_p$ )	$R_{FAIN\ CC}$	100	–	200	kOhm	
Settling time of a channel amplifier after changing ENN or ENP	$t_{SET\ CC}$	–	–	5	$\mu s$	
Analog input voltage range <sup>4)</sup>	$V_{AINF\ SR}$	$V_{SSM}$	–	$V_{DDP}$	V	
Wakeup time from analog powerdown, fast mode	$t_{FWAF\ CC}$	–	–	5	$\mu s$	
Wakeup time from analog powerdown, slow mode	$t_{FWAS\ CC}$	–	–	10	$\mu s$	

## Electrical Parameters

**Table 24 FADC Parameters with  $V_{DDM} = 5V$** 

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Analog reference ground	$V_{FAGNDI}$ CC	–	0	–	V	Internally generated
Analog reference voltage	$V_{FAREFI}$ CC	–	3.3	– <sup>5)6)</sup>	V	Internally generated

- 1) No missing codes.
- 2) Calibration should be performed at each power-up. In case of a continuous operation, it should be performed minimum once per week.
- 3) The offset error voltage drifts over the whole temperature range maximum  $\pm 3LSB$ .
- 4) The accuracy values is valid between 5% and 90% of  $V_{AINF}$ .
- 5) Voltage overshoot to 4V is permissible, provided the pulse duration is less than 100  $\mu s$  and the cumulated sum of the pulses does not exceed 1 h.
- 6) A running conversion may become inexact in case of violating the normal operating conditions (voltage overshoots).

The calibration procedure should run after each power-up, when all power supply voltages and the reference voltage have stabilized.

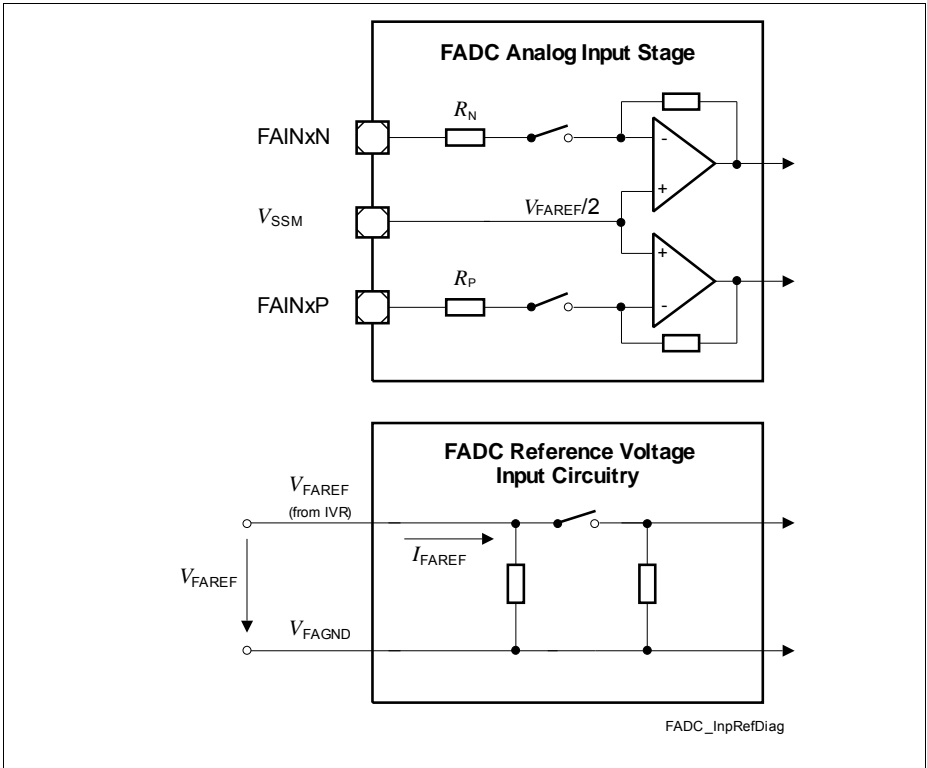


Figure 5 FADC Input Circuits

## 5.2.4 Oscillator Pins

Table 25 OSC\_XTAL Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input current at XTAL1	$I_{IX1}$ CC	-25	–	25	$\mu\text{A}$	$V_{IN} > 0 \text{ V};$ $V_{IN} < V_{DDP}$
Input frequency	$f_{OSC}$ SR	4	–	40	MHz	Direct Input Mode selected
		8	–	25	MHz	External Crystal Mode selected
Oscillator start-up time <sup>1)</sup>	$t_{OSCS}$ CC	–	–	10	ms	
Input high voltage at XTAL1 <sup>2)</sup>	$V_{IHx}$ SR	$0.7 \times V_{DDP}$	–	$V_{DDP} + 0.5$	V	
Input low voltage at XTAL1	$V_{ILx}$ SR	-0.5	–	$0.3 \times V_{DDP}$	V	
Input hysteresis for XTAL1 pad <sup>3)</sup>	HYSAX CC	–	–	200	mV	

1)  $t_{OSCS}$  is defined from the moment when  $V_{DDP} = 3.13\text{V}$  until the oscillations reach an amplitude at XTAL1 of  $0.3 * V_{DDP}$ . The external oscillator circuitry must be optimized by the customer and checked for negative resistance as recommended and specified by crystal suppliers.

2) If the XTAL1 pin is driven by a crystal, reaching a minimum amplitude (peak-to-peak) of  $0.3 * V_{DDP}$  is necessary.

3) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can't be guaranteed that it suppresses switching due to external system noise.

*Note: It is strongly recommended to measure the oscillation allowance (negative resistance) in the final target system (layout) to determine the optimal parameters for the oscillator operation. Please refer to the limits specified by the crystal or ceramic resonator supplier.*

### 5.2.5 Power Supply Current

The total power supply current defined below consists of leakage and switching component.

Application relevant values are typically lower than those given in the following two tables and depend on the customer's system operating conditions (e.g. thermal connection or used application configurations).

The operating conditions for the parameters in the following table are:

$V_{DD}=1.365\text{ V}$ ,  $V_{DDP}=3.47\text{ V}$ ,  $V_{DDM}=5.1\text{ V}$ ,  $f_{LMB}=133 / 80\text{ MHz}$ ,  $T_J=160\text{ °C}$

The realistic power pattern defines the following conditions:

- $T_J=150\text{ °C}$
- $f_{LMB} = f_{PCP} = f_{CPU} = 133 / 80\text{ MHz}$
- $f_{FPI} = 66.5 / 80\text{ MHz}$
- $V_{DD} = 1.326\text{ V}$
- $V_{DDP} = 3.366\text{ V}$
- $V_{DDM} = 5.1\text{ V}$

The max power pattern defines the following conditions:

- $T_J=160\text{ °C}$
- $f_{LMB} = f_{PCP} = f_{CPU} = 133 / 80\text{ MHz}$
- $f_{FPI} = 66.5 / 80\text{ MHz}$
- $V_{DD} = 1.37\text{ V}$
- $V_{DDP} = 3.47\text{ V}$
- $V_{DDM} = 5.25\text{ V}$

**Table 26 Power Supply Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min	Typ.	Max.		
Core active mode supply current <sup>1)</sup>	$I_{DD}$ CC	–	–	310 <sup>2)</sup>	mA	power pattern= max
		–	–	212 <sup>3)</sup>	mA	power pattern= realistic
$I_{DD}$ current at PORST Low	$I_{DD\_PORST}$ CC	–	–	110	mA	
PORST pad output current	$I_{DDPORST}$ CC	13	–	–	mA	
Sum of all 1.3 V supply currents	$I_{DDSUM}$ CC	–	–	212 <sup>4)</sup>	mA	power pattern= realistic
$I_{DDP}$ current at PORST Low	$I_{DDP\_PORS}$ T CC	–	–	6	mA	

## Electrical Parameters

Table 26 Power Supply Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min	Typ.	Max.		
$I_{DDP}$ current no pad activity, LVDS off <sup>5)</sup>	$I_{DDP\_CC}$	–	–	$I_{DDP\_PORST} + 83$	mA	including flash read current
		–	–	$I_{DDP\_PORST} + 62$	mA	including flash programming current <sup>6)</sup>
		–	–	$I_{DDP\_PORST} + 91$ <sup>7)</sup>	mA	including flash erase verify current <sup>6)</sup>
ADC 5V power supply current	$I_{DDM\_CC}$	–	–	32	mA	
Current Consumption of LVDS Pad Pairs	$I_{LVDS\_CC}$	–	–	12	mA	for all LVDS pads in total
EVR Supply current	$I_{V5\_CC}$	–	–	387	mA	power pattern= max; mode = 5V only with ext. pass device; SAK-TC1728F-192F133HL SAK-TC1728F-192F133HR
				382	mA	power pattern= max; mode = 5V only with ext. pass device; SAK-TC1728N-192F133HL SAK-TC1728N-192F133HR
		–	–	292	mA	power pattern= real; mode = 5V only with ext. pass device; SAK-TC1728F-192F133HL SAK-TC1728F-192F133HR
				287	mA	power pattern= real; mode = 5V only with ext. pass device; SAK-TC1728N-192F133HL SAK-TC1728N-192F133HR

## Electrical Parameters

Table 26 Power Supply Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min	Typ.	Max.		
Maximum power dissipation	PD CC	–	–	902	mW	power pattern= max; mode = all external
		–	–	744	mW	power pattern= realistic mode = all external
Maximum power dissipation	PD CC	–	–	2032	mW	power pattern= max; mode = 5V only with ext. pass device; SAK-TC1728F-192F133HL SAK-TC1728F-192F133HR
				2006 <sup>8)</sup>	mW	power pattern= max; mode = 5V only with ext. pass device; SAK-TC1728N-192F133HL SAK-TC1728N-192F133HR
		–	–	1490	mW	power pattern= realistic mode = 5V only with ext. pass device; SAK-TC1728F-192F133HL SAK-TC1728F-192F133HR
		–	–	1464 <sup>9)</sup>	mW	power pattern= realistic mode = 5V only with ext. pass device; SAK-TC1728N-192F133HL SAK-TC1728N-192F133HR

1) Infineon Power Loop: CPU and PCP running, all peripherals active. The power consumption of each customer application will most probably be lower than this value, but must be evaluated separately.

2) The  $I_{DD}$  decreases typically by 62mA if the  $f_{CPU}$  decreases by 50MHz, at constant  $T_j$ .

3) The  $I_{DD}$  decreases typically by 52mA if the  $f_{CPU}$  decreases by 50MHz, at constant  $T_j$ .

4) The  $I_{DD}$  decreases typically by 52mA if the  $f_{CPU}$  decreases by 50MHz, at constant  $T_j$ .

5) For operations including the D-Flash the required current is always lower than the current for non-DFlash operations.

6) Relevant for the power supply dimensioning, not for thermal considerations.

7) In case of erase of Program Flash PF, internal flash array loading effects may generate transient current spikes of up to 15 mA for maximum 5 ms per flash module.

8) Maximum power dissipation for  $f_{CPU} = 80$  MHz and no external pass device is 1695mW.

9) Maximum power dissipation for  $f_{CPU} = 80$  MHz and no external pass device is 1260 mW.

### 5.2.5.1 Calculating the 1.3 V Current Consumption

The current consumption of the 1.3 V rail compose out of two parts:

- Static current consumption
- Dynamic current consumption

The static current consumption is related to the device temperature  $T_J$  and the dynamic current consumption depends of the configured clocking frequencies and the software application executed. These two parts needs to be added in order to get the rail current consumption.

(1)

$$I_0 = 0,674 \left[ \frac{\text{mA}}{\text{C}} \right] \times e^{0,02592 \times T_J[\text{C}]}$$

(2)

$$I_0 = 3,9 \left[ \frac{\text{mA}}{\text{C}} \right] \times e^{0,02085 \times T_J[\text{C}]}$$

Function 1 defines the typical static current consumption and Function 2 defines the maximum static current consumption. Both functions are valid for  $V_{DD} = 1.326 \text{ V}$ .

For the dynamic current consumption using the application pattern and  $f_{LMB} = f_{PCP} = 2 * f_{FPI}$  the function 4 applies:

(3)

$$I_{Dym} = 0,76 \left[ \frac{\text{mA}}{\text{MHz}} \right] \times f_{CPU}[\text{MHz}]$$

For the dynamic current consumption using the application pattern and  $f_{LMB} = f_{PCP} = f_{FPI}$  the function 5 applies:

(4)

$$I_{Dym} = 0,9 \left[ \frac{\text{mA}}{\text{MHz}} \right] \times f_{CPU}[\text{MHz}]$$

and this finally results in

(5)

$$I_{DD} = I_0 + I_{DYM}$$



### 5.3 AC Parameters

All AC parameters are defined with maximum driver strength unless otherwise stated.

#### 5.3.1 Testing Waveforms

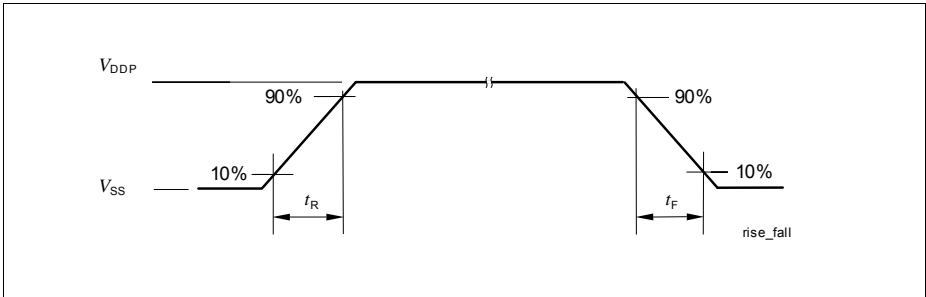


Figure 6 Rise/Fall Time Parameters

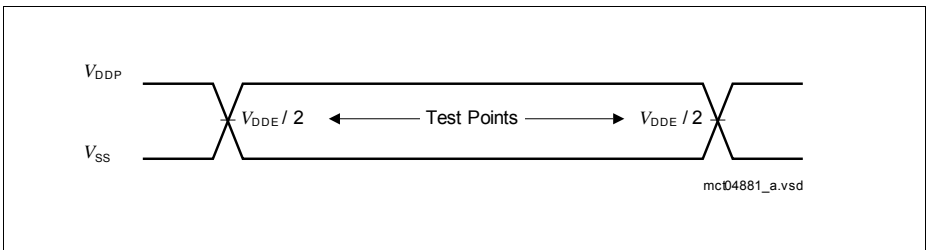


Figure 7 Testing Waveform, Output Delay

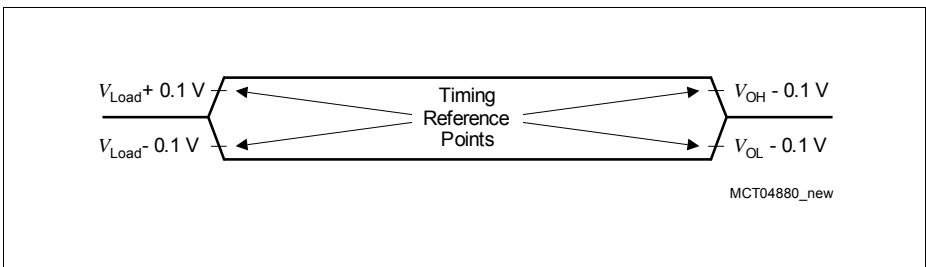
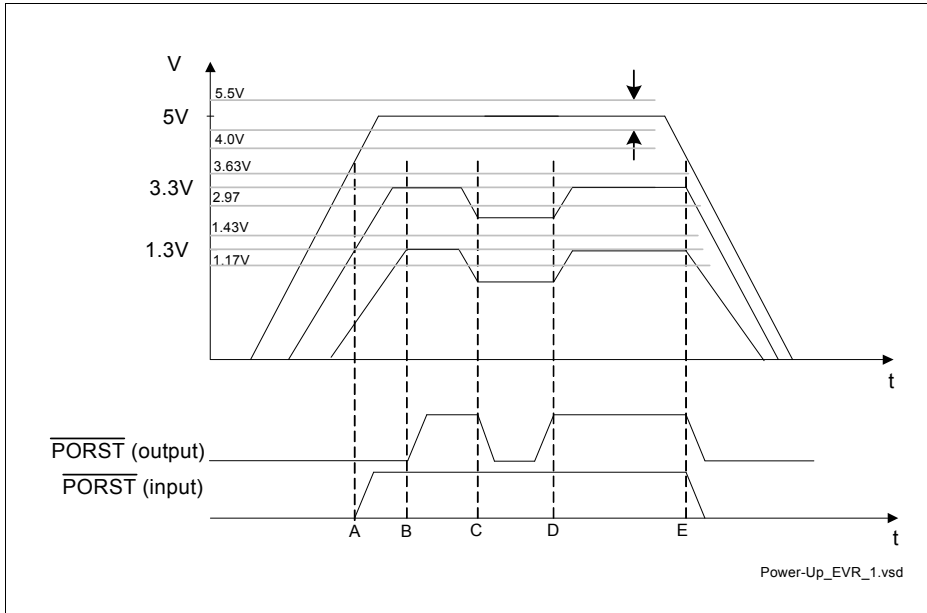


Figure 8 Testing Waveform, Output High Impedance

### 5.3.2 Power Sequencing 5V Supply Only



**Figure 9 5 V / 3.3 V / 1.3 V Power-Up/Down Sequence**

The events for the above points in the power-up/down sequence

- A :external supplied voltage reaches operating level
- B: external supplied and internal generated voltages reaches operating levels
- C: internal generated voltage drops below operating level
- D: internal generated voltage resumes operating level
- E: external supplied voltage leaves operating level

P0.4 and P0.5 should be kept at the selected setting of '0' or '1' until external supplied voltage has reached its operating level.

The following list of rules applies to the power-up/down sequence:

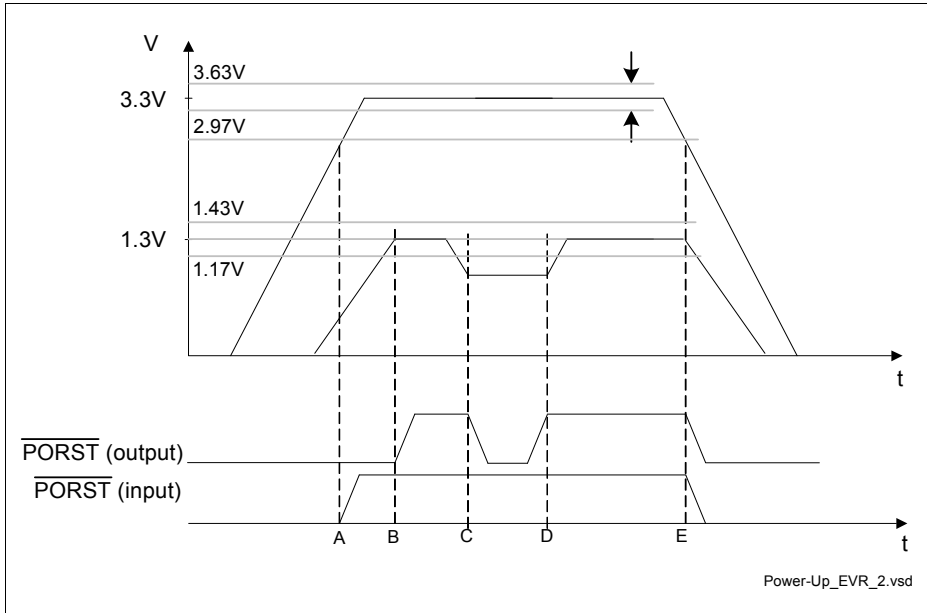
- All ground pins  $V_{SS}$  must be externally connected to one single star point in the system. Regarding the DC current component, all ground pins are internally directly connected.
- The latch-up risk is minimized if the I/O currents are limited to:
  - 20 mA for one pin group
  - AND 100 mA for the completed device I/Os

---

**Electrical Parameters**

- AND additionally before power-up / after power-down:
  - 1 mA for one pin in inactive mode (0 V on all power supplies)
- The PORST signal may be deactivated after all VDD5, and VAREF0 power-supplies and the oscillator have reached stable operation, within the normal operating conditions.
- At normal power down the PORST signal should be activated within the normal operating range, and then the power supplies may be switched off. Care must be taken that all Flash write or delete sequences have been completed.
- In case of a power-loss at any power-supply, all power supplies must be powered-down, conforming at the same time to the rule number 2.
- Although not necessary, it is additionally recommended that all power supplies are powered-up/down together in a controlled way, as tight to each other as possible.
- Additionally, regarding the ADC reference voltage VAREF0:
  - VAREF0 must power-up at the same time or later then VDDM, and
  - VAREF0 must power-down either earlier or at latest to satisfy the condition  $VAREF0 < VDDM + 0.5 \text{ V}$ . This is required in order to prevent discharge of VAREF0 filter capacitance through the ESD diodes through the VDDM power supply. In case of discharging the reference capacitance through the ESD diodes, the current must be lower than 5 mA.

### 5.3.3 Power Sequencing 3.3V Supply Only



**Figure 10 3.3 V / 1.3 V Power-Up/Down Sequence**

The events for the above points in the power-up/down sequence

- A :external supplied voltage reaches operating level
- B: external supplied and internal generated voltages reaches operating levels
- C: internal generated voltage drops below operating level
- D: internal generated voltage resumes operating level
- E: external supplied voltage leaves operating level

P0.4 and P0.5 should be kept at the selected setting of '0' or '1' until external supplied voltage has reached its operating level.

The following list of rules applies to the power-up/down sequence:

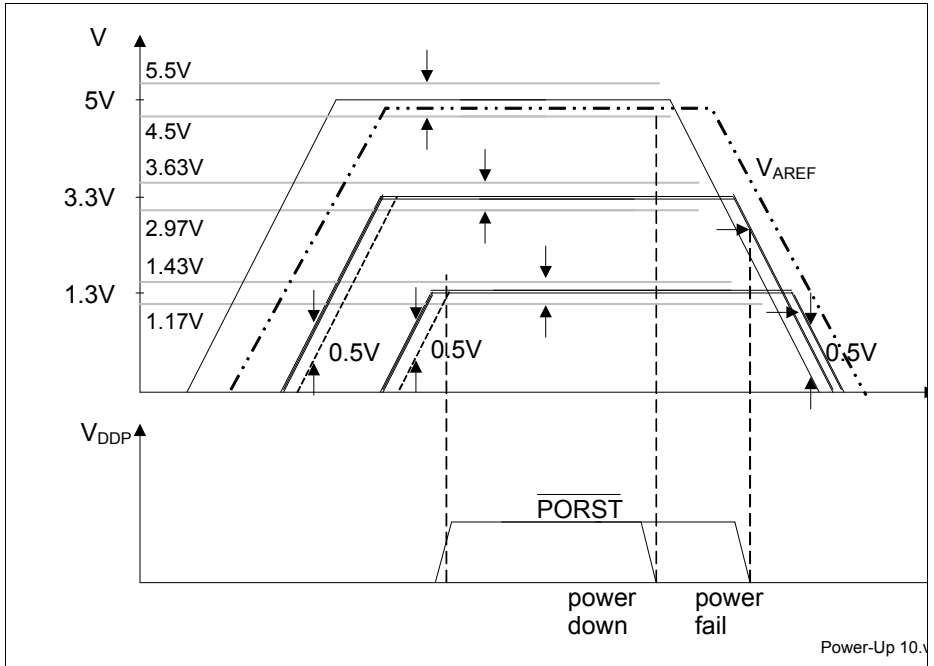
- All ground pins  $V_{SS}$  must be externally connected to one single star point in the system. Regarding the DC current component, all ground pins are internally directly connected.
- The latch-up risk is minimized if the I/O currents are limited to:
  - 20 mA for one pin group
  - AND 100 mA for the completed device I/Os

---

**Electrical Parameters**

- AND additionally before power-up / after power-down:
  - 1 mA for one pin in inactive mode (0 V on all power supplies)
- The PORST signal may be deactivated after all VDD3.3, and VAREF0 power-supplies and the oscillator have reached stable operation, within the normal operating conditions.
- At normal power down the PORST signal should be activated within the normal operating range, and then the power supplies may be switched off. Care must be taken that all Flash write or delete sequences have been completed.
- In case of a power-loss at any power-supply, all power supplies must be powered-down, conforming at the same time to the rule number 2.
- Although not necessary, it is additionally recommended that all power supplies are powered-up/down together in a controlled way, as tight to each other as possible.
- Additionally, regarding the ADC reference voltage VAREF0:
  - VAREF0 must power-up at the same time or later then VDDM, and
  - VAREF0 must power-down either earlier or at latest to satisfy the condition  $VAREF0 < VDDM + 0.5 \text{ V}$ . This is required in order to prevent discharge of VAREF0 filter capacitance through the ESD diodes through the VDDM power supply. In case of discharging the reference capacitance through the ESD diodes, the current must be lower than 5 mA.

### 5.3.4 Power Sequencing all Voltages supplied from External



**Figure 11 5 V / 3.3 V / 1.3 V Power-Up/Down Sequence**

P0.4 and P0.5 should be kept at the selected setting until external supplied voltage has reached its operating level.

The following list of rules applies to the power-up/down sequence:

- All ground pins  $V_{SS}$  must be externally connected to one single star point in the system. Regarding the DC current component, all ground pins are internally directly connected.
- At any moment in time to avoid increased latch-up risk, each power supply must be higher than any lower\_power\_supply - 0.5 V, or:  $V_{DD5} > V_{DDP} - 0.5 \text{ V}$ ;  $V_{DD5} > V_{DD} - 0.5 \text{ V}$ ;  $V_{DDP} > V_{DD} - 0.5 \text{ V}$ , see [Figure 11](#).
  - The latch-up risk is minimized if the I/O currents are limited to:
    - 20 mA for one pin group
    - AND 100 mA for the completed device I/Os
    - AND additionally before power-up / after power-down:
      - 1 mA for one pin in inactive mode (0 V on all power supplies)

---

**Electrical Parameters**

- During power-up and power-down, the voltage difference between the power supply pins of the same voltage (3.3 V, 1.3 V, and 5 V) with different names, that are internally connected via diodes, must be lower than 100 mV. On the other hand, all power supply pins with the same name (for example all VDDP), are internally directly connected. It is recommended that the power pins of the same voltage are driven by a single power supply.
- The PORST signal may be deactivated after all VDD5, VDDP, VDD, and VAREF0 power-supplies and the oscillator have reached stable operation, within the normal operating conditions.
- At normal power down the PORST signal should be activated within the normal operating range, and then the power supplies may be switched off. Care must be taken that all Flash write or delete sequences have been completed.
- At power fail the PORST signal must be activated at latest when any 3.3 V or 1.3 V power supply voltage falls 10% below the nominal level. If, under these conditions, the PORST is activated during a Flash write, only the memory row that was the target of the write at the moment of the power loss will contain unreliable content. In order to ensure clean power-down behavior, the PORST signal should be activated as close as possible to the normal operating voltage range.
- In case of a power-loss at any power-supply, all power supplies must be powered-down, conforming at the same time to the rules number 2 and 4.
- Although not necessary, it is additionally recommended that all power supplies are powered-up/down together in a controlled way, as tight to each other as possible.
- Additionally, regarding the ADC reference voltage VAREF0:
  - VAREF0 must power-up at the same time or later then VDDM, and
  - VAREF0 must power-down either earlier or at latest to satisfy the condition  $VAREF0 < VDDM + 0.5\text{ V}$ . This is required in order to prevent discharge of VAREF0 filter capacitance through the ESD diodes through the VDDM power supply. In case of discharging the reference capacitance through the ESD diodes, the current must be lower than 5 mA.

### 5.3.5 Power, Pad and Reset Timing

**Table 27 Reset Timings Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Application Reset Boot Time <sup>1)2)</sup>	$t_B$ CC	150	–	810	$\mu\text{s}$	
Power on Reset Boot Time <sup>3)4)</sup>	$t_{BP}$ CC	–	–	2.5	ms	
EVR Startup time from Supply ramp-up till PORST release	$t_{EVR}$ CC	–	860	1100	$\mu\text{s}$	
HWCFG pins hold time from ESR0 rising edge	$t_{HDH}$ SR	$16 / f_{FPI}$	–	–	ns	
HWCFG pins setup time to ESR0 rising edge	$t_{HDS}$ CC	0	–	–	ns	
Ports inactive after ESR0 reset active	$t_{PI}$ CC	–	–	$8/f_{FPI}$	ns	
Ports inactive after PORST reset active <sup>5)</sup>	$t_{PIP}$ CC	–	–	150	ns	
Minimum PORST active time after power supplies are stable at operating levels	$t_{POA}$ CC	4.5	–	–	ms	<sup>6)</sup>
TESTMODE / TRST hold time from PORST rising edge	$t_{POH}$ SR	100	–	–	ns	
PORST rise time	$t_{POR}$ SR	–	–	50	ms	



**Table 27 Reset Timings Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
$\overline{\text{TESTMODE}} / \overline{\text{TRST}}$ setup time to PORST rising edge	$t_{\text{POS SR}}$	0	–	–	ns	
Application Reset inactive after PORST deassertion	$t_{\text{POR\_APP SR}}$	–	–	40 <sup>7)</sup>	μs	

- 1) The duration of the boot time is defined between the rising edge of the internal application reset and the clock cycle when the first user instruction has entered the CPU pipeline and its processing starts.
- 2) The given time includes the time of the internal reset extension for a configured value of SCU\_RSTCNTCON.RELSA = 0x05BE.
- 3) The duration of the boot time is defined between the rising edge of the  $\overline{\text{PORST}}$  and the clock cycle when the first user instruction has entered the CPU pipeline and its processing starts.
- 4) The given time includes the internal reset extension time for the System and Application Reset which is visible through ESR0.
- 5) This parameter includes the delay of the analog spike filter in the  $\overline{\text{PORST}}$  pad.
- 6) This parameter represents the additional time required to ensure that external crystal is stable and operational at  $\overline{\text{PORST}}$ .
- 7) Application Reset is assumed not to be extended from external, otherwise the time extends by the time the Application Reset is extended.

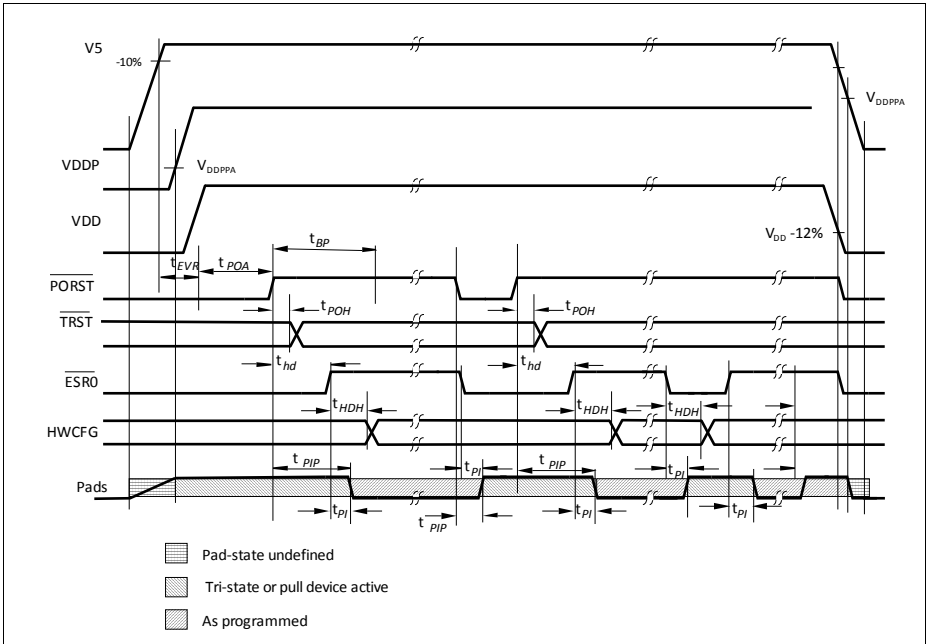


Figure 12 Power, Pad and Reset Timing

## 5.3.6 EVR Parameter

Table 28 Pass device detector

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Pull-up current at VDPG	$I_{PU\_VDPG}$ SR	0.7	–	2.0	mA	$V_{DD5} \geq 4.5V$ ; $V_{DD5} \leq 5.5V$
Input low voltage	$V_{IL}$ SR	0	–	1.5	V	

Table 29 EVR Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Output Capacitance on $V_{DDP}$	$C_{OUT33}$ CC	–	6.8	–	$\mu F$	$I_{LOAD} > 310$ mA; ESR < 50m $\Omega$ ;a with external pass device, additional decoupling capacitor on each supply pin
Output Capacitance on $V_{DD}$	$C_{OUT13}$ CC	–	6.8	–	$\mu F$	$I_{LOAD} < 250$ mA; ESR < 50m $\Omega$ ; additional decoupling capacitor on each supply pin
Input Capacitance on $V_5$	$C_{IN5}$ CC	–	6.8	–	$\mu F$	depending on ext. regulator
Undervoltage Reset threshold for external supply	$V_{RST5}$ CC	–	–	2.97	V	3.3V single supply
		–	–	4.5	V	5.0 single supply
Output accuracy of EVR33 after trimming	$\Delta V_{OUT33}$ CC	-80	–	+80	mV	$4.5 \leq V_{IN} \leq 5.5V$ ; $1$ mA $\leq I_{OUT} \leq 310$ mA
Dynamic Load Regulation of EVR33	$\Delta V_{LOREG}$ 33 CC	-225	–	+225	mV	dl / dt = 150mA / 10 ns

## Electrical Parameters

**Table 29 EVR Parameters (cont'd)**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Dynamic Line Regulation of EVR33	$\Delta V_{LIREG_{33}}^{CC}$	-25	–	+25	mV	$dV5 / dt = 1V / ms$ 1 ... 310mA, 4.5V ... 5.5V
Undervoltage Reset threshold for EVR33	$V_{RST33}^{CC}$	–	–	2.97	V	
Current drawn from EVR33 for external devices with internal pass devices.	$EXI_{33}^{SR}$	–	–	30	mA	No inductive loads allowed. Decoupling capacitor > 330 nF
Output accuracy of EVR13 after trimming	$\Delta V_{OUT13}^{CC}$	-30	–	+30	mV	$2.97V \leq V_{IN} \leq 3.63V$ ; $1 mA \leq I_{OUT} \leq 250mA$
Dynamic Load Regulation of EVR13	$\Delta V_{LOREG_{13}}^{CC}$	-100	–	+100	mV	5.0V/3.3V single supply, $dI / dt = 150mA / 10 ns$
Dynamic Line Regulation of EVR13	$\Delta V_{LIREG_{13}}^{CC}$	-10	–	+10	mV	5.0V/3.3V single supply, $dV5 / dt=1V / ms$ 1 ... 250mA, 2.97V ... 3.63V
Undervoltage Reset threshold for EVR13	$V_{RST13}^{CC}$	–	–	1.17	V	
Current drawn from EVR13 for external devices	$EXI_{13}^{SR}$	–	–	10	mA	No inductive loads allowed. Decoupling capacitor > 100 nF
Supply ramp-up	$SR$ $SR$	–	–	50	V/ms	

### 5.3.7 Phase Locked Loop (PLL)

**Table 30 PLL\_SysClk Parameters**

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Accumulated Jitter	$D_P$	CC	-7	–	7	ns	
PLL base frequency	$f_{PLLBASE}$	CC	50	200	320	MHz	
VCO input frequency	$f_{REF}$	CC	8	–	16	MHz	
VCO frequency range	$f_{VCO}$	CC	400	–	720	MHz	
PLL lock-in time	$t_L$	CC	14	–	200	$\mu$ s	$N > 32$
			14	–	400	$\mu$ s	$N \leq 32$

#### Phase Locked Loop Operation

When PLL operation is enabled and configured, the PLL clock  $f_{VCO}$  (and with it the LMB-Bus clock  $f_{LMB}$ ) is constantly adjusted to the selected frequency. The PLL is constantly adjusting its output frequency to correspond to the input frequency (from crystal or clock source), resulting in an accumulated jitter that is limited. This means that the relative deviation for periods of more than one clock cycle is lower than for a single clock cycle.

This is especially important for bus cycles using wait states and for the operation of timers, serial interfaces, etc. For all slower operations and longer periods (e.g. pulse train generation or measurement, lower baudrates, etc.) the deviation caused by the PLL jitter is negligible.

Two formulas are defined for the (absolute) approximate maximum value of jitter  $D_m$  in [ns] dependent on the  $K2$  - factor, the LMB clock frequency  $f_{LMB}$  in [MHz], and the number  $m$  of consecutive  $f_{LMB}$  clock periods.

for  $(K2 \leq 100)$  and  $(m \leq (f_{LMB}[\text{MHz}])/2)$

$$|D_m[\text{ns}]| = \left( \frac{740}{K2 \times f_{LMB}[\text{MHz}]} + 5 \right) \times \left( \frac{(1 - 0,01 \times K2) \times (m - 1)}{0,5 \times f_{LMB}[\text{MHz}] - 1} + 0,01 \times K2 \right) \quad (6)$$

$$\text{else} \quad |D_m[\text{ns}]| = \frac{740}{K2 \times f_{LMB}[\text{MHz}]} + 5 \quad (7)$$

## Electrical Parameters

With rising number  $m$  of clock cycles the maximum jitter increases linearly up to a value of  $m$  that is defined by the K2-factor of the PLL. Beyond this value of  $m$  the maximum accumulated jitter remains at a constant value. Further, a lower LMB-Bus clock frequency  $f_{LMB}$  results in a higher absolute maximum jitter value.

*Note: The specified PLL jitter values are valid if the capacitive load per pin does not exceed  $C_L = 20$  pF with the maximum driver and sharp edge.*

### Oscillator Watchdog (OSC\_WDT)

The expected input frequency is selected via the bit field SCU\_OSCCON.OSCVAL. The OSC\_WDT checks for too low frequencies and for too high frequencies.

The frequency that is monitored is  $f_{OSCREF}$  which is derived for  $f_{OSC}$ .

$$f_{OSCREF} = \frac{f_{OSC}}{OSCVAL + 1} \quad (8)$$

The divider value SCU\_OSCCON.OSCVAL has to be selected in a way that  $f_{OSCREF}$  is 2.5 MHz.

*Note:  $f_{OSCREF}$  has to be within the range of 2 MHz to 3 MHz and should be as close as possible to 2.5 MHz.*

The monitored frequency is too low if it is below 1.25 MHz and too high if it is above 7.5 MHz. This leads to the following two conditions:

- Too low:  $f_{OSC} < 1.25 \text{ MHz} \times (\text{SCU\_OSCCON.OSCVAL} + 1)$
- Too high:  $f_{OSC} > 7.5 \text{ MHz} \times (\text{SCU\_OSCCON.OSCVAL} + 1)$

*Note: The accuracy is 30% for these boundaries.*

### 5.3.8 ERAY Phase Locked Loop (ERAY\_PLL)

**Table 31 PLL\_ERAY Parameters**

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Accumulated jitter at SYSCLK pin	$D_{PP}$	CC	-0.8	–	0.8	ns	
Accumulated_Jitter	$D_P$	CC	-0.5	–	0.5	ns	
PLL Base Frequency of the ERAY PLL	$f_{PLLBASE\_ERAY}$	CC	50	250	360	MHz	
VCO input frequency of the ERAY PLL	$f_{REF}$	CC	20	–	40	MHz	
VCO frequency range of the ERAY PLL	$f_{VCO\_ERAY}$	CC	450	–	500	MHz	
PLL lock-in time	$t_L$	CC	5.6	–	200	$\mu$ s	

Note: The specified PLL jitter values are valid if the capacitive load per pin does not exceed  $C_L = 20$  pF with the maximum driver and sharp edge.

### 5.3.9 JTAG Interface Timing

The following parameters are applicable for communication through the JTAG debug interface. The JTAG module is fully compliant with IEEE1149.1-2000.

*Note: These parameters are not subject to production test but verified by design and/or characterization.*

**Table 32 JTAG Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
TCK clock period	$t_1$ SR	25	–	–	ns	
TCK high time	$t_2$ SR	10	–	–	ns	
TCK low time	$t_3$ SR	10	–	–	ns	
TCK clock rise time	$t_4$ SR	–	–	4	ns	
TCK clock fall time	$t_5$ SR	–	–	4	ns	
TDI/TMS setup to TCK rising edge	$t_6$ SR	6.0	–	–	ns	
TDI/TMS hold after TCK rising edge	$t_7$ SR	6.0	–	–	ns	
TDO valid after TCK falling edge <sup>1)</sup>	$t_8$ CC	3.0	–	–	ns	$C_L = 20$ pF
		–	–	13	ns	$C_L = 50$ pF
TDO high impedance to valid from TCK falling edge <sup>2)</sup>	$t_9$ CC	–	–	14	ns	$C_L = 50$ pF
TDO valid output to high impedance from TCK falling edge	$t_{10}$ CC	–	–	13.5	ns	$C_L = 50$ pF
TDO hold after TCK falling edge	$t_{18}$ CC	2	–	–	ns	

1) The falling edge on TCK is used to generate the TDO timing.

2) The setup time for TDO is given implicitly by the TCK cycle time.



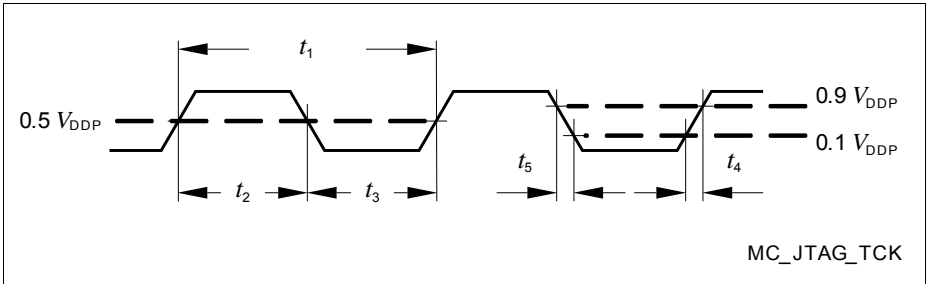


Figure 13 Test Clock Timing (TCK)

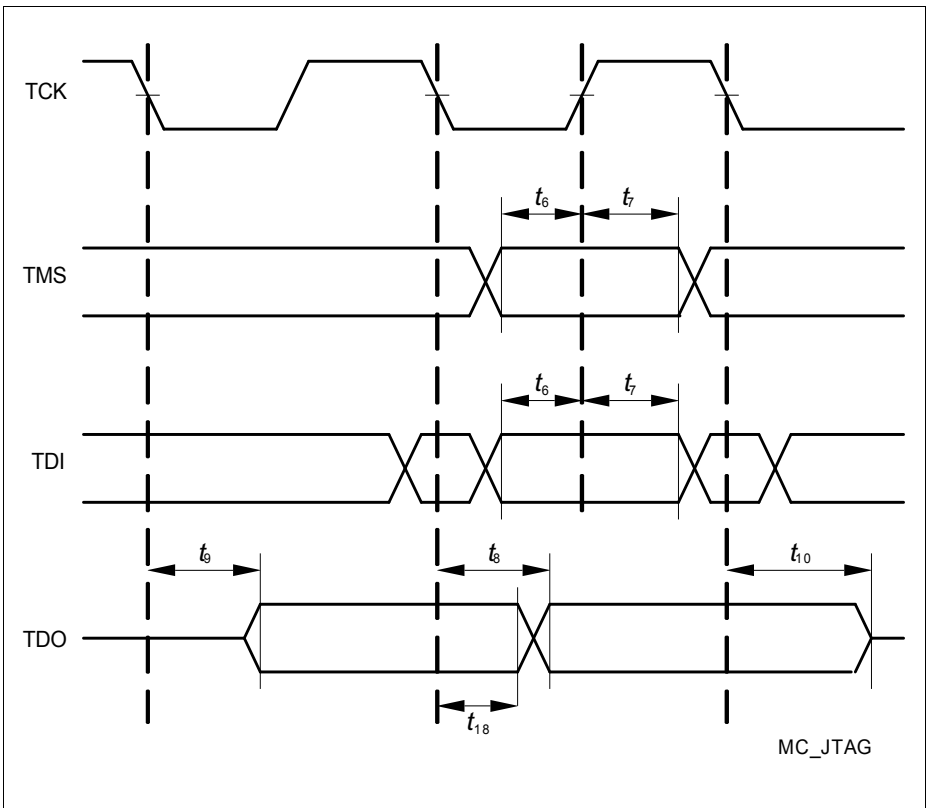


Figure 14 JTAG Timing

### 5.3.10 DAP Interface Timing

The following parameters are applicable for communication through the DAP debug interface.

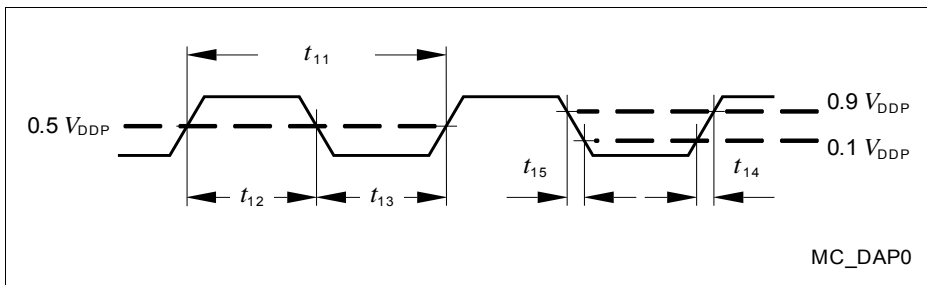
*Note: These parameters are not subject to production test but verified by design and/or characterization.*

**Table 33 DAP Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
DAP0 clock period <sup>1)</sup>	$t_{TCK}$ SR	12.5	–	–	ns	
DAP0 high time	$t_{12}$ SR	4	–	–	ns	
DAP0 low time <sup>1)</sup>	$t_{13}$ SR	4	–	–	ns	
DAP0 clock rise time	$t_{14}$ SR	–	–	2	ns	
DAP0 clock fall time	$t_{15}$ SR	–	–	2	ns	
DAP1 setup to DAP0 rising edge	$t_{16}$ SR	6.0	–	–	ns	
DAP1 hold after DAP0 rising edge	$t_{17}$ SR	6.0	–	–	ns	
DAP1 valid per DAP0 clock period <sup>2)</sup>	$t_{19}$ CC	8	–	–	ns	$C_L = 20$ pF; $f = 80$ MHz
		10	–	–	ns	$C_L = 50$ pF; $f = 40$ MHz

1) See the DAP chapter for clock rate restrictions in the Active::IDLE protocol state.

2) The Host has to find a suitable sampling point by analyzing the sync telegram response.



**Figure 15 Test Clock Timing (DAP0)**

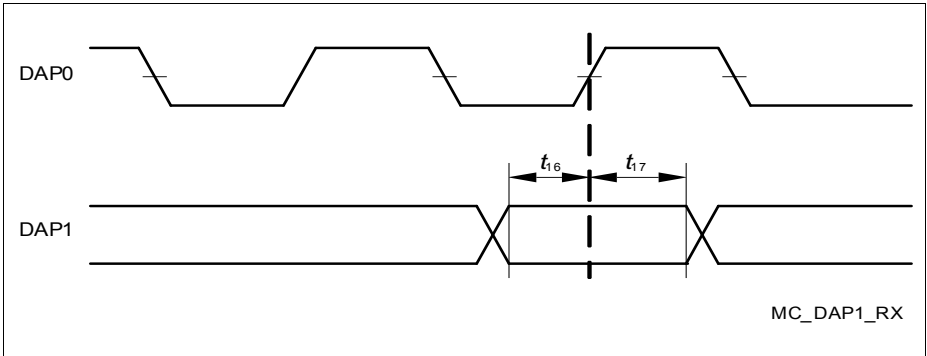


Figure 16 DAP Timing Host to Device

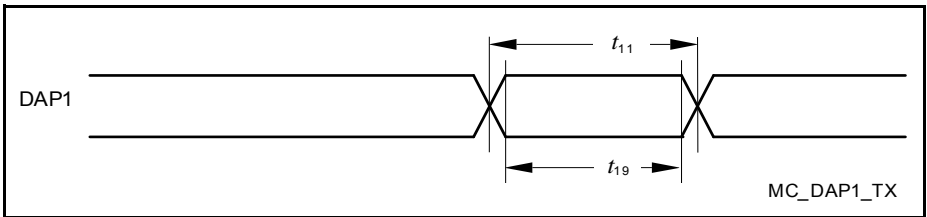


Figure 17 DAP Timing Device to Host

### 5.3.11 Peripheral Timings

Note: Peripheral timings are not subjected to production test. They are verified by design / characterization.

#### 5.3.11.1 Micro Link Interface (MLI) Timing

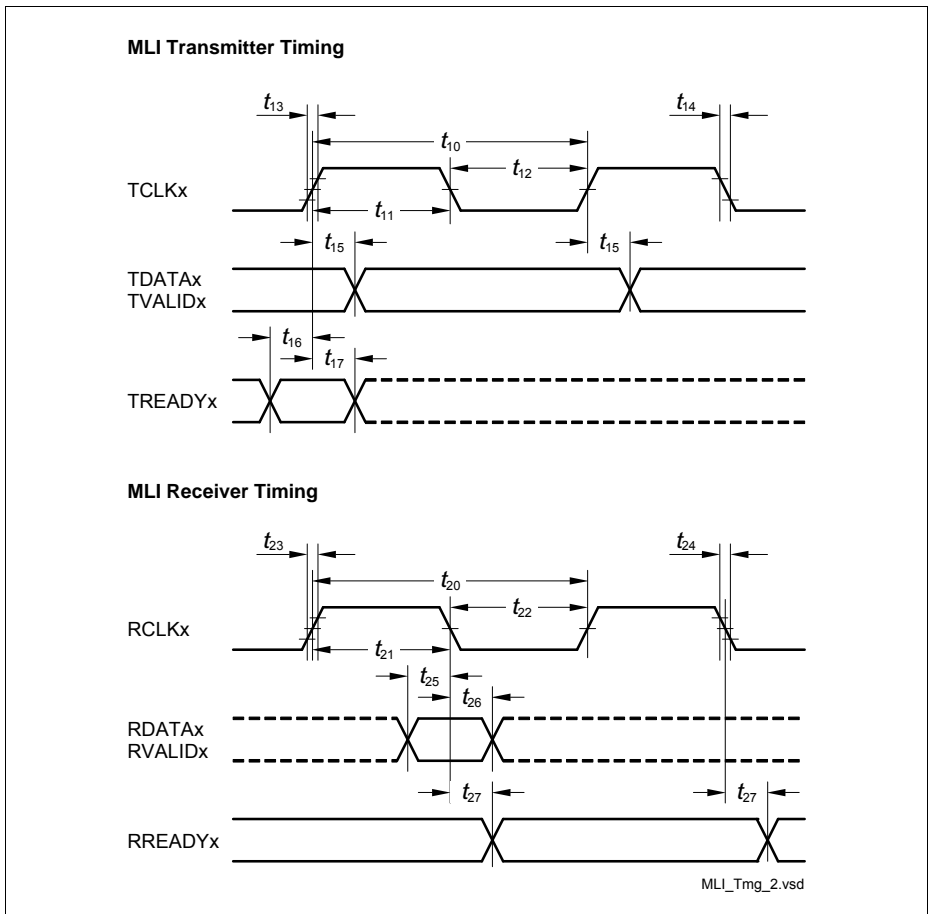


Figure 18 MLI Interface Timing

**Electrical Parameters**

Note: The generation of RREADY<sub>x</sub> is in the input clock domain of the receiver. The reception of TREADY<sub>x</sub> is asynchronous to TCLK<sub>x</sub>.

The MLI parameters are valid for C<sub>L</sub> = 50 pF, strong driver medium edge.

**Table 34 MLI Receiver**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
RCLK clock period	$t_{20}$ SR	$1 / f_{FPI}$	–	–	ns	
RCLK high time <sup>1)2)</sup>	$t_{21}$ SR	–	$0.5 \times t_{20}$	–	ns	
RCLK low time <sup>1)2)</sup>	$t_{22}$ SR	–	$0.5 \times t_{20}$	–	ns	
RCLK rise time <sup>3)</sup>	$t_{23}$ SR	–	–	4	ns	
RCLK fall time <sup>3)</sup>	$t_{24}$ SR	–	–	4	ns	
RDATA/RVALID setup time before RCLK falling edge	$t_{25}$ SR	4.2	–	–	ns	
RDATA/RVALID hold time after RCLK falling edge	$t_{26}$ SR	2.2	–	–	ns	
RREADY output delay time	$t_{27}$ SR	0	–	16	ns	

1) The following formula is valid:  $t_{21} + t_{22} = t_{20}$ .

2) Min and Max values for this parameter can be derived from the typ. value by considering the other receiver timing parameters.

3) The RCLK max. input rise/fall times are best case parameters for f<sub>FPI</sub>max. For reduction of EMI, slower input signal rise/fall times can be used for longer RCLK clock periods.

**Table 35 MLI Transmitter**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
TCLK clock period	$t_{10}$ CC	$2 \times 1 / f_{FPI}$	–	–	ns	
TCLK high time <sup>1)2)</sup>	$t_{11}$ CC	$0.45 \times t_{10}$	$0.5 \times t_{10}$	$0.55 \times t_{10}$	ns	
TCLK low time <sup>1)2)</sup>	$t_{12}$ CC	$0.45 \times t_{10}$	$0.5 \times t_{10}$	$0.55 \times t_{10}$	ns	

## Electrical Parameters

**Table 35 MLI Transmitter**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
TCLK rise time	$t_{13}$ CC	–	–	$0.3 \times t_{10}^{3)}$	ns	
TCLK fall time	$t_{14}$ CC	–	–	$0.3 \times t_{10}^{3)}$	ns	
TDATA/TVALID output delay time	$t_{15}$ CC	-3	–	4.4	ns	
TREADY setup time before TCLK rising edge	$t_{16}$ SR	18	–	–	ns	
TREADY hold time after TCLK rising edge	$t_{17}$ SR	-2	–	–	ns	

1) The following formula is valid:  $t_{11} + t_{12} = t_{10}$ .

2) The min./max. TCLK low/high times  $t_{11}/t_{12}$  include the PLL jitter of fSYS. Fractional divider settings must be regarded additionally to  $t_{11} / t_{12}$ .

3) For high-speed MLI interface, strong driver sharp or medium edge selection (class A2 pad) is recommended for TCLK.

### 5.3.11.2 Micro Second Channel (MSC) Interface Timing

The MSC parameters are valid for  $C_L = 50$  pF.

**Table 36 MSC Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
FCLP clock period <sup>1)2)</sup>	$t_{40}$ CC	$2 \times T_{MSC}^{3)}$	–	–	ns	

## Electrical Parameters

Table 36 MSC Parameters

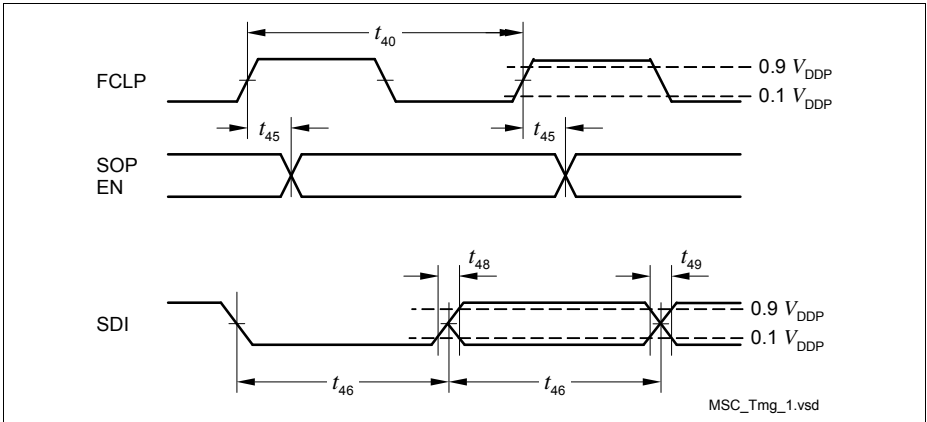
Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
SOP <sup>4)</sup> /ENx outputs delay from FCLP <sup>4)</sup> rising edge	$t_{45}$ CC	-2	–	5	ns	ENx with strong driver and sharp (minus) edge; LVDS mode
		-5	–	5	ns	ENx with strong driver and sharp (minus) edge; CMOS mode
		-2	–	10	ns	ENx with strong driver and medium (minus) edge
		0	–	21	ns	ENx with strong driver and soft edge
SDI bit time	$t_{46}$ CC	8 x $T_{MSC}$	–	–	ns	
SDI rise time	$t_{48}$ SR	–	–	200	ns	
SDI fall time	$t_{49}$ SR	–	–	200	ns	

1) FCLP signal rise/fall times are only defined by the pad rise/fall times.

2) FCLP signal high and low can be minimum 1 /  $T_{MSC}$

3)  $T_{MSC} = T_{SYS} = 1 / f_{SYS}$ .

4) SOP / FCLP either propagated by LVDS or by CMOS strong driver and non soft edge.



**Figure 19 MSC Interface Timing**

*Note: The data at SOP should be sampled with the falling edge of FCLP in the target device.*



### 5.3.11.3 SSC Master/Slave Mode Timing

The SSC parameters are valid for  $C_L = 50$  pF, strong driver medium edge.

**Table 37 Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
SCLK clock period <sup>1)2)3)</sup>	$t_{50}$ CC	$2 \times 1 / f_{FPI}$	–	–	ns	
MTSR/SLSOx delay from SCLK rising edge	$t_{51}$ CC	0	–	8	ns	
MRST setup to SCLK latching edge <sup>3)</sup>	$t_{52}$ SR	16.5	–	–	ns	
MRST hold from SCLK latching edge <sup>3)</sup>	$t_{53}$ SR	0	–	–	ns	
SCLK input clock period <sup>1)3)</sup>	$t_{54}$ SR	$4 \times 1 / f_{FPI}$	–	–	ns	
SCLK input clock duty cycle	$t_{55\_t_{54}}$ SR	45	–	55	%	
MTSR setup to SCLK latching edge <sup>3)4)</sup>	$t_{56}$ SR	$1 / f_{FPI} + 1$	–	–	ns	
MTSR hold from SCLK latching edge	$t_{57}$ SR	$1 / f_{FPI} + 5$	–	–	ns	
SLSI setup to first SCLK latching edge	$t_{58}$ SR	$1 / f_{FPI} + 5$	–	–	ns	
SLSI hold from last SCLK latching edge <sup>5)</sup>	$t_{59}$ SR	7	–	–	ns	
MRST delay from SCLK shift edge	$t_{60}$ CC	0	–	16.5	ns	
SLSI to valid data on MRST	$t_{61}$ CC	–	–	16.5	ns	

1) SCLK signal rise/fall times are the same as the rise/fall times of the pad.

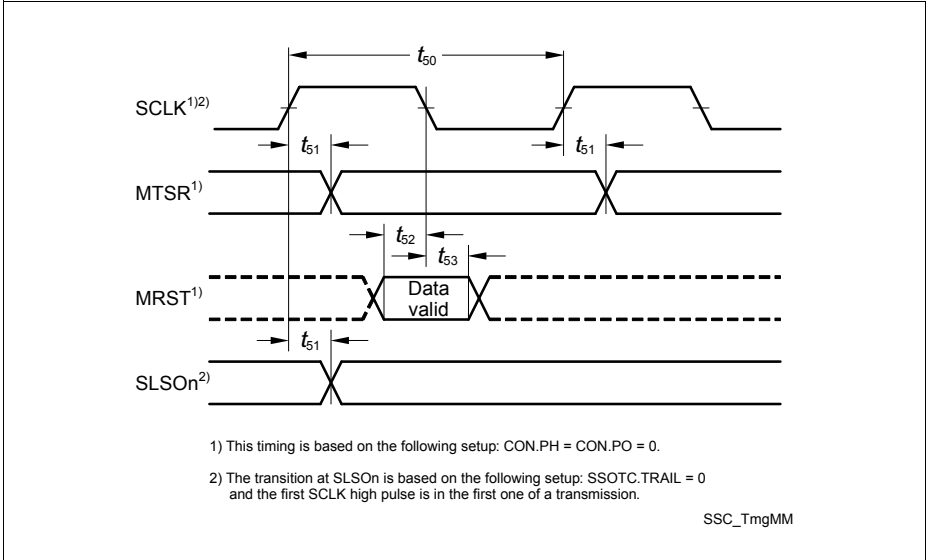
2) SCLK signal high and low times can be minimum 1xT.

3)  $T_{min} = T_{SYS} = 1/f_{SYS}$ .

4) Fractional divider switched off, internal baud rate generation used.

**Electrical Parameters**

- 5) For CON.PH=1 slave select must not be removed before the following shifting edge. This mean, that what ever is configured (shifting / latching first), SLSI must not be de-activated before the last trailing edge from the pair of shifting / latching edges.



**Figure 20 Master Mode Timing**

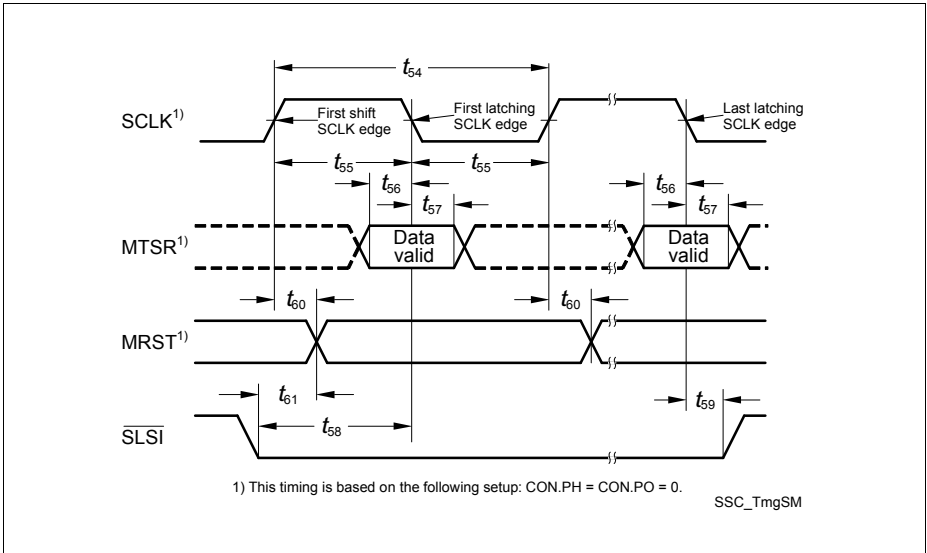


Figure 21 Slave Mode Timing

### 5.3.11.4 ERAY Interface Timing

The timings of this section are valid for the strong driver and either sharp edge or medium edge settings of the output drivers with  $C_L = 25 \text{ pF}$ .

The ERAY interface is only available for SAK-TC1728F-192F133HR / SAK-TC1728F-192F133HR.

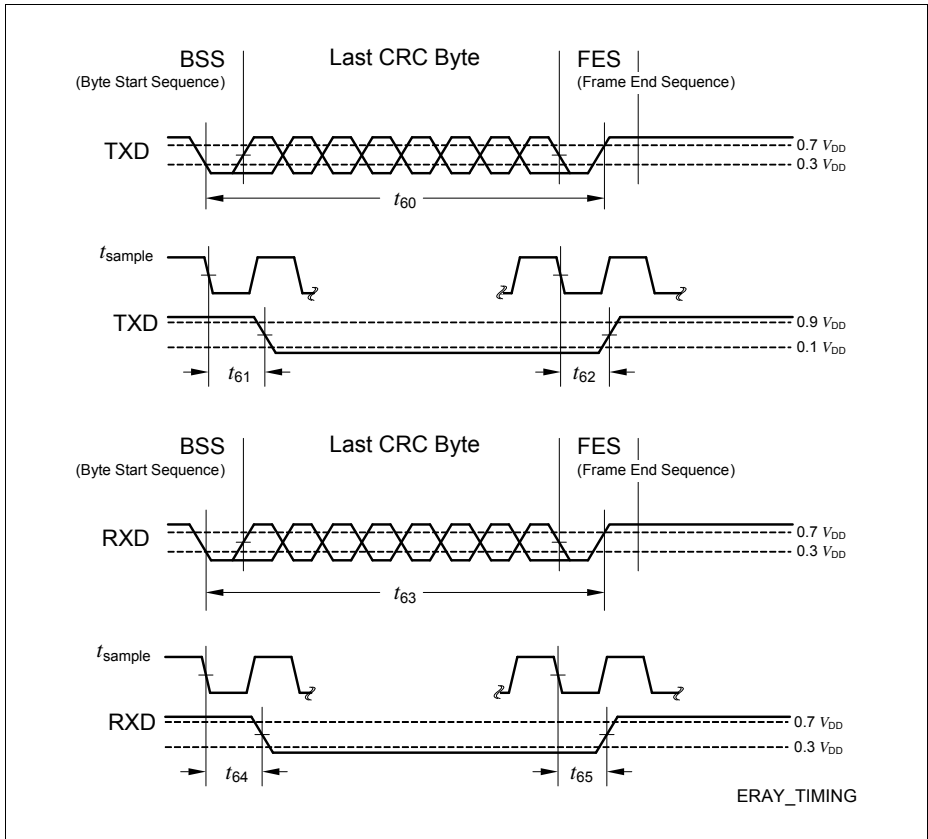


Figure 22 ERAY Timing

## 5.4 Package and Reliability

### 5.4.1 Package Parameters

**Table 38 Thermal Characteristics of the Package**

Device	Package	R <sub>ΘJCT</sub> 1)	R <sub>ΘJC</sub> B <sup>1)</sup>	R <sub>ΘJCL</sub> 1)	Unit	Note
TC1728	PG-LQFP-176-6	7.6	0.6	32.5	K/W	

1) The top and bottom thermal resistances between the case and the ambient ( $R_{TCAT}$ ,  $R_{TCAB}$ ) are to be combined with the thermal resistances between the junction and the case given above ( $R_{TJCT}$ ,  $R_{TJCB}$ ), in order to calculate the total thermal resistance between the junction and the ambient ( $R_{TJA}$ ). The thermal resistances between the case and the ambient ( $R_{TCAT}$ ,  $R_{TCAB}$ ) depend on the external system (PCB, case) characteristics, and are under user responsibility.

The junction temperature can be calculated using the following equation:  $T_J = T_A + R_{TJA} \times P_D$ , where the  $R_{TJA}$  is the total thermal resistance between the junction and the ambient. This total junction ambient resistance  $R_{TJA}$  can be obtained from the upper four partial thermal resistances.

### 5.4.2 Package Outline

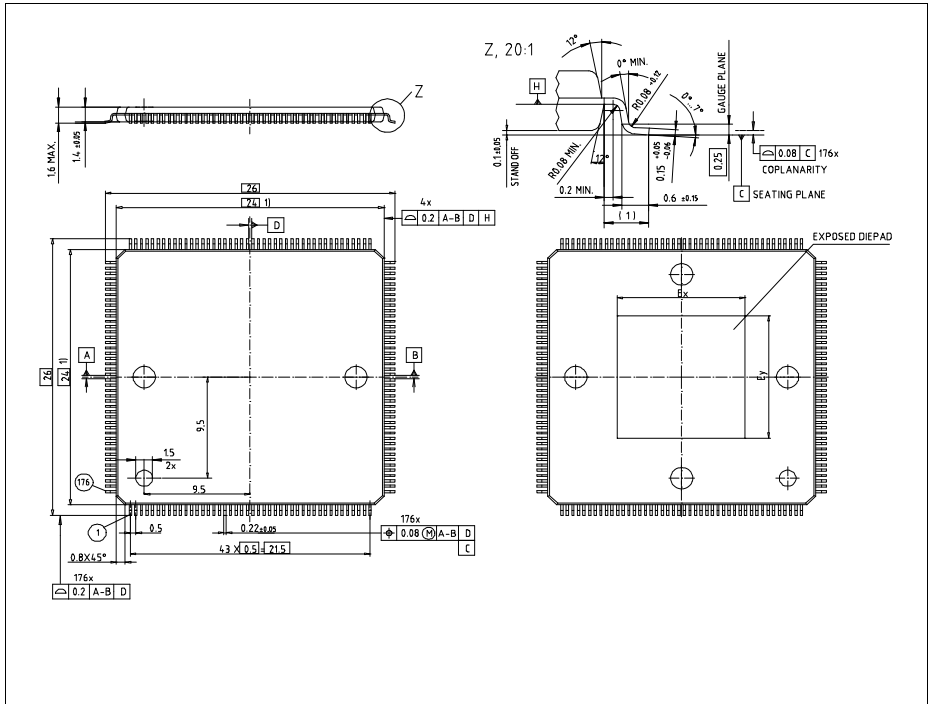


Figure 23 Package Outlines PG-LQFP-176-6

Table 39 Exposed pad Dimensions

Ex	7.5 mm
Ey	7.5 mm

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": <http://www.infineon.com/products>.

### 5.4.3 Flash Memory Parameters

The data retention time of the TC1728's Flash memory depends on the number of times the Flash memory has been erased and programmed.

**Table 40 FLASH32 Parameters**

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Data Flash Erase Time per Sector	$t_{ERD}$	CC	–	–	3 <sup>1)</sup>	s	
Program Flash Erase Time per 256 KByte Sector	$t_{ERP}$	CC	–	–	5	s	
Program time data flash per page <sup>2)</sup>	$t_{PRD}$	CC	–	–	5.3	ms	without reprogramming
			–	–	15.9	ms	with two reprogramming cycles
Program time program flash per page <sup>3)</sup>	$t_{PRP}$	CC	–	–	5.3	ms	without reprogramming
			–	–	10.6	ms	with one reprogramming cycle
Data Flash Endurance	$N_E$	CC	60000 <sup>4)</sup>	–	–	cycles	Min. data retention 5 years
Erase suspend delay	$t_{FL\_ErSusp}$	CC	–	–	15	ms	
Wait time after margin change	$t_{FL\_MarginDel}$	SR	10	–	–	μs	
Program Flash Retention Time, Physical Sector <sup>5)6)</sup>	$t_{RET}$	CC	20	–	–	years	Max. 1000 erase/program cycles
Program Flash Retention Time, Logical Sector <sup>5)6)</sup>	$t_{RETL}$	CC	20	–	–	years	Max. 100 erase/program cycles
UCB Retention Time <sup>5)6)</sup>	$t_{RTU}$	CC	20	–	–	years	Max. 4 erase/program cycles per UCB
Wake-Up time <sup>2)</sup>	$t_{WU}$	CC	–	–	270	μs	

## Electrical Parameters

**Table 40 FLASH32 Parameters**

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
DFlash wait state configuration	$WS_{DF}$	SR	$50ns \times f_{LMB}$	–	–		
PFlash wait state configuration	$WS_{PF}$	SR	$26ns \times f_{LMB}$	–	–		

- 1) In case of wordline oriented defects (see robust EEPROM emulation in the User's Manual) this erase time can increase by up to 100%.
- 2) In case the Program Verify feature detects weak bits, these bits will be programmed up to twice more. Each reprogramming takes additional 5 ms.
- 3) In case the Program Verify feature detects weak bits, these bits will be programmed once more. The reprogramming takes additional 5 ms.
- 4) Only valid when a robust EEPROM emulation algorithm is used. For more details see the User's Manual.
- 5) Storage and inactive time included.
- 6) At average weighted junction temperature  $T_j = 100^\circ\text{C}$ , or the retention time at average weighted temperature of  $T_j = 110^\circ\text{C}$  is minimum 10 years, or the retention time at average weighted temperature of  $T_j = 150^\circ\text{C}$  is minimum 0.7 years.

#### 5.4.4 Quality Declarations

**Table 41 Quality Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Operation Lifetime <sup>1)</sup>	$t_{OP}$	–	–	24000	hours	– <sup>2)</sup>
ESD susceptibility according to Human Body Model (HBM)	$V_{HBM}$	–	–	2000	V	Conforming to JESD22-A114-B
ESD susceptibility of the LVDS pins	$V_{HBM1}$	–	–	500	V	–
ESD susceptibility according to Charged Device Model (CDM)	$V_{CDM}$	–	–	500	V	Conforming to JESD22-C101-C
Moisture Sensitivity Level	MSL	–	–	3	–	Conforming to Jedec J-STD-020C for 240°C



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**Electrical Parameters**

- 1) This lifetime refers only to the time when the device is powered on.
- 2) For worst-case temperature profile equivalent to:
  - 1200 hours at  $T_j = 125...160^{\circ}\text{C}$
  - 3600 hours at  $T_j = 110...125^{\circ}\text{C}$
  - 7200 hours at  $T_j = 100...110^{\circ}\text{C}$
  - 11000 hours at  $T_j = 25...110^{\circ}\text{C}$
  - 1000 hours at  $T_j = -40...25^{\circ}\text{C}$



## 6 Revision History

Changes from V0.3 to V0.4D1

- Operating Conditions
  - Added footnote 3 and 4
  - Updated  $K_{OVAN}$  and  $K_{OVAP}$  max values
  - Added  $f_{CPU}$ ,  $f_{LMB}$ ,  $f_{PCP}$ ,  $f_{FPI,max}$  for SAK-TC1724F-192F133HL, SAK-TC1724F-192F133HR, SAK-TC1724N-192F80HR, SAK-TC1724N-128F80HR.
  - Updated limits for  $V_{DD}$ ,  $V_{DDM}$ ,  $V_{DDP}$ .
  - Added  $I_{IN}$ ,  $\Sigma I_{IN}$
  - Updated  $\Sigma I_{SC\_PG}$
- Standard Pad Class A1
  - Changed  $R_{DSON1}$  to  $R_{DSONM}$ , added new condition “PMOS” for 140ohms, added a new condition for “NMOS” with a max value of 100ohms
  - Added  $R_{DSONW}$
  - Changed min value of  $V_{IHA1}$  to  $0.6 \times V_{DDP}$
  - Changed min value of  $V_{ILA1} / V_{IHA1}$  to 0.6
- Standard Pad Class A1+
  - Added HYSA1+
  - Added  $V_{ILA1+} / V_{IHA1+}$
  - Added  $R_{DSONW}$ ,  $R_{DSONM}$
  - $R_{DSON1+}$ , added new condition “PMOS” for 85ohms, added a new condition for “NMOS” with a max value of 70ohms
  - Changed min value of  $V_{IHA1+}$  to  $0.6 \times V_{DDP}$
  - Deleted -2000nA to 2000nA limits for  $I_{OZA1+}$
- Standard Pad Class A2
  - Added HYSA2
  - Added  $R_{DSONW}$ ,  $R_{DSONM}$
  - $R_{DSON2}$ , added new condition “PMOS” for 25ohms, added a new condition for “NMOS” with a max value of 20ohms
  - $t_{FA2}$ , added max 18000ns for CL=20000pF; pinout driver=medium, 65000ns for CL=20000pF;pinout driver=weak
  - $t_{RA2}$ , removed 140ns for CL=150pF;pinout driver=weak
  - $t_{RA2}$ , added 550ns for CL=150pF,pinout driver=weak, 18000ns for CL=20000pF, pinout driver=medium, 65000ns for CL=20000pF, pinoutdriver=weak
- Standard Pad Class F
  - Added HYSF
  - Changed min value of VIHf to  $0.6 \times V_{DDP}$
  - Added min value of  $V_{ILF} / V_{IHf}$  as 0.6
  - Added  $R_{DSONW}$ ,  $R_{DSONM}$
  - Deleted note for  $t_{FF}$ ,  $t_{RF}$
- Standard Pad Class I
  - Changed min value of  $V_{IHl}$  to  $0.6 \times V_{DDP}$

- Changed min value of  $V_{IL1}$  /  $V_{IH1}$  as 0.6
- LVDS Pads
  - Removed input hysteresis F, HYSF
  - Added note “Parallel termination 100 Ohm +/-1%” for  $t_{FL}$ ,  $t_{RL}$ ,  $t_{SET\_LVDS}$
- Standard Pad Class S
  - Changed max value of  $V_{IHS}$  to 3.6
  - Changed min value of  $V_{ILS}$  to 2.1
  - Added input leakage current,  $I_{OZS}$
- ADC parameters
  - Changed typ value of  $C_{AINSW}$  to 9pF
  - Changed typ value of  $C_{AINTOT}$  to 20pF
  - Updated notes for  $EA_{DNL}$ ,  $EA_{GAIN}$ , TUE,  $EA_{INL}$ ,  $EA_{OFF}$
  - Changed  $f_{ADCI}$  to max 20MHz
  - Added  $f_{ADC}$  of 110MHz where ffpimax=110MHz
  - Added  $f_{ADC}$  of 80MHz where ffpimax=80MHz
  - Updated  $f_{ADC}$  min of 4MHz
  - Added sample time,  $t_S$ , 2 to 255 tADCI
  - Added calibration time after reset,  $t_{CAL}$  max 4352 cycles
  - Included footnote for TUE for 10-bit and 8-bit conversion
  - Removed  $I_{AIN7T}$  (covered by  $R_{AIN7T}$ )
  - Removed  $I_{AREF}$ , added  $Q_{CONV}$
  - Updated notes for  $I_{OZ2}$  and  $I_{OZ3}$
  - Updated typ value of 900Ohm for  $R_{AIN}$
- FADC parameters
  - Updated note for  $EF_{GRAD}$
  - Updated note for  $EF_{OFF}$
  - Added  $f_{FADC}$  of 110MHz where ffpimax=110MHz
  - Added  $f_{FADC}$  of 80MHz where ffpimax=80MHz
  - Added conversion time,  $t_C$
  - Added analog input voltage range,  $V_{AINF}$
- OSC XTAL parameters
  - Added  $f_{OSC}$
  - Changed max value of  $V_{IHx}$  to  $V_{DDP}+0.5V$
  - Changed min value of  $V_{ILx}$  to -0.5V
  - Added typ values for internal load capacitors,  $C_{L0}$  to  $C_{L3}$ , 2.5pF, 2.5pF, 4pF, 6.5pF
  - Added HYSAX
- Power Supply parameters
  - Updated  $I_{DDP}$ ,  $I_{DDM}$ ,  $I_{DDP\_FP}$
  - Added  $I_{DD}$  for  $f_{CPU}=80MHz$  for max and realistic patterns
  - Updated PD values for max and real patterns, all external,  $f_{CPU}=133MHz$
  - Added text to of  $f_{CPU}=133MHz$  to the note for the PD parameter.
  - Added PD for  $f_{CPU}=80MHz$  for max and realistic patterns for both all external mode and 5V only with ext.pass device mode

## Revision History

- Current consumption for LVDS pad pairs is updated for all LVDS pads in total
- Deleted the redundant  $I_{DDP}$
- Updated  $I_{DDP\_FP}$ ,  $I_{DDP\_PORST}$ ,  $I_{DD\_PORST}$
- Deleted  $R_{THJA}$  parameter
- Power Sequencing
  - Added Power Sequencing for 3.3V Supply Only section
- Power, Pad and Reset Timing parameters
  - Removed redundant note for  $t_{HDH}$ ,  $t_{HDS}$
  - Added text from note “TESTMODE/TRST” to the name of  $t_{POH}$  and  $t_{POS}$ , deleted note
- EVR Parameters
  - Added  $I_{PU\_VDPG}$ ,  $V_{IH}$  and  $V_{IL}$  parameters in Pass Device Detector Table
  - Added EVR Parameter Table
- PLL SYSCLK parameters
  - Changed max value for  $f_{VCO}$
  - Added min value of 50us for  $t_L$
  - Included formula 1 and 2
  - Removed note for peak-to-peak noise on pad supply voltage
- PLL ERAY parameters
  - Changed typ value to 250MHz for  $f_{PLLBASE}$
  - Added min value of 50us for  $t_L$
  - Removed note for peak-to-peak noise on pad supply voltage
- JTAG Interface parameters
  - Changed to ‘=’ signs in the notes for  $t_8$ ,  $t_9$  and  $t_{10}$
- DAP parameters
- Peripheral Timings
  - Removed note for Peripheral Timings “Peripheral timing parameters are not subject to production test. They are verified by design/characterization.”
- MLI Timing
  - Added text for MLI parameters valid for CL=25pF
- MLI Receiver parameters
  - Changed  $f_{SYS}$  to 110MHz in footnote 3
- MLI Trmitter parameters
  - Changed  $t_{13}$ , TCLK rise time and  $t_{14}$ , TCLK fall time to  $0.3 \times t_{10}$
- MSC parameters
  - Added text for MSC parameters valid for CL=25pF
  - Added limits for different pad drive strength of  $t_{45}$
- parameters
  - Changed min value of  $t_{52}$  to 16.5ns
- ERAY parameters
  - Changed min value of  $t_{60}$
  - Changed max value of  $t_{61}$ - $t_{62}$
  - Changed min and max values of  $t_{63}$

- Changed max value of  $t_{64-t65}$
- Added  $dTx\,dly$ ,  $dRx\,dly$
- Updated ERAY timing figure
- Flash32 parameters
  - Updated  $t_{PRD}$ ,  $t_{PRP}$
  - Changed min value of  $WS_{DF}$  to  $50ns \times f_{LMB}$
  - Updated footnote 3
- Package parameters
  - Added  $R_{THJCT}$ ,  $R_{THJCB}$ ,  $R_{THJCL}$  for LQFP144
- Package outline
  - Added package outline for LQFP176

#### Changes from V0.5 to V0.6

- Added max limit for  $V_{RST5}$  for 5.0V single supply
- Removed note above MLI Transmitter table
- Updated conditions for  $t_{FL}$  and  $t_{RL}$  for LVDS pad parameters
- Updated limits for  $R_{DSONW}$  and  $R_{DSONM}$  for Class A1 pads
- Updated limits for  $R_{DSONW}$  and  $R_{DSONM}$  and  $R_{DSON1+}$  for Class A1+ pads
- Updated limits for  $R_{DSONW}$  and  $R_{DSONM}$  and  $R_{DSON2}$  for Class A2 pads
- Updated limits for  $R_{DSONW}$  and  $R_{DSONM}$  for Class F pads
- Updated conditions for  $t_{RF}$  and  $t_{FF}$  for Class F pad parameters
- Added footnote 7 to ADC table
- Updated  $Q_{CONV}$  of ADC table
- Updated conditions to  $t_L$  of PLL Sysclk
- Changed  $t_{19}$  of DAP from SR to CC
- Removed condition for  $V_5$
- Added FADC input circuit
- Updated max limit for  $V_{AGND0}$  and min limit for  $V_{AREF0}$
- $t_{BWG}$  and  $t_{BWR}$  are added to ADC table
- Updated description of  $t_{CAL}$
- Added a placeholder for  $R_{AIN}$ ,  $R_{AIN7T}$ ,  $R_{AREF}$ ,  $t_S$ ,  $f_{ADCI}$ ,  $EA_{DNL}$ ,  $EA_{INL}$ ,  $EA_{GAIN}$ ,  $EA_{OFF}$ ,  $TUE$  at a separate ADC table for  $V_{DDM}=3.3V$
- Added a placeholder for  $t_{AWAF}$ ,  $t_{AWAS}$  to both ADC tables for  $V_{DDM}=5V$  and  $V_{DDM}=3.3V$
- Added a placeholder for  $t_{FWAF}$ ,  $t_{FWAS}$  to FADC table for  $V_{DDM}=5V$ ,  $V_{DDM}=3.3V$
- Removed limits of gain=8 for  $EF_{GRAD}$
- Added  $V_{FAREF1}$  and  $V_{FAGND1}$  parameters
- Updated limit of  $t_{SF2}$  to min 120ns
- Typo in Note for  $I_{V5}$  at 80MHz is corrected.
- Updated max limit of  $\Sigma I_{IN}$ .
- Added  $I_{IN}$ .
- Added Pin Reliability in Overload subchapter.
- Removed sentence “Exposure to conditions within the maximum ratings will not affect device reliability.” Replaced with the Pin Reliability in Overload subchapter.

**Revision History**

- Removed capacitance conditions for LVDS pad parameters,  $t_{RL}$ ,  $t_{FL}$ , loads defined by interface (MSC) timing.
- Updated max limits of Flash parameters  $t_{PRD}$ ,  $t_{PRP}$
- Updated representation of  $I_{DDP}$
- Updated limits of  $I_{DD\_PORST}$  to max 110mA
- Updated limits of  $I_{DDP\_PORST}$  to max 6mA
- Updated limits of  $I_{DD}$  for real pattern,  $f_{CPU=133MHz}$ , to max 212mA
- Added new parameter  $I_{DDSUM}$
- Updated max limit of  $I_{DDM}$  to 32mA
- Updated TC1728  $I_{V5}$  for max and real patterns,  $f_{CPU=133MHz}$
- Updated  $PD$  for real pattern,  $f_{CPU=133MHz}$ , all external supplies.
- Updated TC1728  $PD$  for max and real patterns,  $f_{CPU=133MHz}$ , 5V only with external pass device.
- Updated limit for  $R_{DSON2}$  of A2 pad, P\_MOS
- Updated limits for  $R_{DSONM}$  of F pad, P\_MOS, N\_MOS
- Removed  $V_{IH}$  for Pass Device Detector
- Updated limits for  $V_{IL}$  of Pass Device Detector
- Updated limits and test conditions for  $\Delta V_{LOREG33}$  and  $\Delta V_{LIREG33}$
- Updated test condition for 5.0V single supply  $\Delta V_{LOREG13}$
- Updated limits and test condition for 5.0V single supply  $\Delta V_{LIREG13}$
- Corrected typ and max limits for  $C_{OUT33}$  and  $C_{OUT13}$
- Added limit and test condition for 3.3V single supply  $\Delta V_{LOREG13}$  and  $\Delta V_{LIREG13}$
- Application reset boot time limits are updated
- Added min limit for  $I_{OZS}$
- Added a new parameter  $V_{ILSD}$
- Updated limits for  $t_{BP}$ ,  $STT$
- Removed typical text from load of Peripheral Timing sections.
- Limits for  $EF_{GRAD}$  with Gain=4 is changed to TBD
- Min limit for  $V_{DDM}$  is changed to TBD
- Added  $EF_{REFI}$
- Added a placeholder for  $R_{FAIN}$ ,  $EF_{DNL}$ ,  $EF_{INL}$ ,  $EF_{GRAD}$ ,  $EF_{OFF}$  at a separate ADC table for  $V_{DDM}=3.3V$
- Added max and typ limits for  $R_{RAIN}$  for  $V_{DDM}=3.3V$
- Updated limits of  $P_D$  for real pattern,  $f_{CPU=80MHz}$ , to max 669mW
- Updated text for Note column of  $N_E$
- Corrected typo for Class D pads in PN-Junction Characteristics for positive/negative overload tables
- Updated limits of  $I_{DD}$  for max pattern,  $f_{CPU=133MHz}$ , to max 310mA
- Updated limits of  $I_{DD}$  for max pattern,  $f_{CPU=80MHz}$ , to max 248mA
- Updated limits of  $P_D$  for max pattern,  $f_{CPU=133MHz}$ , to max 902mA
- Updated limits of  $I_{DD}$  for max pattern,  $f_{CPU=80MHz}$ , to max 810mA
- Corrected typo for  $C_{OUT13}$
- Updated load jump current for  $C_{OUT33}$  and  $C_{OUT13}$  for  $f_{CPU}=80MHz$
- Changed min to typ value for  $C_{IN5}$

**Changes from V0.6 to V0.7**

- Name of package is updated

**Changes from V0.7 to V0.8**

- Absolute maximum rating section for is updated for  $V_{DDP}$ ,  $V_{IN}$ ,  $V_{AIN}$ ,  $V_{AREF0}$ ,  $V_{AINF}$
- A footnote is added to  $t_{ERD}$
- A note is added, updated pad supply levels in Pin Reliability in Overload section
- Updated min limit for  $t_{17}$  of MLI
- Added a footnote to  $I_{DDP}$
- Included text to power sequencing sections for setting of P0.4 and P0.5.
- Added limits for  $EF_{DNL}$  for Gain= 4, 8
- Changed STT to  $t_{EVR}$ , updated Power, Pad and Reset Timing figure
- Changed min limit of  $t_L$  for PLL\_Sysclk timing
- Removed  $I_{PU\_VDPG}$  for  $V_{DD5} \geq 2.97V$ ,  $V_{DD5} \leq 3.63V$
- Updated limit and test condition for  $C_{OUT33}$ ,  $C_{OUT13}$
- Updated limit for  $C_{IN5}$
- Updated limit and test condition for  $\Delta V_{LOREG33}$
- Removed  $PSRR_{33}$ ,  $PSRR_{13}$
- Updated test condition for  $\Delta V_{LOREG13}$
- Updated limit and test condition for  $\Delta V_{LIREG13}$
- Updated min limit for MSC t45, strong sharp setting, CMOS mode
- Added  $\Delta V_{OUT33}$ ,  $\Delta V_{OUT13}$  parameters
- Updated first sentence for Chapter 5.3
- Added text for MLI and SSC parameters for validity of strong driver medium edge only
- Updated description for  $t_{52}$  and  $t_{53}$
- Changed SSC parameters from CC to SR for  $t_{56}$ ,  $t_{57}$ ,  $t_{58}$ , and  $t_{59}$
- Changed min to max limit for EVR Supply ramp-up parameter
- Updated min limit for  $I_{PU\_VDPG}$

**Changes from V0.8 to V1.0**

- Added limits for  $EF_{GRAD}$  for Gain= 4, 8
- Added limits for  $EF_{REFI}$
- Updated  $V_{FAGND1}$ ,  $V_{FAREF1}$ , changed from SR to CC
- A footnote is added for  $V_{FAREF1}$
- Updated limit for  $C_{IN5}$
- Added min limit for  $V_5$
- Updated limits for  $f_{ADC1}$ ,  $t_{BWG}$ ,  $t_{BWR}$ ,  $t_{AWAF}$ ,  $t_{AWAS}$ ,  $t_{FWAF}$ ,  $t_{FWAS}$
- Updated limits for ADC table,  $V_{DDM} = 3.3V$ ,  $f_{ADC1}$ ,  $t_{BWG}$ ,  $t_{BWR}$ ,  $t_{AWAF}$ ,  $t_{AWAS}$ ,  $t_{FWAF}$ ,  $t_{FWAS}$ ,  $R_{AIN7T}$ ,  $EA_{DNL}$ ,  $EA_{GAIN}$ ,  $EA_{INL}$ ,  $EA_{OFF}$ ,  $TUE$ ,  $Q_{CONV}$
- Corrected typo in test condition for  $R_{DSON}$
- Removed  $R_{DSONW}$  parameter for class F pads
- Removed footnote 2 from  $\Sigma I_{SC\_D}$



- Added footnote 3 to  $V_{DDM}$
- Updated max limit for ADC parameter  $t_S$
- Added footnote 2 for  $t_9$  of JTAG parameter
- Changed  $t_{26}$ ,  $t_{27}$  from CC to SR
- Updated max limit for ADC parameter  $V_{AIN}$
- Added footnote 5 to  $t_{59}$
- Added  $t_{POR\_APP}$  parameter of Reset Timing parameters

#### Changes from V1.0 to V1.1

- Updated description for  $t_{CAL}$
- Added a footnote to  $Q_{CONV}$
- Added marking option SAK-TC1728F-192F133HR to Table 1, Summary of Features section
- Updated Figure 2, Figure 3-1, Figure 3-2
- Added identification registers in Table 4
- Updated  $f_{CPU}$ ,  $f_{FPI}$ ,  $f_{LMB}$ ,  $f_{PCP}$ ,  $f_{ADC}$ ,  $f_{FADC}$ ,  $I_{DD}$ ,  $I_{DDSUM}$ ,  $I_{V5}$ ,  $PD$
- Added footnote 8 to  $PD$

#### Changes from V1.1 to V1.2

- change  $t_{48}$  from 100ns to 200ns in table 29
- change  $t_{49}$  from 100ns to 200ns in table 29
- extend  $K_{OVAN}$  condition from  $I_{OV} \leq 0$  mA;  $I_{OV} \geq -1$  mA to  $I_{OV} \leq 0$  mA;  $I_{OV} \geq -2$  mA
- clarify leakage definition for A1 and I pads for  $150^\circ\text{C} < T_J \leq 160^\circ\text{C}$
- change  $V_{ILS}$  from 2.1V to 1.9V in table 25
- change  $t_{56}$  from  $1 / f_{FPI}$  to  $1 / f_{FPI} + 1$  in table 30
- change  $R_{AIN}$  from 4500 Ohm to 9000 Ohm in table 15
- add the product options SAK-TC1728F-192F133HL
- shift the products SAK-TC1728F-192F133HR and SAK-TC1728N-192F80HR from step AB to AC
- Update max limit for pad class F parameter  $R_{DSONM}$

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